

## RL78/H1D

**RENESAS MCU** 

R01DS0318EJ0111 Rev. 1.11 Mar 22, 2024

Analog front-end (24-bit  $\Delta\Sigma$ A/D converter with programmable gain instrumentation amplifier, Amplifier unit and 12-bit D/A converter), External signal sampler/Sampling output timer detector and Integrated LCD controller/driver.

True Low Power Platform (as low as 70.8  $\mu$ A/MHz, and 0.68  $\mu$ A in Halt mode( RTC2 + LVD)), 1.8 V to 5.5V operation, 64 to 128 Kbyte Flash, 33 DMIPS at 24 MHz, for Healthcare and Flow meter applications.

## 1. OUTLINE

### 1.1 Features

- O Ultra-low power consumption technology
  - VDD = 2.4 to 5.5 V
     (10-bit SAR A/D converter: 2.4 to 5.5 V, operating voltage of the analog front-end (AFE): 2.7 to 5.5 V) Note 1,
     VDD = 1.8 to 5.5 VNote 2
  - HALT mode
  - STOP mode
  - SNOOZE mode
- O RL78 CPU core
  - CISC architecture with 3-stage pipeline
  - Minimum instruction execution time: Can be changed from high speed (0.04167 μs: @ 24 MHz operation with high-speed on-chip oscillator clock) to ultra-low speed (30.5 μs: @ 32.768 kHz operation with subsystem clock)
  - Multiply/divide and multiply/accumulate instructions are supported.
  - Address space: 1 MB
  - General-purpose registers: (8-bit register x 8)
     x 4 banks
  - On-chip RAM: 5.5 KBNote 1, 8 KBNote 2
- Code flash memory
  - Code flash memory: 64 to 128 KB
  - Block size: 1 KB
  - Prohibition of block erase and rewriting (security function)
  - On-chip debug function
  - Self-programming (with boot swap function/flash shield window function)
- O Data flash memory
  - Data flash memory: 4 KB

- Background operation (BGO): Instructions can be executed from the program memory while rewriting the data flash memory.
- Number of rewrites: 1,000,000 times (TYP.)
- Voltage of rewrites: VDD = 2.4 to 5.5 V<sup>Note 1</sup>,
   1.8 to 5.5 V<sup>Note 2</sup>
- O High-speed on-chip oscillator
  - Select from 24 MHz, 16 MHz, 12 MHz, 8 MHz, 6 MHz, 4 MHz, 3 MHz, 2 MHz, and 1 MHz
  - High accuracy: ±1.0% (VDD = 2.4 to 5.5 V, TA = -20 to +85°C<sup>Note 1</sup>, VDD = 1.8 to 5.5 V, TA = -20 to +85°C<sup>Note 2</sup>)
- Operating ambient temperature
  - TA = -40 to +85°C (A: Consumer applications<sup>Note 1</sup>, D: Industrial applications<sup>Note 2</sup>)
- O Power management and reset function
  - On-chip power-on-reset (POR) circuit
  - On-chip voltage detector (LVD) (Select interrupt and reset from 9<sup>Note 1</sup> or 12<sup>Note 2</sup> levels)
- O Data transfer controller (DTC)
  - Transfer modes: Normal transfer mode, repeat transfer mode, block transfer mode
  - Activation sources: Activated by interrupt sources (35 sources).
  - Chain transfer function
- O Event link controller (ELC)
  - Event signals of 18 to 26 types can be linked to the specified peripheral function.



- O Serial interfaces
  - Simplified SPI(CSI Note 3)/Simplified SPI(CSI)(SPI supported): 3 channels
  - UART/UART (LIN-bus supported):3 channels
  - I2C/simplified I2C: 4 channels
  - Serial interface UARTMG (9600 bps @ 38.4 kHz): 1 channel (R5F11R only)

#### ○ Timers

• 16-bit timer:

Timer array unit (TAU): 8 channels, Timer RJ: 2 channels (R5F11R only)

- 8-bit timer:2 channelsNote 1, 6 channelsNote 2
- 12-bit interval timer: 1 channel
- Real-time clock 2: 1 channel (calendar for 99 years, alarm function, and clock correction function)
- Watchdog timer: 1 channel (operable with the dedicated low-speed on-chip oscillator)
- External signal sampler: 1 channel (R5F11R only)
- Sampling output timer detector (SMOTD):
   6 channels for input, 3 channels for output (R5F11R only)

### O LCD controller/driver

- Internal voltage boosting method, capacitor split method, and external resistance division method are switchable.
- Segment signal output: 27 (23) to 36 (32) Note 4
- Common signal output: 4 (8) Note 4
- Analog front-end power supply circuit (R5F11N and R5F11P only)
  - AFE reference power supply (ABGR)
  - LDO for supplying power to internal circuits (REGA)
  - LDO for supplying power to a sensor (SBIAS): 0.5 to 2.2 V
- $\bigcirc$  24-bit  $\Delta\Sigma$  A/D converter with programmable gain instrumentation amplifier (R5F11N and R5F11P only)
  - 24-bit second-order  $\Delta\Sigma$  A/D converter (AVDD = 2.7 to 5.5 V)
  - SNDR: 85 dB (TYP.)
  - Output data rate: 488 sps to 15.625 ksps in normal mode
  - 61 sps to 1.953 ksps in low power mode
  - Programmable gain instrumentation amplifier (PGA0)

- Analog input: 1 to 5 channels (differential input mode or single-ended input mode)
- D/A converter for offset adjustment
- Variable gain: x1 to x64
- Amplifier unit (R5F11N and R5F11P only)
  - Programmable gain instrumentation amplifier (PGA1): 1 channel (R5F11NL, R5F11PL, and R5F11NG only)
    - Analog input: 1 or 2 channels
    - Variable gain: x12, x16, x20, x24
  - Rail-to-rail operational amplifier (AMP0): 1 channel
  - General-purpose operational amplifier (AMP1, AMP2): 2 channels (R5F11NL, R5F11PL, and R5F11NG only)
- O D/A converter (R5F11N and R5F11P only)
  - 8-bit resolution R-2R resistor ladder D/A converter (DAC0) (AVDD = 2.7 to 5.5 V):
     1 channel
  - 12-bit resolution R-2R resistor ladder D/A converter (DAC1) (AVDD = 2.7 to 5.5 V): 1 channel (R5F11NL, R5F11PL, and R5F11NG only)
- O 10-bit SAR A/D converter
  - 10-bit resolution A/D converter (VDD = 2.4 to 5.5 V<sup>Note 1</sup>, VDD = 1.8 to 5.5 V<sup>Note 2</sup>)
  - Analog input: 3 channels
  - Internal reference voltage (TYP. 1.45 V) Note 5 and temperature sensor Note 5
- O I/O ports
  - I/O ports: 29 to 63 (N-ch open drain I/O [withstand voltage of 6 V]: 2)
  - Can be set to N-ch open drain, TTL input buffer, and on-chip pull-up resistor
  - On-chip clock output/buzzer output controller
- Others
  - On-chip BCD (binary-coded decimal) correction circuit
- Note 1. In case of R5F11N and R5F11P.
- Note 2. In case of R5F11R.
- Note 3. Although the CSI function is generally called SPI, it is also called CSI in this product, so it is referred to as such in this manual.
- Note 4. The number in parentheses indicates the number of signal outputs when 8 coms are used.

Note 5. Selectable only in HS (high-speed main) mode.

**Remark** The functions mounted depend on the product. See **1.6 Outline of Functions**.

## O ROM, RAM capacities

| Flash ROM  | Data Flash  | RAM    | RL78/H1D     |              |              |              |  |
|------------|-------------|--------|--------------|--------------|--------------|--------------|--|
| Flasii KOW | Data Flasii | KAW    | 80-pin LFQFP | 64-pin LFQFP | 64-pin TFBGA | 48-pin LFQFP |  |
| 128 KB     | 4 KB        | 5.5 KB | R5F11NMG     | R5F11NLG     | R5F11PLG     | R5F11NGG     |  |
| 96 KB      | 4 KB        | 5.5 KB | R5F11NMF     | R5F11NLF     | R5F11PLF     | R5F11NGF     |  |
| 64 KB      | 4 KB        | 5.5 KB | R5F11NME     | _            | _            | _            |  |
| 128 KB     | 4 KB        | 8 KB   | R5F11RMG     | _            | _            | _            |  |

# 1.2 Ordering Information

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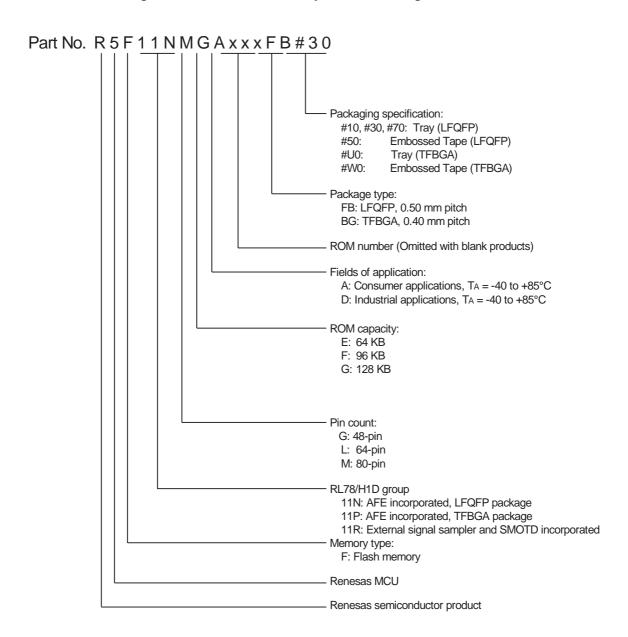
| Pin     | Package  | Fields of   | Orderable F                                 | RENESAS Code             |               |
|---------|--|-------------|---|--------------------------|---------------|
| Count   | Package  | Application | Product Name                                | Packaging Specifications | RENESAS Code  |
| 80 pins | 80-pin plastic LFQFP<br>(12 x 12 mm, 0.5 mm pitch) | A           | R5F11NMGAFB,<br>R5F11NMFAFB,<br>R5F11NMEAFB | #10, #30, #50, #70       | PLQP0080KB-B  |
| 64 pins | 64-pin plastic LFQFP<br>(10 × 10 mm, 0.5 mm pitch) | А           | R5F11NLGAFB,<br>R5F11NLFAFB                 | #10, #30, #50, #70       | PLQP0064KB-C  |
| 64 pins | 64-pin plastic TFBGA<br>(4 × 4 mm, 0.4 mm pitch)   | А           | R5F11PLGABG,<br>R5F11PLFABG                 | #U0, #W0                 | PTBG0064LA-A  |
| 48 pins | 48-pin plastic LFQFP<br>(7 × 7 mm, 0.5 mm pitch)   | А           | R5F11NGGAFB,<br>R5F11NGFAFB                 | #10, #30, #50, #70       | PLQP0048KB-B  |
| 80 pins | 80-pin plastic LFQFP<br>(12 x 12 mm, 0.5 mm pitch) | D           | R5F11RMGDFB                                 | #10, #30, #50, #70       | PLQP0080KB- B |

Remark 1. Products (R5F11PL) in 64-pin TFBGA have the same functionality as those (R5F11NG) in 48-pin LFQFP. The only difference is the package.

Remark 2. For the fields of application, refer to Part Number, Memory Size, and Package.

Figure 1 - 1 Part Number, Memory Size, and Package of RL78/H1D

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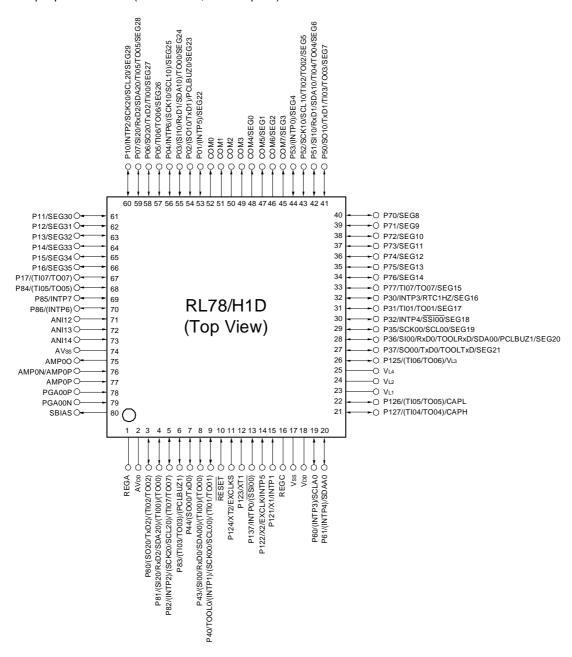
Caution Orderable part numbers are current as of when this manual was published.

Please make sure to refer to the relevant product page on the Renesas website for the latest part numbers.

# 1.3 Pin Configuration (Top View)

## 1.3.1 80-pin products (R5F11NM)

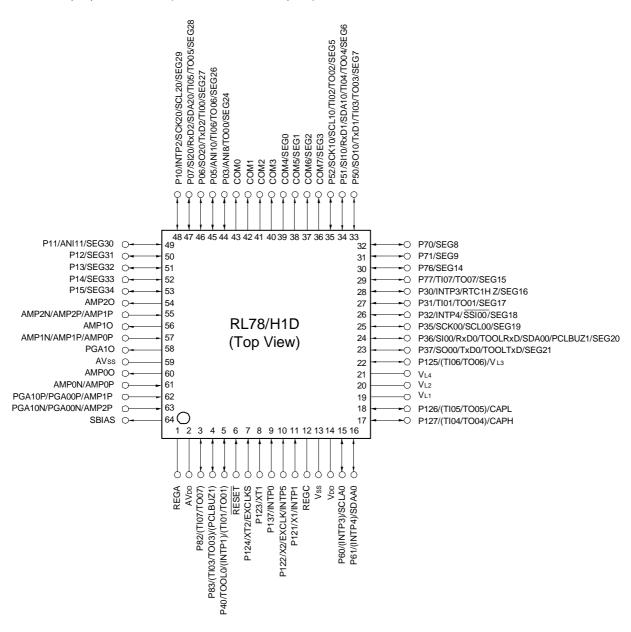
• 80-pin plastic LFQFP (12 x 12 mm, 0.5 mm pitch)



- Caution 1. Connect the REGC pin to Vss pin via a capacitor (0.47 to 1  $\mu\text{F}).$
- Caution 2. Connect the REGA pin to AVss pin via a capacitor (0.22  $\mu\text{F}).$
- Caution 3. Make the AVss pin the same potential as the Vss pin.
- Caution 4. Make the AVDD pin the same potential as the VDD pin.
- Caution 5. Connect the SBIAS pin to AVss pin via a capacitor (0.22 µF).
- Remark 1. For pin identification, see 1.4 Pin Identification.
- Remark 2. Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection registers 0 to 3 (PIOR0 to PIOR3)
- Remark 3. Set the AMP0P and AMP0N functions in the above figure by the amplifier unit 1 input select register (AMP0S).

# 1.3.2 64-pin products (R5F11NL)

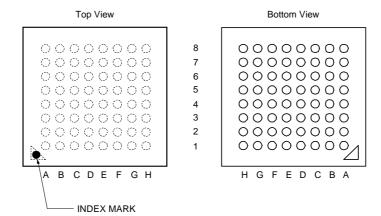
• 64-pin plastic LFQFP (10 x 10 mm, 0.5 mm pitch)



- Caution 1. Connect the REGC pin to Vss pin via a capacitor (0.47 to 1  $\mu$ F).
- Caution 2. Connect the REGA pin to AVss pin via a capacitor (0.22  $\mu F$ ).
- Caution 3. Make the AVss pin the same potential as the Vss pin.
- Caution 4. Make the AVDD pin the same potential as the VDD pin.
- Caution 5. Connect the SBIAS pin to AVss pin via a capacitor (0.22  $\mu F$ ).
- Remark 1. For pin identification, see 1.4 Pin Identification.
- **Remark 2.** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection registers 0 to 3 (PIOR0 to PIOR3).
- Remark 3. Set the AMP0P and AMP0N functions in the above figure by the amplifier unit 1 input select register (AMP0S). Set the AMP1P and AMP1N functions in the above figure by the amplifier unit 2 input select register (AMP1S). Set the AMP2P and AMP2N functions in the above figure by the amplifier unit 3 input select register (AMP2S).

# 1.3.3 64-pin products (R5F11PL)

• 64-pin plastic TFBGA (4 × 4 mm, 0.4 mm pitch)

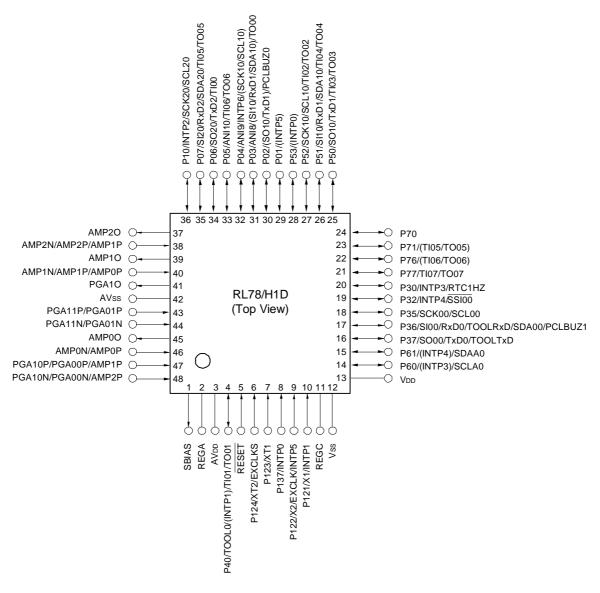


|   | Α                               | В   | С                                    | D                             | Е   | F                                   | G                           | Н                           |   |
|---|---------------------------------|---|--------------------------------------|-------------------------------|---|-------------------------------------|-----------------------------|-----------------------------|---|
| 8 | Vss                             | P71/(TI05/<br>TO05)                         | P77/TI07/<br>TO07                    | P35/SCK00/<br>SCL00           | P36/SI00/<br>RxD0/<br>TOOLRxD/<br>SDA00/<br>PCLBUZ1 | P61/(INTP4)/<br>SDAA0               | VDD                         | Vss                         | 8 |
| 7 | P50/SO10/<br>TxD1/Tl03/<br>TO03 | P51/SI10/Rx<br>D1/SDA10/<br>TI04/TO04       | P76/(TI06/<br>TO06)                  | P32/INTP4/<br>SSI00           | P37/SO00/<br>TxD0/<br>TOOLTxD                       | P60/(INTP3)/<br>SCLA0               | Vss                         | P121/X1/<br>INTP1           | 7 |
| 6 | P53/(INTP0)                     | P52/SCK10/<br>SCL10/TI02/<br>TO02           | P70                                  | P30/INTP3/<br>RTC1HZ          | Vss   | RESET                               | REGC                        | P122/X2/<br>EXCLK/<br>INTP5 | 6 |
| 5 | P02/(SO10/<br>TxD1)/<br>PCLBUZ0 | P03/ANI8/<br>(SI10/RxD1/<br>SDA10)/<br>TO00 | P04/ANI9/IN<br>TP6/(SCK10/<br>SCL10) | P01/(INTP5)                   | Vss   | P40/TOOL0/<br>(INTP1)/TI01<br>/TO01 | P137/INTP0                  | P123/XT1                    | 5 |
| 4 | P05/ANI10/<br>TI06/TO06         | P07/SI20/<br>RxD2/<br>SDA20/<br>TI05/TO05   | P06/SO20/<br>TxD2/TI00               | P10/INTP2/<br>SCK20/<br>SCL20 | Vss   | Vss                                 | Vss                         | P124/XT2/<br>EXCLKS         | 4 |
| 3 | AMP1O                           | AVss  | AVss                                 | AVss                          | AVss  | AVss                                | REGA                        | AVDD                        | 3 |
| 2 | AMP2O                           | AMP1N/<br>AMP1P/<br>AMP0P                   | PGA11P/<br>PGA01P                    | PGA11N/<br>PGA01N             | AMPON/<br>AMPOP                                     | AVss                                | AVss                        | SBIAS                       | 2 |
| 1 | AVss                            | AMP2N/<br>AMP2P/<br>AMP1P                   | PGA1O                                | AVss                          | AMP0O   | PGA10P/<br>PGA00P/<br>AMP1P         | PGA10N/<br>PGA00N/<br>AMP2P | SBIAS                       | 1 |
|   | Α                               | В   | С                                    | D                             | E   | F                                   | G                           | Н                           |   |

- Caution 1. Connect the REGC pin to Vss pin via a capacitor (0.47 to 1  $\mu$ F).
- Caution 2. Connect the REGA pin to AVss pin via a capacitor (0.22  $\mu$ F).
- Caution 3. Make the AVss pin the same potential as the Vss pin.
- Caution 4. Make the AVDD pin the same potential as the VDD pin.
- Caution 5. Connect an SBIAS pin (either of two) to the AVss pin via a capacitor (0.22 µF).
- Remark 1. For pin identification, see 1.4 Pin Identification.
- Remark 2. Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection registers 0, 1, and 3 (PIOR0, PIOR1, and PIOR3).
- Remark 3. Set the AMP0P and AMP0N functions in the above figure by the amplifier unit 1 input select register (AMP0S). Set the AMP1P and AMP1N functions in the above figure by the amplifier unit 2 input select register (AMP1S). Set the AMP2P and AMP2N functions in the above figure by the amplifier unit 3 input select register (AMP2S).

# 1.3.4 48-pin products (R5F11NG)

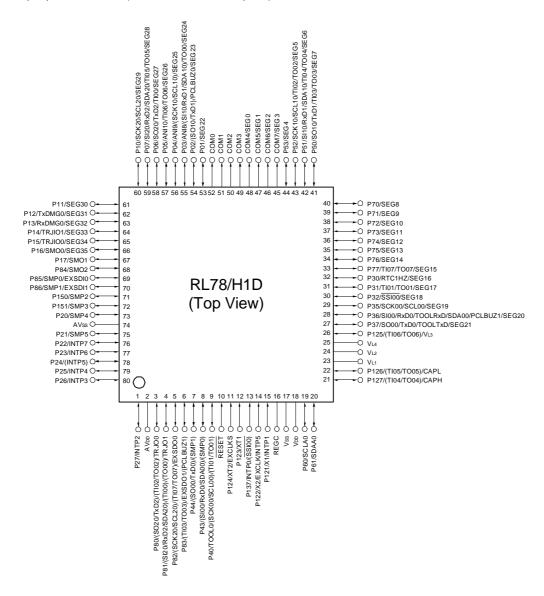
• 48-pin plastic LFQFP (7 x 7 mm, 0.5 mm pitch)



- Caution 1. Connect the REGC pin to Vss pin via a capacitor (0.47 to 1  $\mu$ F).
- Caution 2. Connect the REGA pin to AVss pin via a capacitor (0.22 µF).
- Caution 3. Make the AVss pin the same potential as the Vss pin.
- Caution 4. Make the AVDD pin the same potential as the VDD pin.
- Caution 5. Connect the SBIAS pin to AVss pin via a capacitor (0.22 µF).
- Remark 1. For pin identification, see 1.4 Pin Identification.
- **Remark 2.** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection registers 0, 1, and 3 (PIOR0, PIOR1, and PIOR3).
- Remark 3. Set the AMP0P and AMP0N functions in the above figure by the amplifier unit 1 input select register (AMP0S). Set the AMP1P and AMP1N functions in the above figure by the amplifier unit 2 input select register (AMP1S). Set the AMP2P and AMP2N functions in the above figure by the amplifier unit 3 input select register (AMP2S).

# 1.3.5 80-pin products (R5F11RM)

• 80-pin plastic LFQFP (12 x 12 mm, 0.5 mm pitch)



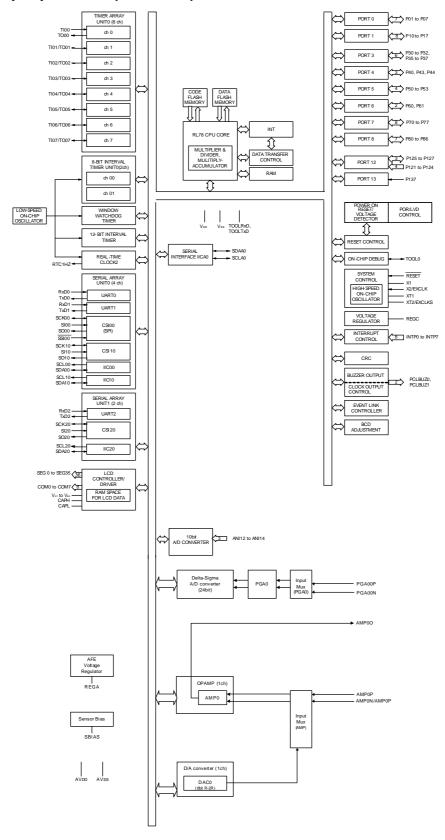
- Caution 1. Connect the REGC pin to Vss pin via a capacitor (0.47 to 1  $\mu$ F).
- Caution 2. Make the AVss pin the same potential as the Vss pin.
- Caution 3. Make the AVDD pin the same potential as the VDD pin.
- Remark 1. For pin identification, see 1.4 Pin Identification.
- **Remark 2.** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection registers 0 to 3 (PIOR0 to PIOR3).

# 1.4 Pin Identification

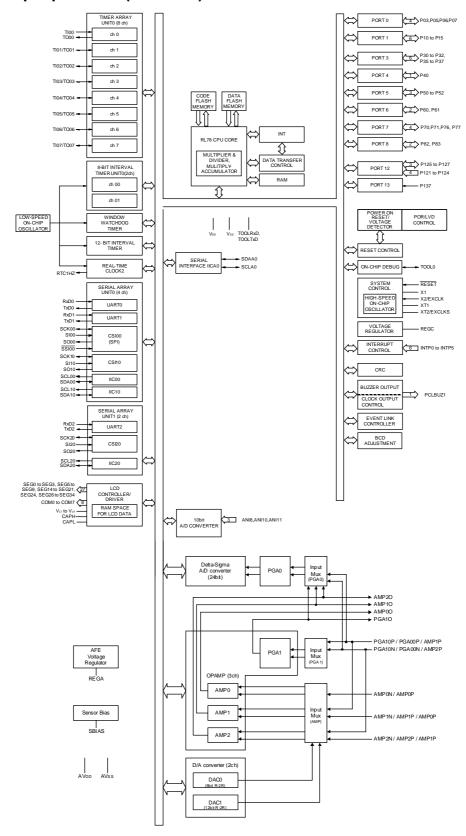
| AMP0N to AMP2N   | :OP AMP Negative Input      | REGA                      | :Regulator Capacitance for  |
|------------------|-----------------------------|---------------------------|-----------------------------|
| AMP0P to AMP2P   | :OP AMP Positive Input      |                           | Analog                      |
| AMP0O to AMP2O   | :OP AMP Output              | REGC                      | :Regulator Capacitance      |
| ANI8 to ANI14    | :Analog Input               | SBIAS                     | :Reference Voltage Output   |
| AVDD             | :Analog Power Supply        | RESET                     | :Reset                      |
| AVss             | :Analog Ground              | RTC1HZ                    | :Real-time Clock Correction |
| CAPH, CAPL       | :Capacitor for LCD          | RxD0 to RxD2, RxDMG0      | :Receive Data               |
| COM0 to COM7     | :LCD Common Output          | SCK00, SCK10, SCK20,      | :Serial Clock Input/Output  |
| EXCLK            | :External Clock Input       | SCLA0                     | :Serial Clock Input/Output  |
|                  | (Main System Clock)         | SCL00, SCL10, SCL20       | :Serial Clock Output        |
| EXCLKS           | :External Clock Input       | SDAA0, SDA00, SDA10,      | :Serial Data Input/Output   |
|                  | (Sub System Clock)          | SDA20                     |                             |
| EXSDI0, EXSDI1   | :External Sampling Input    | SEG0 to SEG35             | :LCD Segment Output         |
| EXSDO0, EXSDO1   | :External Sampling Clock    | SI00, SI10, SI20          | :Serial Data Input          |
|                  | Output                      | SO00, SO10, SO20          | :Serial Data Output         |
| INTP0 to INTP7   | :External Interrupt Input   | SSI00                     | :Slave Select Input         |
| P01 to P07       | :Port 0                     | SMP0 to SMP5              | :Sampling Input             |
| P10 to P17       | :Port 1                     | SMO0 to SMO2              | :Sampling Clock Output      |
| P20 to P27       | :Port 2                     | TI00 to TI07              | :Timer Input                |
| P30 to P32,      | :Port 3                     | TO00 to TO07,TRJO0, TRJO1 | :Timer Output               |
| P35 to P37       |                             | TOOL0                     | :Data Input/Output for Tool |
| P40, P43, P44    | :Port 4                     | TOOLRxD, TOOLTxD          | :Data Input/Output for      |
| P50 to P53       | :Port 5                     |                           | External Device             |
| P60 to P61       | :Port 6                     | TRJIO0, TRJIO1            | :Timer Input/Output         |
| P70 to P77       | :Port 7                     | TxD0 to TxD2, TxDMG0      | :Transmit Data              |
| P80 to P86       | :Port 8                     | VDD                       | :Power Supply               |
| P121 to P127     | :Port 12                    | VL1 to VL4                | :LCD Power Supply           |
| P137             | :Port 13                    | Vss                       | :Ground                     |
| P150, P151       | :Port 15                    | X1, X2                    | :Crystal Oscillator         |
| PCLBUZ0, PCLBUZ1 | :Programmable Clock Output/ |                           | (Main System Clock)         |
|                  | Buzzer Output               | XT1, XT2                  | :Crystal Oscillator         |
| PGA00N, PGA01N   | :PGA Negative Input         |                           | (Subsystem Clock)           |
| PGA10N, PGA11N   |                             |                           |                             |
| PGA00P, PGA01P   | :PGA Positive Input         |                           |                             |
| PGA10P, PGA11P   |                             |                           |                             |
| PGA1O            | :PGA Output                 |                           |                             |
|                  | ·                           |                           |                             |

# 1.5 Block Diagram

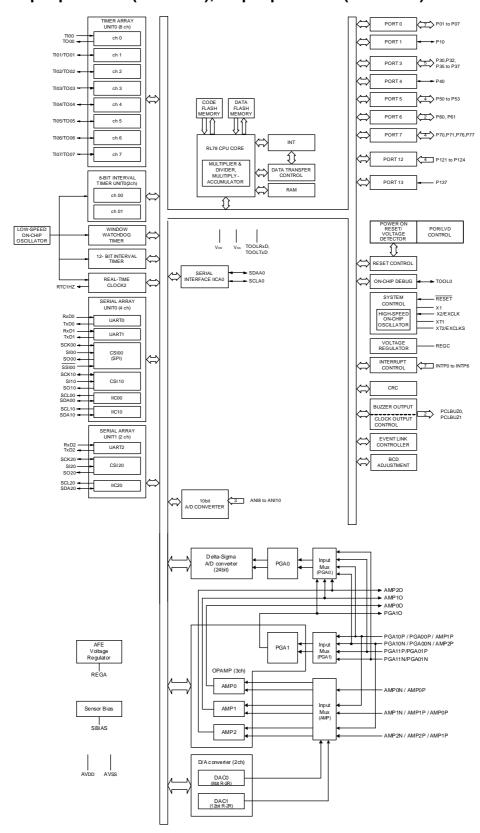
# 1.5.1 80-pin products (R5F11NM)



# 1.5.2 64-pin products (R5F11NL)

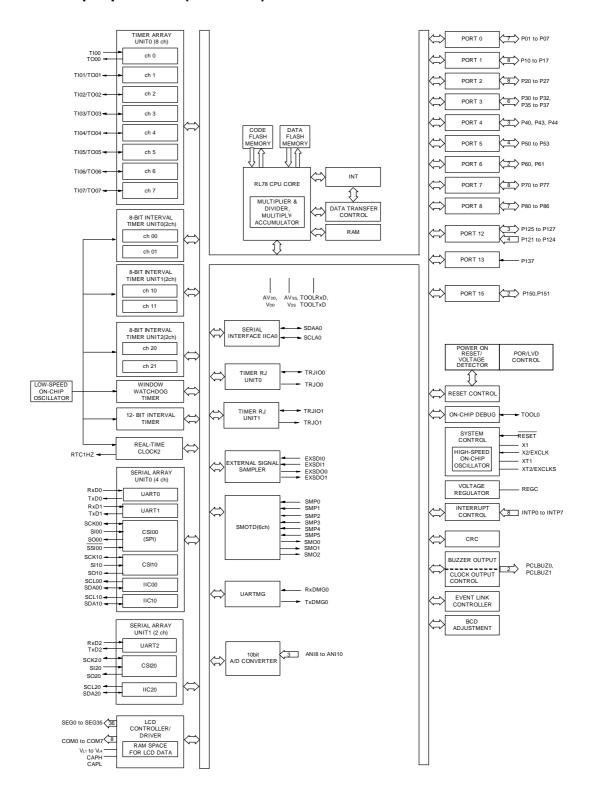


# 1.5.3 64-pin products (R5F11PL), 48-pin products (R5F11NG)



**Remark** 64-pin products (R5F11PL) have the same functionality as 48-pin products (R5F11NG). The only difference is the package.

# 1.5.4 80-pin products (R5F11RM)



# 1.6 Outline of Functions

(1/3)

|                      |  | 80-pin LFQFP   | 64-pin LFQFP           | 64-pin TFBGA<br>48-pin LFQFP   | 80-pin LFQFP   |  |
|----------------------|--|--|------------------------|--|--|--|
|                      | Item                                   | R5F11NMx<br>(x = E to G)   | R5F11NLx<br>(x = F, G) | R5F11PLx,<br>R5F11NGx<br>(x = F, G)  | R5F11RMG   |  |
| Code flash memory    | (KB)                                   | 64 to 128  | 96 to 128              | 96 to 128  | 128  |  |
| Data flash memory (  | KB)                                    | 4  | 4                      | 4  | 4  |  |
| RAM (KB)             |  | 5.5  | 5.5                    | 5.5  | 8  |  |
| Memory space         |  | 1 MB   | 1                      | •  |  |  |
| Main system clock    | High-speed system clock                | X1 (crystal/ceram  | nic) oscillation, exte | ernal main system  | clock input (EXCLK)  |  |
|                      |  | 1 to 20 MHz: VDD<br>1 to 8 MHz: VDD  |                        |  | 1 to 20 MHz: VDD = 2.7 to 5.5 V,<br>1 to 8 MHz: VDD = 1.8 to 2.7 V           |  |
|                      | High-speed on-chip oscillator clock    | (VDD = 2.7  to  5.5)   | nain) operation mo     | HS (high-speed main) operation mode:  1 to 24 MHz (VDD = 2.7 to 5.5 V),  HS (high-speed main) operation mode:  1 to 16 MHz (VDD = 2.4 to 5.5 V),  LS (low-speed main) operation mode:  1 to 8 MHz (VDD = 1.8 to 5.5 V) |  |  |
| Subsystem clock      |  | XT1 (crystal) osc  | illation, external su  | bsystem clock inp  | ut (EXCLKS)  |  |
|                      |  | 32.768 kHz (TYP.): VDD = 2.4 to 5.5 V  |                        |  | 32.768 kHz (TYP.): VDD = 1.8 to 5.5 V<br>38.4 kHz (TYP.): VDD = 1.8 to 5.5 V |  |
| Low-speed on-chip of | scillator clock                        | 15 kHz (TYP.): VDD = 2.4 to 5.5 V 15 kHz (TYP.): VDD = 1.8 to 5.5 V  |                        |  |  |  |
| General-purpose reg  | ister                                  | 8 bits × 32 registers (8 bits × 8 registers × 4 banks)   |                        |  |  |  |
| Minimum instruction  | execution time                         | 0.04167 µs (High   | -speed on-chip os      | cillator clock: fIH =  | 24 MHz operation)  |  |
|                      |  | 0.05 µs (High-spe  | eed system clock:      | fmx = 20 MHz oper  | ration)  |  |
|                      |  | 30.5 µs (Subsysto  | em clock: fSUB = 3     | 2.768 kHz operation  | on)  |  |
| Instruction set      |  | <ul> <li>Data transfer (8/16 bits)</li> <li>Adder and subtractor/logical operation (8/16 bits)</li> <li>Multiplication (8 bits x 8 bits, 16 bits x 16 bits), Division (16 bits ÷ 16 bits, 32 bits ÷ 32 bits)</li> <li>Multiplication and Accumulation (16 bits x 16 bits + 32 bits)</li> <li>Rotate, barrel shift, and bit manipulation (Set, reset, test, and Boolean operation), etc.</li> </ul> |                        |  |  |  |
| I/O port             | Total                                  | 53   | 36                     | 29   | 63   |  |
|                      | CMOS I/O                               | 46   | 29                     | 22   | 56   |  |
|                      | CMOS input                             | 5  | 5                      | 5  | 5  |  |
|                      | CMOS output                            | _  | _                      | _  | _  |  |
|                      | N-ch open-drain I/O<br>(6 V tolerance) | 2  | 2                      | 2  | 2  |  |

(2/3)

|  |  |   |  |   | (2/3)  |  |
|--|--|---|--|---|--|--|
|  |  | 80-pin LFQFP  | 64-pin LFQFP   | 64-pin TFBGA<br>48-pin LFQFP  | 80-pin LFQFP   |  |
|  | Item   | R5F11NMx<br>(x = E to G)  | R5F11NLx<br>(x = F, G)   | R5F11PLx,<br>R5F11NGx<br>(x = F, G)   | R5F11RMG   |  |
| Timer  | 16-bit timer TAU                               | 8 channels (Time  | r outputs: 8, PWM  | outputs: 7 Note 1)  |  |  |
|  | 8-bit or 16-bit interval timer                 | 2 channels (8 bits  | s)/1 channel (16 bi  | ts)   | 6 channels (8 bits)/3 channels (16 bits)   |  |
|  | Watchdog timer                                 | 1 channel   |  |   |  |  |
|  | 12-bit interval timer                          | 1 channel   |  |   |  |  |
|  | Real-time clock 2                              | 1 channel   |  |   |  |  |
|  | RTC output                                     | 1<br>1 Hz (subsystem  | clock: fSUB = 32.7   | 68 kHz)   |  |  |
|  | 16-bit timer RJ                                |   | _  |   | 2 channels, timer outputs: 2   |  |
|  | External signal sampler                        |   | _  |   | 1 channel  |  |
|  | Sampling output timer detector (SMOTD)         |   | _  |   | Input: 6 channels<br>Output: 3 channels  |  |
| Clock output/buzzer                                | output   | 2   | 1  | 2   | 2  |  |
|  |  | (Main system c<br>• 256 Hz, 512 Hz  | lock: fmain = 20 Mi  | 8 kHz, 4.096 kHz, 8   | 5 MHz, 10 MHz<br>3.192 kHz, 16.384 kHz, 32.768 kHz   |  |
| 8/10-bit resolution                                | Internal                                       | 3 channels  |  |   |  |  |
| A/D converter                                      | External                                       | 2 channels: Internal reference voltage (1.45 V), temperature sensor output voltage (only selectable in HS (high-speed main) mode) |  |   |  |  |
| 24-bit $\Delta\Sigma$ A/D conveinstrumentation amp | rter with programmable gain<br>lifier 0 (PGA0) | Analog input:<br>1 channel<br>(differential or<br>single-ended)   | Analog input:<br>1 channel<br>(differential or<br>single-ended),<br>3 channels<br>(single-ended) | Analog input:<br>2 channels<br>(differential or<br>single-ended),<br>3 channels<br>(single-ended) | _  |  |
| D/A converter                                      | 12-bit   | -   | 1 channel (with<br>an output<br>amplifier but no<br>external output<br>pin)                      | 1 channel (with<br>an output<br>amplifier but no<br>external output<br>pin)                       | _  |  |
|  | 8-bit  | 1 channel<br>(without an<br>output amplifier<br>and no external<br>output pin)  | 1 channel<br>(without an<br>output amplifier<br>and no external<br>output pin)                   | 1 channel<br>(without an<br>output amplifier<br>and no external<br>output pin)                    | _  |  |
| Programmable gain (PGA1)                           | instrumentation amplifier 1                    | _   | 1 channel  | 1 channel   | _  |  |
| Rail-to-rail operation                             | al amplifier                                   | 1 channel   | 1 channel  | 1 channel   |  |  |
| General-purpose op                                 | erational amplifier                            | _   | 2 channels   | 2 channels  |  |  |
| Serial interface                                   |  | I <sup>2</sup> C: 1 channel • Simplified SPI(0  | CSI): 1 channel/UA   | ART: 1 channel/sim  | RT (LIN-bus supported): 1 channel/simplified applified I <sup>2</sup> C: 1 channel applified I <sup>2</sup> C: 1 channel |  |
|  | I <sup>2</sup> C bus                           |   | 1 channel  |   | 1 channel  |  |
|  | Serial interface UARTMG                        |   | _  |   | 1 channel  |  |

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|                             |                       | 80-pin LFQFP  | 64-pin LFQFP  | 64-pin TFBGA<br>48-pin LFQFP                      | 80-pin LFQFP   |  |  |  |
|-----------------------------|-----------------------|---|---|---|--|--|--|--|
|                             | Item                  | R5F11NMx<br>(x = E to G)  | R5F11NLx<br>(x = F, G)  | R5F11PLx,<br>R5F11NGx<br>(x = F, G)               | R5F11RMG   |  |  |  |
| LCD controller/driver       |                       | Internal voltage bare switchable.   | nternal voltage boosting method, capacitor split method, and external resistance division method are switchable.        |   |  |  |  |  |
|                             | Segment signal output | 36 (32) Note 2  | 27 (23) Note 2  | _   | 36 (32) Note 2   |  |  |  |
|                             | Common signal output  | 4 (8) Note 2  | 4 (8) Note 2  | _   | 4 (8) Note 2   |  |  |  |
| Data transfer control       | ler (DTC)             | 26 sources  | 24 sources  | 25 sources  | 35 sources   |  |  |  |
| Event link controller (ELC) |                       | Event input: 20,<br>Event trigger<br>output: 7  | Event input: 18,<br>Event trigger<br>output: 10   | Event input: 19,<br>Event trigger<br>output: 10   | Event input: 26, Event trigger output: 5   |  |  |  |
| Vectored interrupt          | Internal              | 29  | 29  | 29  | 43   |  |  |  |
| sources                     | External              | 8   | 6   | 7   | 8  |  |  |  |
| Reset                       |                       | <ul><li>Internal reset b</li><li>Internal reset b</li><li>Internal reset b</li><li>Internal reset b</li></ul> | ET pin y watchdog timer y power-on-reset y voltage detector y illegal instruction y RAM parity error y illegal-memory a |   |  |  |  |  |
| Power-on-reset circu        | iit                   | Power-on-reser     Power-down-re  | t: 1.51 ±0.04 V<br>eset: 1.50 ±0.04 V   |   |  |  |  |  |
| Voltage detector            |                       |   | 50 V to 4.06 V (9 s<br>.45 V to 3.98 V (9 s   | • ,   | Rising edge: 1.88 V to 4.06 V (12 stages)     Falling edge: 1.84 V to 3.98 V (12 stages) |  |  |  |
| On-chip debug funct         | ion                   | Provided  |   |   |  |  |  |  |
| Power supply voltage        |                       | ,   | V<br>converter: 2.4 to 5.<br>alog front-end (AF   |   | VDD = 1.8 to 5.5 V   |  |  |  |
| Operating ambient to        | emperature            | TA = -40 to +85°0   | C (A: Consumer ap   | TA = -40 to +85°C<br>(D: Industrial applications) |  |  |  |  |

- **Note 1.** The number of outputs depends on the setting of channels in use and the number of the master.
- **Note 2.** The number in parentheses indicates the number of signal outputs when 8 coms are used.
- Note 3. The illegal instruction is generated when instruction code FFH is executed.

  Reset by the illegal instruction execution not is issued by emulation with the in-circuit emulator or on-chip debug emulator.

# 2. ELECTRICAL SPECIFICATIONS (R5F11N, R5F11P) (A: TA = -40 to +85°C)

This chapter describes the electrical specifications for the products A: Consumer applications (TA = -40 to +85°C).

- Caution 1. The RL78 microcontroller has an on-chip debug function, which is provided for development and evaluation. Do not use the on-chip debug function in products designated for mass production, because the guaranteed number of rewritable times of the flash memory may be exceeded when this function is used, and product reliability therefore cannot be guaranteed. Renesas Electronics is not liable for problems occurring when the on-chip debug function is used.
- Caution 2. The pins mounted depend on the product. Refer to 2.1 Port Function to 2.2 Functions other than port pins in the User's Manual: Hardware.



## 2.1 Absolute Maximum Ratings

### **Absolute Maximum Ratings**

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| Parameter              | Symbols | Conditions  | Ratings                       | Unit |
|------------------------|---------|---|-------------------------------|------|
| Supply voltage         | Vdd     |   | -0.5 to +6.5                  | V    |
|                        | AVDD    | AVDD = VDD  | -0.5 to +6.5                  | V    |
|                        | AVss    | AVss = Vss  | -0.5 to +0.3                  | V    |
| REGC pin input voltage | VIREGC  | REGC  | -0.3 to +2.8                  | V    |
|                        |         |   | and -0.3 to VDD + 0.3 Note 1  |      |
| REGA pin input voltage | VIREGA  | REGA  | -0.3 to +2.8                  | ٧    |
|                        |         |   | and -0.3 to AVDD + 0.3 Note 2 |      |
| Input voltage          | VI1     | P01 to P07, P10 to P17, P30 to P32, P35 to P37, P40, P43, P44, P50 to P53, P70 to P77, P80 to P86, P121 to P124, P125 to P127, P137, EXCLK, EXCLKS, RESET | -0.3 to VDD + 0.3 Note 3      | V    |
|                        | VI2     | P60, P61 (N-ch open-drain)  | -0.3 to +6.5                  | V    |
| Output voltage         | VO1     | P01 to P07, P10 to P17, P30 to P32, P35 to P37, P40, P43, P44, P50 to P53, P60, P61, P70 to P77, P80 to P86, P125 to P127                                 | -0.3 to VDD + 0.3 Note 3      | V    |
| Analog input voltage   | VAI1    | ANI8 to ANI11   | -0.3 to VDD + 0.3 Note 3      | V    |
|                        | VAI2    | ANI12 to ANI14 PGA00P, PGA01P, PGA10P, PGA11P, PGA00N, PGA01N, PGA10N, PGA11N, AMP0P to AMP2P, AMP0N to AMP2N   | -0.3 to AVDD + 0.3 Note 3     | V    |
| Analog output voltage  | Voa     | SBIAS, PGA1O, AMP0O to AMP2O  | -0.3 to AVDD + 0.3 Note 3     | V    |

- Note 1. Connect the REGC pin to Vss via a capacitor (0.47 to 1  $\mu$ F). This value regulates the absolute maximum rating of the REGC pin. Do not use this pin with voltage applied to it.
- **Note 2.** Connect the REGA pin to AVss via a capacitor (0.22 μF). This value regulates the absolute maximum rating of the REGA pin. Do not use this pin with voltage applied to it.
- Note 3. Must be 6.5 V or lower.

Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter.

That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

- Remark 1. Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.
- Remark 2. The reference voltage is Vss (for the VDD systems) = AVss (for the AVDD systems)

### **Absolute Maximum Ratings**

(2/3)

| Parameter   | Symbols        |  | Conditions                          | Ratings                      | Unit |
|-------------|----------------|--|-------------------------------------|------------------------------|------|
| LCD voltage | VLI1           | V <sub>L1</sub> input voltage <sup>I</sup> | Note 1                              | -0.3 to +2.8                 | V    |
|             | VLI2           | VL2 input voltage                          | Note 1                              | -0.3 to +6.5                 | V    |
|             | VLI3           | VL3 input voltage                          | Note 1                              | -0.3 to +6.5                 | V    |
|             | VLI4           | V <sub>L4</sub> input voltage <sup>I</sup> | Note 1                              | -0.3 to +6.5                 | V    |
|             | VLI5           | CAPL, CAPH inpu                            | ıt voltage <sup>Note 1</sup>        | -0.3 to +6.5                 | V    |
|             | VLO1           | VL1 output voltage                         | 9                                   | -0.3 to +2.8                 | V    |
|             | VLO2           | VL2 output voltage                         | 3                                   | -0.3 to +6.5                 | V    |
|             | VLO3           | VL3 output voltage                         | 3                                   | -0.3 to +6.5                 | V    |
|             | VLO4           | VL4 output voltage                         | )                                   | -0.3 to +6.5                 | V    |
|             | VLO5           | CAPL, CAPH outp                            | out voltage                         | -0.3 to +6.5                 | V    |
|             | VLO6           | COM0 to COM7<br>SEG0 to SEG35              | External resistance division method | -0.3 to VDD + 0.3<br>Note 2  | V    |
|             | output voltage |  | Capacitor split method              | -0.3 to VDD + 0.3<br>Note 2  | V    |
|             |                |  | Internal voltage boosting method    | -0.3 to VLI4 + 0.3<br>Note 2 | V    |

- Note 1. This value only indicates the absolute maximum ratings when applying voltage to the VL1, VL2, VL3, and VL4 pins; it does not mean that applying voltage to these pins is recommended. When using the internal voltage boosting method or capacitance split method, connect these pins to Vss via a capacitor (0.47 μF ± 30%) and connect a capacitor (0.47 μF ± 30%) between the CAPL and CAPH pins.
- Note 2. Must be 6.5 V or lower.
- Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

## **Absolute Maximum Ratings**

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| Parameter            | Symbols |                 | Conditions   | Ratings     | Unit |
|----------------------|---------|-----------------|--|-------------|------|
| Output current, high | Іон1    | Per pin         |  | -40         | mA   |
|                      |         | Total of all    | P40, P43, P44, P80 to P83  | -70         | mA   |
|                      |         | pins<br>-170 mA | P01 to P07, P10 to P17, P30 to P32, P35 to P37, P50 to P53, P70 to P77, P84 to P86, P125 to P127           | -100        | mA   |
| Output current, low  | IOL1    | Per pin         |  | 40          | mA   |
|                      |         | Total of all    | P40, P43, P44, P80 to P83  | 70          | mA   |
|                      |         | pins<br>170 mA  | P01 to P07, P10 to P17, P30 to P32, P35 to P37, P50 to P53, P60, P61, P70 to P77, P84 to P86, P125 to P127 | 100         | mA   |
| Operating ambient    | TA      | In normal c     | pperation mode   | -40 to +85  | °C   |
| temperature          |         | In flash me     | mory programming mode  |             |      |
| Storage temperature  | Tstg    |                 |  | -65 to +150 | °C   |

Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

### 2.2 Oscillator Characteristics

## 2.2.1 X1 and XT1 oscillator characteristics

### $(TA = -40 \text{ to } +85^{\circ}\text{C}, 2.4 \text{ V} \le \text{AVDD} = \text{VDD} \le 5.5 \text{ V}, \text{AVss} = \text{Vss} = 0 \text{ V})$

| Parameter                           | Resonator                           | Conditions          | MIN. | TYP.   | MAX. | Unit |
|-------------------------------------|-------------------------------------|---------------------|------|--------|------|------|
| X1 clock oscillation frequency (fx) | Ceramic resonator/crystal resonator | 2.7 V ≤ VDD ≤ 5.5 V | 1.0  |        | 20.0 | MHz  |
| Note                                |                                     | 2.4 V ≤ VDD < 2.7 V | 1.0  |        | 16.0 |      |
| XT1 clock oscillation frequency     | Crystal resonator                   |                     | 32   | 32.768 | 35   | kHz  |
| (fxr) Note                          |                                     |                     |      |        |      |      |

Note Indicates only permissible oscillator frequency ranges. Refer to AC Characteristics for instruction execution time.

Request evaluation by the manufacturer of the oscillator circuit mounted on a board to check the oscillator characteristics.

Caution Since the CPU is started by the high-speed on-chip oscillator clock after a reset release, check the X1 clock oscillation stabilization time using the oscillation stabilization time counter status register (OSTC) by the user.

Determine the oscillation stabilization time of the OSTC register and the oscillation stabilization time select register (OSTS) after sufficiently evaluating the oscillation stabilization time with the resonator to be used.

Remark When using the X1 and XT1 oscillator, refer to 5.4 System Clock Oscillator in the User's Manual: Hardware.

# 2.2.2 On-chip oscillator characteristics

(TA = -40 to +85°C, 2.4 V  $\leq$  AVDD = VDD  $\leq$  5.5 V, AVSS = VSS = 0 V)

| •   |        |                   |                     |      |    |      |      |
|---|--------|-------------------|---------------------|------|----|------|------|
| Oscillators   | Symbol |                   | Conditions          |      |    | MAX. | Unit |
| High-speed on-chip oscillator clock                   | fıн    | 2.7 V ≤ VDD ≤ 5.5 | 2.7 V ≤ VDD ≤ 5.5 V |      |    | 24   | MHz  |
| frequency Notes 1, 2                                  |        | 2.4 V ≤ VDD < 2.7 | 7 V                 | 1    |    | 16   | MHz  |
| High-speed on-chip oscillator clock                   |        | -20 to +85°C      | 2.4 V ≤ VDD ≤ 5.5 V | -1.0 |    | +1.0 | %    |
| frequency accuracy                                    |        | -40 to +85°C      | 2.4 V ≤ VDD ≤ 5.5 V | -1.5 |    | +1.5 | %    |
| Low-speed on-chip oscillator clock frequency          | fiL    |                   |                     |      | 15 |      | kHz  |
| nequency  |        |                   |                     |      |    |      |      |
| Low-speed on-chip oscillator clock frequency accuracy |        |                   |                     | -15  |    | +15  | %    |
| · ·   | 1      | I                 |                     | 1    | 1  |      | 1    |

**Note 1.** High-speed on-chip oscillator frequency is selected with bits 0 to 4 of the option byte (000C2H/010C2H) and bits 0 to 2 of the HOCODIV register.

Note 2. This only indicates the oscillator characteristics. Refer to AC Characteristics for instruction execution time.

### 2.3 DC Characteristics

## 2.3.1 Pin characteristics

 $(TA = -40 \text{ to } +85^{\circ}\text{C}, 2.4 \text{ V} \le \text{AVDD} = \text{VDD} \le 5.5 \text{ V}, \text{AVss} = \text{Vss} = 0 \text{ V})$ 

| Items                       | Symbol | Conditions   |  | MIN. | TYP. | MAX.              | Unit           |
|-----------------------------|--------|--|--|------|------|-------------------|----------------|
| Output current, high Note 1 | ІОН1   | Per pin for P01 to P07, P10 to P17,<br>P30 to P32, P35 to P37, P40, P43,<br>P44, P50 to P53, P70 to P77,<br>P80 to P86, P125 to P127 |  |      |      | -10.0<br>Note 2   | mA             |
|                             |        | Total of P40, P43, P44, P80 to P83<br>(When duty ≤ 70% Note 3)   | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}$<br>$2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}$<br>$2.4 \text{ V} \le \text{VDD} < 2.7 \text{ V}$     |      |      | -55<br>-10<br>-5  | mA<br>mA       |
|                             |        | Total of P01 to P07, P10 to P17, P30 to P32, P35 to P37, P50 to P53, P70 to P77, P84 to P86, P125 to P127 (When duty ≤ 70% Note 3)   | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}$<br>$2.7 \text{ V} \le \text{VDD} \le 4.0 \text{ V}$<br>$2.4 \text{ V} \le \text{VDD} \le 2.7 \text{ V}$ |      |      | -69<br>-23<br>-12 | mA<br>mA<br>mA |
|                             |        | Total of all pins (When duty ≤ 70% Note 3)   | 2.4 V ≤ VDD ≤ 5.5 V  |      |      | -124              | mA             |

- **Note 1.** Value of current at which the device operation is guaranteed even if the current flows from the VDD pin (IOH1) to an output pin.
- Note 2. However, do not exceed the total current value.
- **Note 3.** Specification under conditions where the duty factor  $\leq 70\%$ .

The output current value that has changed to the duty factor > 70% the duty ratio can be calculated with the following expression (when changing the duty factor from 70% to n%).

- Total output current of pins =  $(IOH \times 0.7)/(n \times 0.01)$ 
  - <Example> Where n = 80% and IOH = -10.0 mA

Total output current of pins = (-10.0 × 0.7)/(80 × 0.01)  $\cong$  -8.7 mA

However, the current that is allowed to flow into one pin does not vary depending on the duty factor. A current higher than the absolute maximum rating must not flow into one pin.

Caution P02 to P04, P06, P07, P10, P35 to P37, P40, P43, P44, P50 to P52, and P80 to P82 do not output high level in N-ch open-drain mode.

 $(TA = -40 \text{ to } +85^{\circ}C, 2.4 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$ 

| Items                      | Symbol | Conditions   |                     | MIN. | TYP. | MAX.           | Unit |
|----------------------------|--------|--|---------------------|------|------|----------------|------|
| Output current, low Note 1 | IOL1   | Per pin for P01 to P07, P10 to P17,<br>P30 to P32, P35 to P37, P40, P43,<br>P44, P50 to P53, P70 to P77,<br>P80 to P86, P125 to P127 |                     |      |      | 20.0<br>Note 2 | mA   |
|                            |        | Per pin for P60 and P61  |                     |      |      | 15.0<br>Note 2 | mA   |
|                            |        | Total of P40, P43, P44, P80 to P83   | 4.0 V ≤ VDD ≤ 5.5 V |      |      | 70             | mA   |
|                            |        | (When duty ≤ 70% Note 3)   | 2.7 V ≤ VDD < 4.0 V |      |      | 15             | mA   |
|                            |        |  | 2.4 V ≤ VDD < 2.7 V |      |      | 9              | mA   |
|                            |        | P01 to P07, P10 to P17, P30 to P32,  | 4.0 V ≤ VDD ≤ 5.5 V |      |      | 90             | mA   |
|                            |        | P35 to P37, P50 to P53, P60, P61,  | 2.7 V ≤ VDD < 4.0 V |      |      | 35             | mA   |
|                            |        | P70 to P77, P84 to P86, P125 to P127   | 2.4 V ≤ VDD < 2.7 V |      |      | 20             | mA   |
|                            |        | (When duty ≤ 70% Note 3)   |                     |      |      |                |      |
|                            |        | Total of all pins<br>(When duty ≤ 70% <sup>Note 3</sup> )  |                     |      |      | 160            | mA   |

- Note 1. Value of current at which the device operation is guaranteed even if the current flows from an output pin to the Vss pin (IOL1).
- Note 2. However, do not exceed the total current value.
- **Note 3.** Specification under conditions where the duty factor  $\leq 70\%$ .

The output current value that has changed to the duty factor > 70% the duty ratio can be calculated with the following expression (when changing the duty factor from 70% to n%).

• Total output current of pins =  $(IOL \times 0.7)/(n \times 0.01)$ 

<Example> Where n = 80% and IOL = 10.0 mA

Total output current of pins =  $(10.0 \times 0.7)/(80 \times 0.01) \approx 8.7 \text{ mA}$ 

However, the current that is allowed to flow into one pin does not vary depending on the duty factor. A current higher than the absolute maximum rating must not flow into one pin.

 $(TA = -40 \text{ to } +85^{\circ}\text{C}, 2.4 \text{ V} \le \text{AVDD} = \text{VDD} \le 5.5 \text{ V}, \text{AVSS} = \text{VSS} = 0 \text{ V})$ 

| Items               | Symbol | Conditions   |   | MIN.    | TYP. | MAX.    | Unit |
|---------------------|--------|--|---|---------|------|---------|------|
| Input voltage, high | VIH1   | P01 to P07, P10 to P17, P30 to P32,<br>P35 to P37, P40, P43, P44, P50 to P53,<br>P70 to P77, P80 to P86, P125 to P127              | Normal input buffer                     | 0.8 VDD |      | VDD     | V    |
|                     | VIH2   | For TTL mode supported ports   | TTL input buffer<br>4.0 V ≤ VDD ≤ 5.5 V | 2.2     | VDD  | VDD     | V    |
|                     |        |  | TTL input buffer 3.3 V ≤ VDD < 4.0 V    | 2.0     |      | VDD     | V    |
|                     |        |  | TTL input buffer<br>2.4 V ≤ VDD < 3.3 V | 1.50    |      | VDD     | V    |
|                     | VIH4   | P60, P61   | 0.7 VDD                                 |         | 6.0  | V       |      |
|                     | VIH5   | P121 to P124, P137, EXCLK, EXCLKS,   | RESET                                   | 0.8 VDD |      | VDD     | V    |
| Input voltage, low  | VIL1   | P01 to P07, P10 to P17, P30 to P32,<br>P35 to P37, P40, P43, P44, P50 to P53,<br>P60, P61, P70 to P77, P80 to P86,<br>P125 to P127 | Normal input buffer                     | 0       |      | 0.2 VDD | V    |
|                     | VIL2   | For TTL mode supported ports   | TTL input buffer<br>4.0 V ≤ VDD ≤ 5.5 V | 0       |      | 0.8     | V    |
|                     |        |  | TTL input buffer 3.3 V ≤ VDD < 4.0 V    | 0       |      | 0.5     | V    |
|                     |        |  | TTL input buffer<br>2.4 V ≤ VDD < 3.3 V | 0       |      | 0.32    | V    |
|                     | VIL4   | P60, P61   | •                                       | 0       |      | 0.3 VDD | V    |
|                     | VIL5   | P121 to P124, P137, EXCLK, EXCLKS,   | RESET                                   | 0       |      | 0.2 VDD | V    |

Caution The maximum value of VIH of pins P02 to P04, P06, P07, P10, P35 to P37, P40, P43, P44, P50 to P52, and P80 to P82 is VDD, even in the N-ch open-drain mode.

(TA = -40 to +85°C, 2.4 V  $\leq$  AVDD = VDD  $\leq$  5.5 V, AVSS = VSS = 0 V)

| Items                | Symbol Conditions MIN. TY |  | TYP.   | MAX.      | Unit |     |   |
|----------------------|---------------------------|--|--|-----------|------|-----|---|
| Output voltage, high | VOH1                      | P01 to P07, P10 to P17, P30 to P32, P35 to P37, P40, P43, P44, | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V},$<br>10H = -10.0  mA | VDD - 1.5 |      |     | V |
|                      |                           | P50 to P53, P70 to P77, P80 to P86,<br>P125 to P127            | 4.0 V ≤ VDD ≤ 5.5 V,<br>IOH = -3.0 mA                                | VDD - 0.7 |      |     | V |
|                      |                           |  | $2.7 \text{ V} \le \text{VDD} \le 5.5 \text{ V},$<br>IOH = -2.0  mA  | VDD - 0.6 |      |     | V |
|                      |                           |  | $2.4 \text{ V} \le \text{VDD} \le 5.5 \text{ V},$<br>IOH = -1.5 mA   | , l       | V    |     |   |
| Output voltage, low  | VOL1                      | P01 to P07, P10 to P17, P30 to P32, P35 to P37, P40, P43, P44, | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V},$<br>IOL = 20.0  mA  |           | 1.3  | V   |   |
|                      |                           | P50 to P53, P70 to P77, P80 to P86, P125 to P127               | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V},$<br>IOL = 8.5  mA   |           |      | 0.7 | V |
|                      |                           |  | $2.7 \text{ V} \le \text{VDD} \le 5.5 \text{ V},$<br>IOL = 3.0  mA   |           |      | 0.6 | V |
|                      |                           |  | $2.7 \text{ V} \le \text{VDD} \le 5.5 \text{ V},$<br>IOL = 1.5  mA   |           |      | 0.4 | ٧ |
|                      |                           |  | $2.4 \text{ V} \le \text{VDD} \le 5.5 \text{ V},$<br>IOL = 0.6  mA   |           |      | 0.4 | V |
|                      | VOL3                      | P60, P61   | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V},$<br>IOL = 15.0  mA  |           |      | 2.0 | ٧ |
|                      |                           |  | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V},$<br>IOL = 5.0  mA   |           |      | 0.4 | ٧ |
|                      |                           |  | $2.7 \text{ V} \le \text{VDD} \le 5.5 \text{ V},$<br>IOL = 3.0  mA   |           |      | 0.4 | V |
|                      |                           |  | $2.4 \text{ V} \le \text{VDD} \le 5.5 \text{ V},$<br>IOL = 2.0  mA   |           |      | 0.4 | V |

Caution P02 to P04, P06, P07, P10, P35 to P37, P40, P43, P44, P50 to P52, and P80 to P82 do not output high level in N-ch open-drain mode.

(TA = -40 to +85°C, 2.4 V  $\leq$  AVDD = VDD  $\leq$  5.5 V, AVSS = VSS = 0 V)

| Items                          | Symbol | Conditio   | ns          |                                       | MIN. | TYP. | MAX. | Unit |
|--------------------------------|--------|--|-------------|---------------------------------------|------|------|------|------|
| Input leakage<br>current, high | ILIH1  | P01 to P07, P10 to P17, P30 to P32, P35 to P37, P40, P43, P44, P50 to P53, P60, P61, P70 to P77, P80 to P86, P125 to P127, P137, RESET | P, VI = VDD |                                       |      |      | 1    | μА   |
|                                | ILIH3  | P121 to P124 (X1, X2, EXCLK, XT1, XT2, EXCLKS)   | VI = VDD    | In input port or external clock input |      |      | 1    | μA   |
|                                |        |  |             | In resonator connection               |      |      | 10   | μA   |
| Input leakage<br>current, low  | ILIL1  | P01 to P07, P10 to P17, P30 to P32, P35 to P37, P40, P43, P44, P50 to P53, P60, P61, P70 to P77, P80 to P86, P125 to P127, P137, RESET | VI = VSS    |                                       |      |      | -1   | μА   |
|                                | ILIL3  | P121 to P124 (X1, X2, EXCLK, XT1, XT2, EXCLKS)   | VI = VSS    | In input port or external clock input |      |      | -1   | μA   |
|                                |        |  |             | In resonator connection               |      |      | -10  | μA   |
| On-chip pull-up resistance     | Ru1    | P01 to P07, P10 to P17, P30 to P32,<br>P35 to P37, P40, P43, P44,<br>P50 to P53, P70 to P77, P80 to P86,<br>P125 to P127               | VI = VSS    | or In input port                      | 10   | 20   | 100  | kΩ   |

## 2.3.2 Supply current characteristics

(TA = -40 to +85°C, 2.4 V  $\leq$  AVDD = VDD  $\leq$  5.5 V, AVSS = VSS = 0 V)

(1/2)

| Parameter       | Symbol |             |                                       | Conditions               |                      |                      | MIN. | TYP. | MAX. | Unit |
|-----------------|--------|-------------|---------------------------------------|--------------------------|----------------------|----------------------|------|------|------|------|
| Supply          | IDD1   | Operating   | HS                                    | fIH = 24 MHz Note 3      | Basic                | VDD = 5.0 V          |      | 1.7  |      | mA   |
| current         | mode e | mode        | (high-speed main)                     |                          | operation            | VDD = 3.0 V          |      | 1.7  |      |      |
| Notes 1, Note 6 |        |             | mode Note 5                           |                          | Normal operation     | VDD = 5.0 V          |      | 3.7  | 6.2  |      |
|                 |        |             |                                       |                          |                      | VDD = 3.0 V          |      | 3.7  | 6.2  |      |
|                 |        |             |                                       | fIH = 16 MHz Note 3      | Normal               | VDD = 5.0 V          |      | 2.8  | 4.8  |      |
|                 |        |             |                                       | operation                | VDD = 3.0 V          |                      | 2.8  | 4.8  |      |      |
|                 |        |             | HS                                    | fmx = 20 MHz Note 2,     | Normal               | Square wave input    |      | 3.1  | 5.2  | mA   |
|                 |        |             | (high-speed main)                     | VDD = 5.0 V              | operation            | Resonator connection |      | 3.3  | 5.3  |      |
|                 |        | mode Note 5 | tMX = 20 MHz Note 2,                  | Normal                   | Square wave input    |                      | 3.0  | 5.2  |      |      |
|                 |        | f           |                                       | operation                | Resonator connection |                      | 3.3  | 5.3  |      |      |
|                 |        |             | , , , , , , , , , , , , , , , , , , , | Normal                   | Square wave input    |                      | 2.6  | 4.5  |      |      |
|                 |        |             |                                       | Resonator connection     |                      | 2.8                  | 4.6  |      |      |      |
|                 |        |             | fmx = 16 MHz Note 2,                  | Normal                   | Square wave input    |                      | 2.6  | 4.5  |      |      |
|                 |        |             |                                       | VDD = 3.0 V              | operation            | Resonator connection |      | 2.8  | 4.6  |      |
|                 |        |             |                                       | , , ,                    | Normal               | Square wave input    |      | 1.9  | 3.0  |      |
|                 |        |             |                                       |                          | operation            | Resonator connection |      | 1.9  | 3.0  |      |
|                 |        |             |                                       | fmx = 10 MHz Note 2,     | Normal               | Square wave input    |      | 1.9  | 3.0  |      |
|                 |        |             |                                       | VDD = 3.0 V              | operation            | Resonator connection |      | 1.9  | 3.0  |      |
|                 |        |             | Subsystem clock                       | fSUB = 32.768 kHz Note 4 | Normal               | Square wave input    |      | 4.3  | 5.8  | μΑ   |
|                 |        |             | operation                             | TA = -40°C               | operation            | Resonator connection |      | 4.6  | 5.8  |      |
|                 |        |             |                                       | fSUB = 32.768 kHzNote 4  | Normal               | Square wave input    |      | 4.3  | 5.8  |      |
|                 |        |             |                                       | TA = +25°C               | operation            | Resonator connection |      | 4.6  | 5.8  |      |
|                 |        |             |                                       | fSUB = 32.768 kHzNote 4  | Normal               | Square wave input    |      | 4.5  | 7.6  |      |
|                 |        |             |                                       | TA = +50°C               | operation            | Resonator connection |      | 4.5  | 7.6  |      |
|                 |        |             | fsub = 32.768 kHz <sup>Note 4</sup>   | Normal                   | Square wave input    |                      | 4.7  | 9.2  |      |      |
|                 |        |             | TA = +70°C                            | operation                | Resonator connection |                      | 5.1  | 9.2  |      |      |
|                 |        |             |                                       | fSUB = 32.768 kHzNote 4  | Normal               | Square wave input    |      | 5.2  | 12.6 |      |
|                 |        |             |                                       | TA = +85°C               | operation            | Resonator connection |      | 5.7  | 12.6 |      |

- **Note 1.** Total current flowing into VDD, including the input leakage current flowing when the level of the input pin is fixed to VDD or Vss. The following points apply in the HS (high-speed main) mode.
  - •The currents in the "TYP." column do not include the operating currents of the peripheral modules.
  - •The currents in the "MAX." column include the operating currents of the peripheral modules, except for those flowing into the LCD controller/driver, A/D converter, LVD, I/O port, and on-chip pull-up/pull-down resistors, and those flowing while the data flash memory is being rewritten.

In the subsystem clock operation, the currents in both the "TYP." and "MAX." columns do not include the operating currents of the peripheral modules. However, in HALT mode, including the current flowing into the real-time clock 2. The current flowing into AFE is not included.

- Note 2. When high-speed on-chip oscillator and subsystem clock are stopped.
- **Note 3.** When high-speed system clock and subsystem clock are stopped.
- **Note 4.** When high-speed on-chip oscillator and high-speed system clock are stopped. When AMPHS1 = 1 (Ultra-low power consumption oscillation).
- **Note 5.** Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.

HS (high-speed main) mode:  $2.7 \text{ V} \le \text{VDD} \le 5.5 \text{ V} @ 1 \text{ MHz}$  to 24 MHz

 $2.4 \text{ V} \leq \text{VDD} \leq 5.5 \text{ V}@1 \text{ MHz}$  to 16 MHz

Note 6. IDD1 do not include the current flowing to the AFE.

The current value of the RL78 microcontrollers is the sum of IDD1, IDD2, or IDD3 and AFE current (AVDD systems) when the AFE operates in the operating mode, HALT mode, or STOP mode.

- Remark 1. fMX: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
- Remark 2. fil: High-speed on-chip oscillator clock frequency
- Remark 3. fSUB: Subsystem clock frequency (XT1 clock oscillation frequency)
- **Remark 4.** Except subsystem clock operation, temperature condition of the TYP. value is TA = 25°C.

## (TA = -40 to +85°C, 2.4 V $\leq$ AVDD = VDD $\leq$ 5.5 V, AVSS = VSS = 0 V)

(2/2)

| Parameter       | Symbol |           |                        | Conditions               |                      | MIN. | TYP. | MAX. | Unit |
|-----------------|--------|-----------|------------------------|--------------------------|----------------------|------|------|------|------|
| Supply          | IDD2   | HALT mode | HS (high-speed main)   | fIH = 24 MHz Note 4      | VDD = 5.0 V          |      | 0.42 | 1.83 | mA   |
| current         | Note 2 |           | mode Note 6            |                          | VDD = 3.0 V          |      | 0.42 | 1.83 |      |
| Notes 1, Note 8 |        |           |                        | fIH = 16 MHz Note 4      | VDD = 5.0 V          |      | 0.39 | 1.38 |      |
|                 |        |           |                        |                          | VDD = 3.0 V          |      | 0.39 | 1.38 |      |
|                 |        |           | HS (high-speed main)   | fmx = 20 MHz Note 3,     | Square wave input    |      | 0.26 | 1.55 | mA   |
|                 |        |           | mode Note 6            | VDD = 5.0 V              | Resonator connection |      | 0.40 | 1.68 |      |
|                 |        |           |                        | fmx = 20 MHz Note 3,     | Square wave input    |      | 0.25 | 1.55 |      |
|                 |        |           |                        | VDD = 3.0 V              | Resonator connection |      | 0.40 | 1.68 |      |
|                 |        |           |                        | fmx = 16 MHz Note 3,     | Square wave input    |      | 0.23 | 1.22 |      |
|                 |        |           |                        | VDD = 5.0 V              | Resonator connection |      | 0.36 | 1.39 |      |
|                 |        |           |                        | fmx = 16 MHz Note 3,     | Square wave input    |      | 0.22 | 1.22 |      |
|                 |        |           |                        | VDD = 3.0 V              | Resonator connection |      | 0.35 | 1.39 |      |
|                 |        |           |                        | fmx = 10 MHz Note 3,     | Square wave input    |      | 0.19 | 0.82 |      |
|                 |        |           | VDD = 5.0 V            | Resonator connection     |                      | 0.29 | 0.90 |      |      |
|                 |        |           |                        | fmx = 10 MHz Note 3,     | Square wave input    |      | 0.18 | 0.82 |      |
|                 |        |           |                        | VDD = 3.0 V              | Resonator connection |      | 0.28 | 0.90 |      |
|                 |        |           | Subsystem clock        | fSUB = 32.768 kHz Note 5 | Square wave input    |      | 0.32 | 0.69 | μΑ   |
|                 |        |           | operation              | TA = -40°C               | Resonator connection |      | 0.51 | 0.89 |      |
|                 |        |           |                        | fSUB = 32.768 kHz Note 5 | Square wave input    |      | 0.41 | 0.82 |      |
|                 |        |           |                        | TA = +25°C               | Resonator connection |      | 0.62 | 1.00 |      |
|                 |        |           |                        | fSUB = 32.768 kHz Note 5 | Square wave input    |      | 0.52 | 1.40 |      |
|                 |        |           |                        | TA = +50°C               | Resonator connection |      | 0.75 | 1.60 |      |
|                 |        |           |                        | fSUB = 32.768 kHz Note 5 | Square wave input    |      | 0.82 | 2.70 |      |
|                 |        |           |                        | TA = +70°C               | Resonator connection |      | 1.08 | 2.90 |      |
|                 |        |           |                        | fsub = 32.768 kHz Note 5 | Square wave input    |      | 1.38 | 4.95 |      |
|                 |        |           |                        | TA = +85°C               | Resonator connection |      | 1.62 | 5.15 |      |
|                 | IDD3   | STOP mode | TA = -40°C             |                          |                      |      | 0.20 | 0.59 | μΑ   |
|                 |        | Note 7    | T <sub>A</sub> = +25°C |                          |                      |      | 0.26 | 0.72 |      |
|                 |        |           | T <sub>A</sub> = +50°C |                          |                      |      | 0.33 | 1.30 |      |
|                 |        |           | T <sub>A</sub> = +70°C |                          |                      |      | 0.53 | 2.60 |      |
|                 |        |           | T <sub>A</sub> = +85°C |                          |                      |      | 0.93 | 4.85 |      |

(Notes and Remarks are listed on the next page.)

- **Note 1.** Total current flowing into VDD, including the input leakage current flowing when the level of the input pin is fixed to VDD or Vss. The following points apply in the HS (high-speed main) mode.
  - •The currents in the "TYP." column do not include the operating currents of the peripheral modules.
  - •The currents in the "MAX." column include the operating currents of the peripheral modules, except for those flowing into the LCD controller/driver, A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors, and those flowing while the data flash memory is being rewritten.

In the subsystem clock operation, the currents in both the "TYP." and "MAX." columns do not include the operating currents of the peripheral modules. However, in HALT mode, including the current flowing into the real-time clock 2. In the STOP mode, the currents in both the "TYP." and "MAX." columns do not include the operating currents of the peripheral modules. The current flowing into AFE is not included.

- Note 2. During HALT instruction execution by flash memory.
- Note 3. When high-speed on-chip oscillator and subsystem clock are stopped.
- Note 4. When high-speed system clock and subsystem clock are stopped.
- Note 5. When high-speed on-chip oscillator and high-speed system clock are stopped. When RTCLPC = 1 and setting ultra-low current consumption (AMPHS1 = 1).
- Note 6. Relationship between operation voltage width, operation frequency of CPU and operation mode is as below. HS (high-speed main) mode:  $2.7 \text{ V} \le \text{VDD} \le 5.5 \text{ V} @ 1 \text{ MHz}$  to 24 MHz  $2.4 \text{ V} \le \text{VDD} \le 5.5 \text{ V} @ 1 \text{ MHz}$  to 16 MHz
- Note 7. Regarding the value for current to operate the subsystem clock in STOP mode, refer to that in HALT mode.
- Note 8. IDD2 and IDD3 do not include the current flowing to the AFE.

  The current value of the RL78 microcontrollers is the sum of IDD1, IDD2, or IDD3 and AFE current (AVDD systems) when the AFE operates in the operating mode, HALT mode, or STOP mode.
- Remark 1. fmx: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
- Remark 2. fil: High-speed on-chip oscillator clock frequency
- Remark 3. fSUB: Subsystem clock frequency (XT1 clock oscillation frequency)
- Remark 4. Except subsystem clock operation, temperature condition of the TYP. value is TA = 25°C.

## • Peripheral functions

# (TA = -40 to +85°C, 2.4 V $\leq$ AVDD = VDD $\leq$ 5.5 V, AVSS = VSS = 0 V)

| Parameter   | Symbol                 |                                     | Condition  | ns                                     |   | MIN. | TYP.      | MAX.                 | Unit |
|---|------------------------|-------------------------------------|--|--|---|------|-----------|----------------------|------|
| Low-speed on-chip oscillator operating current    | IFIL Note 1            |                                     |  |  |   |      | 0.20      |                      | μА   |
| RTC2 operating current                            | IRTC<br>Notes 1, 3     | fsub = 32.768 kHz                   |  |  |   |      | 0.02      |                      | μA   |
| 12-bit interval timer operating current           | ITMKA<br>Notes 1, 2, 4 | fsub = 32.768 kHz                   | MAIN stopped, per unit  8-bit counter mode × 2-channe operation  16-bit counter mode operation  Maximum speed  Normal mode, VDD = 5.0 V  Low-voltage mode, VDD = 3.0  The mode is performed  During A/D conversion,  low-voltage mode, VDD = 3.0 V  JART operation  1/3 bias  VDD = 5.0 V, |  |   |      | 0.02      |                      | μA   |
| 8-bit interval timer operating current            | ITMRT<br>Notes 1, 14   | fsub = 32.768 kHz                   | fMAIN stopped, per unit  |  | mode x 2-channel                            |      | 0.12      |                      | μА   |
|   |                        |                                     |  | 16-bit counte                          | er mode operation                           |      | 0.10      |                      | μA   |
| Watchdog timer operating current                  | IWDT<br>Notes 1, 5     | fiL = 15 kHz                        |  |  |   |      | 0.22      |                      | μA   |
| A/D converter                                     | IADC                   | When conversion a                   | at maximum speed   | naximum speed Normal mode, VDD = 5.0 V |   |      |           | 1.7                  | mA   |
| operating current                                 | Notes 1, 6             |                                     |  | Low-voltage                            | mode, VDD = 3.0 V                           |      | 0.5       | 0.7                  | mA   |
| Internal reference<br>voltage (1.45 V)<br>current | IADREF<br>Notes 1, 7   |                                     |  |  |   |      | 85        |                      | μА   |
| Temperature sensor operating current              | ITMPS Note 1           |                                     |  |  |   |      | 85        |                      | μА   |
| LVD operating current                             | ILVI<br>Notes 1, 8     |                                     |  |  |   |      | 0.06      |                      | μΑ   |
| Self-programming operating current                | IFSP<br>Notes 1, 9     |                                     |  |  |   |      | 2.0       | 12.2                 | mA   |
| BGO operating current                             | IBGO<br>Notes 1, 10    |                                     |  |  |   |      | 2.0       | 12.2                 | mA   |
| SNOOZE  | Isnoz                  | A/D converter oper                  | ation  | The mode is                            | performed                                   |      | 0.50      | 0.60                 | mA   |
| operating current                                 | Notes 1, 11            |                                     |  | _                                      |   |      | 1.20      | 1.44                 |      |
|   |                        | Simplified SPI(CSI                  | )/UART operation   | 1                                      |   |      | 0.70      | 12.2<br>12.2<br>0.60 | mA   |
|   |                        | DTC operation                       |  |  |   |      | 3.1       |                      | mA   |
| LCD operating current                             | ILCD1<br>Notes 12, 13  | External resistance division method | fLCD = fSUB<br>LCD clock = 128 Hz  |  | •   |      | 0.04      | 0.20                 | μА   |
|   | ILCD2<br>Note 12       | Internal voltage boosting method    | fLCD = fSUB<br>LCD clock = 128 Hz  | 1/3 bias<br>4-time slice               | VDD = 3.0 V,<br>VL4 = 3.0 V<br>(VLCD = 04H) |      | 0.85 2.20 | 2.20                 | μA   |
|   |                        |                                     |  |  | VDD = 5.0 V,<br>VL4 = 5.1 V<br>(VLCD = 04H) |      | 1.55      | 3.70                 | μА   |
|   | ILCD3<br>Note 12       | Capacitor split method              | fLCD = fSUB<br>LCD clock = 128 Hz  | 1/3 bias<br>4-time slice               | VDD = 3.0 V,<br>VL4 = 3.0 V                 |      | 0.20      | 0.50                 | μA   |

(Notes and Remarks are listed on the next page.)

- Note 1. Current flowing to VDD.
- Note 2. When high speed on-chip oscillator and high-speed system clock are stopped.
- Note 3. Current flowing only to the real-time clock 2 (excluding the operating current of the low-speed on-chip oscillator and the XT1 oscillator). The supply current of the RL78 microcontrollers is the sum of the values of either IDD1 or IDD2, and IRTC, when the real-time clock 2 operates in the operating mode or HALT mode. When the low-speed on-chip oscillator is selected, IFIL should be added. IDD2 subsystem clock operation includes the operational current of the real-time clock 2.
- Note 4. Current flowing only to the 12-bit interval timer (excluding the operating current of the low-speed on-chip oscillator and the XT1 oscillator). The supply current of the RL78 microcontrollers is the sum of the values of either IDD1 or IDD2, and ITMKA, when the 12-bit interval timer operates in the operating mode or HALT mode. When the low-speed on-chip oscillator is selected, IFIL should be added. IDD2 subsystem clock operation includes the operational current of the 12-bit interval timer.
- Note 5. Current flowing only to the watchdog timer (including the operating current of the low-speed on-chip oscillator). The current value of the RL78 microcontrollers is the sum of IDD1, IDD2, or IDD3 and IWDT when the watchdog timer operates in STOP mode
- Note 6. Current flowing only to the A/D converter. The supply current of the RL78 microcontrollers is the sum of IDD1 or IDD2 and IADC, IADREF when the A/D converter operates in the operating mode or the HALT mode.
- Note 7. Operation current flowing to the internal reference voltage.
- Note 8. Current flowing only to the LVD circuit. The current value of the RL78 microcontrollers is the sum of IDD1, IDD2, or IDD3 and ILVI when the LVD circuit operates in the operating mode, HALT mode, or STOP mode.
- Note 9. Current flowing only during self-programming.
- Note 10. Current flowing only during data flash rewrite.
- Note 11. For shift time to the SNOOZE mode, see 27.3.3 SNOOZE mode in the User's Manual: Hardware.
- Note 12. Current flowing only to the LCD controller/driver (VDD pin). The current value of the RL78 microcontrollers is the sum of the LCD operating current (ILCD1, ILCD2, or ILCD3) and the supply current (IDD1 or IDD2) when the LCD controller/driver operates in the operating mode or HALT mode. Not including the current that flows through the LCD panel.
- Note 13. Not including the current that flows through the external divider resistor.
- Note 14. Current flowing only to the 8-bit interval timer (excluding the operating current of the low-speed on-chip oscillator and the XT1 oscillator). The supply current of the RL78 microcontrollers is the sum of the values of either IDD1 or IDD2, and IIT, when the 8-bit interval timer operates in the operating mode or HALT mode. When the low-speed on-chip oscillator is selected, IFIL should be added.
- Remark 1. fil: Low-speed on-chip oscillator clock frequency
- Remark 2. fSUB: Subsystem clock frequency (XT1 clock oscillation frequency)
- Remark 3. fclk: CPU/peripheral hardware clock frequency
- Remark 4. Temperature condition of the TYP. value is TA = 25°C

### • AFE functions

## $(TA = -40 \text{ to } +85^{\circ}C, 2.7 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$

| Parameter   | Symbol          | Conditions   | MIN. | TYP. | MAX. | Unit |
|---|-----------------|--|------|------|------|------|
| 24-bit $\Delta\Sigma$ A/D converter operating current | IDSAD           | Normal mode Notes 1, 2 Circuits that operate: ABGR, REGA, SBIAS, VREFAMP, PGA0, 24-bit $\Delta\Sigma$ A/D converter, and digital filter Differential input mode, OSR = 256, SBIAS IOUT = 0 mA    |      | 0.94 | 1.46 | mA   |
|   |                 | Low power mode Notes 1, 2 Circuits that operate: ABGR, REGA, SBIAS, VREFAMP, PGA0, 24-bit $\Delta\Sigma$ A/D converter, and digital filter Differential input mode, OSR = 256, SBIAS IOUT = 0 mA |      | 0.60 | 0.91 | mA   |
| Amplifier operating current                           | IPGA1           | Low power mode Notes 1, 2 Circuits that operate: ABGR, PGA1, and DAC1 IL = 0 mA  |      | 0.60 | 1.10 | mA   |
|   |                 | High-speed mode Notes 1, 2 Circuits that operate: ABGR, PGA1, and DAC1 IL = 0 mA   |      | 1.10 | 1.80 | mA   |
|   | IAMP0           | Low power mode Notes 1, 2 Circuits that operate: ABGR and AMP0 IL = 0 mA   |      | 0.10 | 0.15 | mA   |
|   |                 | High-speed mode Notes 1, 2 Circuits that operate: ABGR and AMP0 IL = 0 mA  |      | 0.30 | 0.48 | mA   |
|   | IAMP1,<br>IAMP2 | Low power mode Notes 1, 2 Circuits that operate: ABGR and AMP1 or AMP2 IL = 0 mA   |      | 0.10 | 0.14 | mA   |
|   |                 | High-speed mode Notes 1, 2 Circuits that operate: ABGR and AMP1 or AMP2 IL = 0 mA  |      | 0.23 | 0.35 | mA   |
| 8-bit D/A<br>converter<br>operating                   | IDAC0           | SBIAS normal mode Notes 1, 2 Circuits that operate: ABGR, REGA, SBIAS, and DAC0 Note 3 IL = 0 mA, SBIAS IOUT = 0 mA  |      | 1.00 | 1.50 | mA   |
| current   |                 | SBIAS low-power mode Notes 1, 2 Circuits that operate: ABGR, REGA, SBIAS, and DAC0 Note 3 IL = 0 mA, SBIAS lout = 0 mA   |      | 0.85 | 1.30 | mA   |
| 12-bit D/A converter operating                        | IDAC1           | When AVDD is selected as the reference voltage Notes 1, 2 Circuits that operate: ABGR and DAC1 IL = 0 mA   |      | 0.61 | 0.97 | mA   |
| current   |                 | When SBIAS (normal mode) is selected as the reference voltage Notes 1, 2 Circuits that operate: ABGR, REGA, SBIAS, and DAC1 Note 3 IL = 0 mA, SBIAS IOUT = 0 mA                                  |      | 1.06 | 1.62 | mA   |
|   |                 | When SBIAS (low-power mode) is selected as the reference voltage Notes 1, 2  Circuits that operate: ABGR, REGA, SBIAS, and DAC1 Note 3  IL = 0 mA, SBIAS IOUT = 0 mA                             |      | 0.91 | 1.42 | mA   |

Note 1. Current flowing to AVDD. The typical conditions are the conditions when TA = 25°C and AVDD = 3.3 V.

Remark Values in parentheses are target design values (i.e. not guaranteed) and therefore are not tested for shipment.

**Note 2.** Current flowing only into the operating circuit indicated in the column for conditions.

**Note 3.** Including the static current of VREFAMP, PGA0, and 24-bit  $\Delta\Sigma$  A/D converter.

#### 2.4 AC Characteristics

## 2.4.1 Basic operation

(TA = -40 to +85°C, 2.4 V  $\leq$  AVDD = VDD  $\leq$  5.5 V, AVSS = VSS = 0 V)

| Items  | Symbol          |                                  | Conditions           |                     | MIN.           | TYP. | MAX. | Unit |
|--|-----------------|----------------------------------|----------------------|---------------------|----------------|------|------|------|
| Instruction cycle  | Tcy             | Main system                      | HS (high-speed main) | 2.7 V ≤ VDD ≤ 5.5 V | 0.0417         |      | 1    | μs   |
| (minimum instruction execution time)                     |                 | clock (fMAIN)<br>operation       | mode                 | 2.4 V ≤ VDD < 2.7 V | 0.0625         |      | 1    | μs   |
|  |                 | Subsystem clock (fSUB) operation | fxT =32.768 kHz      | 2.4 V ≤ VDD ≤ 5.5 V | 28.5           | 30.5 | 31.3 | μs   |
|  |                 | In the self-                     | HS (high-speed main) | 2.7 V ≤ VDD ≤ 5.5 V | 0.0417         |      | 1    | μs   |
|  |                 | programming mode                 | mode                 | 2.4 V ≤ VDD < 2.7 V | 0.0625         |      | 1    | μs   |
| External main system                                     | fEX             | EXCLK                            |                      | 2.7 V ≤ VDD ≤ 5.5 V | 1.0            |      | 20.0 | MHz  |
| clock frequency  |                 |                                  |                      | 2.4 V ≤ VDD < 2.7 V | 1.0            |      | 16.0 | MHz  |
|  | fEXT            | EXCLKS                           |                      |                     | 32             |      | 35   | kHz  |
| External main system                                     | texH,           | EXCLK                            |                      | 2.7 V ≤ VDD ≤ 5.5 V | 24             |      |      | ns   |
| clock input high-level                                   | tEXL            |                                  |                      | 2.4 V ≤ VDD < 2.7 V | 30             |      |      | ns   |
| width, low-level width                                   | tEXHS,          | EXCLKS                           |                      |                     | 13.7           |      |      | μs   |
| Timer input<br>high-level width,<br>low-level width      | ttih,<br>ttil   | TI00 to TI07                     |                      |                     | 1/fMCK +<br>10 |      |      | ns   |
| Timer output   | fто             | TO00 to                          | HS (high-speed main) | 4.0 V ≤ VDD ≤ 5.5 V |                |      | 12   | MHz  |
| frequency  |                 | TO07                             | mode                 | 2.7 V ≤ VDD < 4.0 V |                |      | 8    | MHz  |
|  |                 |                                  |                      | 2.4 V ≤ VDD < 2.7 V |                |      | 4    | MHz  |
| Buzzer output  | fPCL            | PCLBUZ0,                         | HS (high-speed main) | 4.0 V ≤ VDD ≤ 5.5 V |                |      | 12   | MHz  |
| frequency  |                 | PCLBUZ1                          | mode                 | 2.7 V ≤ VDD < 4.0 V |                |      | 8    | MHz  |
|  |                 |                                  |                      | 2.4 V ≤ VDD < 2.7 V |                |      | 4    | MHz  |
| Interrupt input high-<br>level width, low-level<br>width | tINTH,<br>tINTL | INTP0 to INTP                    | 7                    | 2.4 V ≤ VDD ≤ 5.5 V | 1              |      |      | μs   |
| RESET low-level width                                    | tRSL            |                                  |                      |                     | 10             |      |      | μs   |

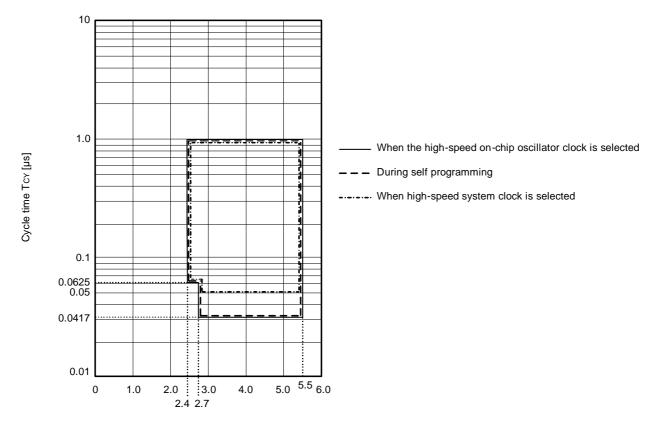
Remark fMCK: Timer array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of timer mode register mn (TMRmn). m: Unit number (m = 0),

n: Channel number (n = 0 to 7))

Minimum Instruction Execution Time during Main System Clock Operation

Tcy vs VDD (HS (high-speed main) mode)

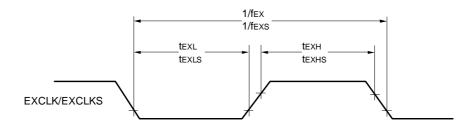


Supply voltage VDD [V]

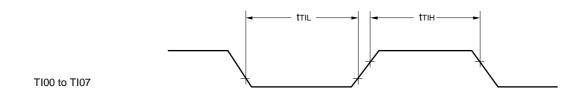
#### **AC Timing Test Points**

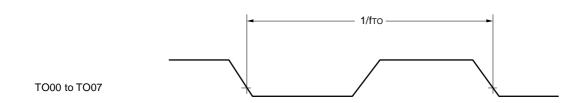


#### External System Clock Timing

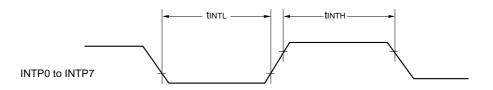


#### TI/TO Timing

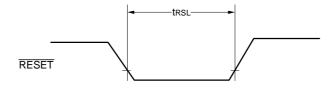




#### Interrupt Request Input Timing



## **RESET** Input Timing



### 2.5 Peripheral Functions Characteristics

#### 2.5.1 Serial array unit

#### (1) During communication at same potential (UART mode)

 $(TA = -40 \text{ to } +85^{\circ}C, 2.4 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$ 

| Parameter            | Symbol | Conditions  | HS (high-speed main) Mode |               | Unit |
|----------------------|--------|---|---------------------------|---------------|------|
| T arameter Symbol    |        | Conditions  | MIN.                      | MAX.          |      |
| Transfer rate Note 1 |        | 2.4 V ≤ VDD ≤ 5.5 V   |                           | fMCK/6 Note 2 | bps  |
|                      |        | Theoretical value of the maximum transfer rate $fMCK = fCLK Note 3$ |                           | 4.0           | Mbps |

Note 1. Transfer rate in the SNOOZE mode is 4800 bps only.

Note 2. The following conditions are required for low voltage interface.

 $2.4 \text{ V} \leq \text{VDD} < 2.7 \text{ V}$ : MAX. 2.6 Mbps

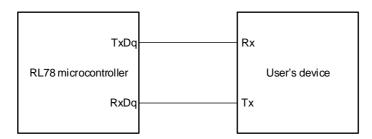
Note 3. The maximum operating frequencies of the CPU/peripheral hardware clock (fCLK) are:

HS (high-speed main) mode: 24 MHz (2.7 V  $\leq$  VDD  $\leq$  5.5 V)

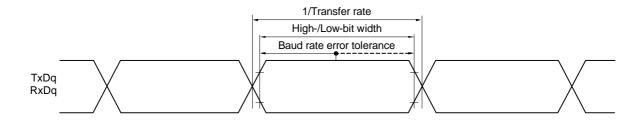
16 MHz (2.4 V  $\leq$  VDD  $\leq$  5.5 V)

Caution Select the normal input buffer for the RxDq pin and the normal output mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg).

#### **UART** mode connection diagram (during communication at same potential)



#### **UART** mode bit width (during communication at same potential) (reference)



**Remark 1.** q: UART number (q = 0 to 2), g: PIM and POM number (g = 0, 1, 3, 4, 5, 8)

Remark 2. fMCK: Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number,

n: Channel number (mn = 00 to 03, 10, 11))

## (2) During communication at same potential (Simplified SPI(CSI) mode) (master mode, SCKp... internal clock output)

 $(TA = -40 \text{ to } +85^{\circ}C, 2.4 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$ 

| Parameter                                  | Symbol | HS Conditions                 |                                 | HS (high-speed<br>Mode | d main) | Unit |
|--|--------|-------------------------------|---------------------------------|------------------------|---------|------|
|  |        |                               |                                 | MIN.                   | MAX.    |      |
| SCKp cycle time                            | tKCY1  | tkcy1 ≥ fclk/4                | 2.7 V ≤ VDD ≤ 5.5 V             | 167                    |         | ns   |
|  |        |                               | 2.4 V ≤ VDD ≤ 5.5 V             | 250                    |         | ns   |
| SCKp high-/low-level width                 | tKH1,  | 4.0 V ≤ VDD ≤ 5.5             | V                               | tKCY1/2 - 12           |         | ns   |
|  | tKL1   | 2.7 V ≤ V <sub>DD</sub> ≤ 5.5 | V                               | tKCY1/2 - 18           |         | ns   |
|  |        | 2.4 V ≤ V <sub>DD</sub> ≤ 5.5 | V                               | tKCY1/2 - 38           |         | ns   |
| SIp setup time (to SCKp↑) Note 1           | tSIK1  | 4.0 V ≤ VDD ≤ 5.5 V           |                                 | 44                     |         | ns   |
|  |        | 2.7 V ≤ VDD ≤ 5.5 V           |                                 | 44                     |         | ns   |
|  |        | 2.4 V ≤ V <sub>DD</sub> ≤ 5.5 | V                               | 75                     |         | ns   |
| SIp hold time (from SCKp↑) Note 2          | tKSI1  | 2.4 V ≤ V <sub>DD</sub> ≤ 5.5 | V                               | 19                     |         | ns   |
| Delay time from SCKp↓ to SOp output Note 3 | tKSO1  | C = 20 pF Note 4              | 2.7 V ≤ VDD ≤ 5.5 V             |                        | 25      | ns   |
|  |        |                               | 2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V |                        | 25      | ns   |

- Note 1. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp setup time becomes "to SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
- Note 2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp hold time becomes "from SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
- Note 3. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes "from  $SCKp\uparrow$ " when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
- **Note 4.** C is the load capacitance of the SCKp and SOp output lines.
- Caution Select the normal input buffer for the SIp pin and the normal output mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg).
- **Remark 1.** p: CSI number (p = 00, 10, 20), m: Unit number (m = 0, 1), n: Channel number (n = 0, 2), g: PIM and POM number (g = 0, 1, 3, 4, 5, 8)
- Remark 2. fMCK: Serial array unit operation clock frequency (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00, 02, 10))

# (3) During communication at same potential (Simplified SPI(CSI) mode) (slave mode, SCKp... external clock output) (1/2)

 $(TA = -40 \text{ to } +85^{\circ}\text{C}, 2.4 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$ 

| Parameter                                  | Cumhal | Co                              | HS (high-speed main) Mode onditions |                   | ed main) Mode | Unit |
|--|--------|---------------------------------|-------------------------------------|-------------------|---------------|------|
| Parameter                                  | Symbol | Co                              | nations                             | MIN.              | MAX.          | Unit |
| SCKp cycle time Note 5                     | tKCY2  | (CY2 4.0 V ≤ VDD ≤ 5.5 V        | 20 MHz < fmck                       | 8/fMCK            |               | ns   |
|  |        |                                 | fMCK ≤ 20 MHz                       | 8/fMCK            |               | ns   |
|  |        | 2.7 V ≤ VDD ≤ 5.5 V             | fмск > 16 MHz                       | 8/fMCK            |               | ns   |
|  |        | IIIION = 10 IIII IZ             | 6/fMCK                              |                   | ns            |      |
|  |        | 2.4 V ≤ VDD ≤ 5.5 V             |                                     | 6/fмск<br>and 500 |               | ns   |
| SCKp high-/low-level width                 | tKH2,  | 4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V |                                     | tKCY2/2 - 7       |               | ns   |
|  | tKL2   | 2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V |                                     | tKCY2/2 - 8       |               | ns   |
|  |        | 2.4 V ≤ VDD ≤ 5.5 V             |                                     | tKCY2/2 - 18      |               | ns   |
| SIp setup time (to SCKp↑) Note 1           | tSIK2  | 2.7 V ≤ VDD ≤ 5.5 V             |                                     | 1/fмcк + 20       |               | ns   |
|  |        | 2.4 V ≤ VDD ≤ 5.5 V             |                                     | 1/fмcк + 30       |               | ns   |
| SIp hold time (from SCKp↑) Note 2          | tKSI2  | 2.4 V ≤ VDD ≤ 5.5 V             |                                     | 1/fMCK + 31       |               | ns   |
| Delay time from SCKp↓ to SOp output Note 3 | tKSO2  | C = 30 pF Note 4                | 2.7 V ≤ VDD ≤ 5.5 V                 |                   | 2/fMCK + 44   | ns   |
|  |        |                                 | 2.4 V ≤ VDD ≤ 5.5 V                 |                   | 2/fMCK + 75   | ns   |

- Note 1. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The SIp setup time becomes "to SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
- Note 2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp hold time becomes "from SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
- Note 3. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes "from SCKp↑" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
- Note 4. C is the load capacitance of the SCKp and SOp output lines.
- Note 5. The maximum transfer rate when using the SNOOZE mode is 1 Mbps.
- Caution Select the normal input buffer for the SIp pin and the normal output mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg).
- **Remark 1.** p: CSI number (p = 00, 10, 20), m: Unit number (m = 0, 1), n: Channel number (n = 0, 2), g: PIM and POM number (g = 0, 1, 3, 4, 5, 8)
- Remark 2. fMCK: Serial array unit operation clock frequency (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00, 02, 10))

## (3) During communication at same potential (Simplified SPI(CSI) mode) (slave mode, SCKp... external clock output) (2/2)

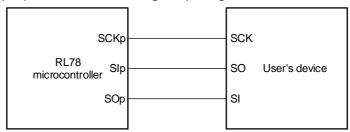
(TA = -40 to +85°C, 2.4 V  $\leq$  AVDD = VDD  $\leq$  5.5 V, AVSS = VSS = 0 V)

| Parameter        | Symbol |           | Conditions          | HS (high-speed | Unit |       |
|------------------|--------|-----------|---------------------|----------------|------|-------|
| Falameter        | Symbol |           | oriditions          | MIN.           |      | Offic |
| SSI00 setup time | tssik  | DAPmn = 0 | 2.7 V ≤ VDD ≤ 5.5 V | 120            |      | ns    |
|                  |        |           | 2.4 V ≤ VDD ≤ 5.5 V | 200            |      | ns    |
|                  |        | DAPmn = 1 | 2.7 V ≤ VDD ≤ 5.5 V | 1/fмск + 120   |      | ns    |
|                  |        |           | 2.4 V ≤ VDD ≤ 5.5 V | 1/fмcк + 200   |      | ns    |
| SSI00 hold time  | tkssi  | DAPmn = 0 | 2.7 V ≤ VDD ≤ 5.5 V | 1/fмcк + 120   |      | ns    |
|                  |        |           | 2.4 V ≤ VDD ≤ 5.5 V | 1/fмcк + 200   |      | ns    |
|                  |        | DAPmn = 1 | 2.7 V ≤ VDD ≤ 5.5 V | 120            |      | ns    |
|                  |        |           | 2.4 V ≤ VDD ≤ 5.5 V | 200            |      | ns    |

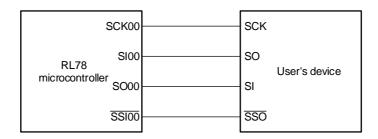
Caution Select the normal input buffer for the SIp pin and SCKp pin and the normal output mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

**Remark** p: CSI number (p = 00), m: Unit number (m = 0), n: Channel number (n = 0), g: PIM and POM number (g = 3, 4)

Simplified SPI(CSI) mode connection diagram (during communication at same potential)

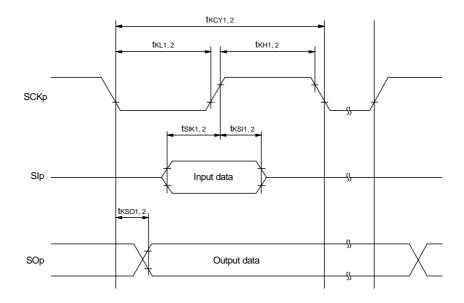


Simplified SPI(CSI) mode connection diagram (during communication at same potential) (Slave Transmission of slave select input function (CSI00))

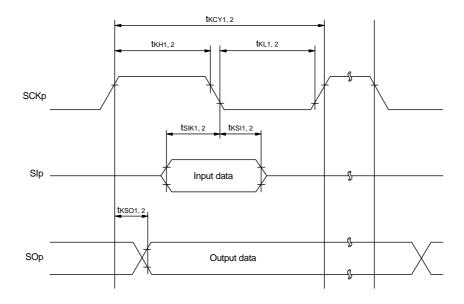


**Remark** p: CSI number (p = 00, 10, 20), m: Unit number (m = 0, 1), n: Channel number (n = 0, 2)

# Simplified SPI(CSI) mode serial transfer timing (during communication at same potential) (When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



# Simplified SPI(CSI) mode serial transfer timing (during communication at same potential) (When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)



**Remark** p: CSI number (p = 00, 10, 20), m: Unit number (m = 0, 1), n: Channel number (n = 0, 2)

#### (4) During communication at same potential (simplified I<sup>2</sup>C mode)

#### (TA = -40 to +85°C, 2.4 V $\leq$ AVDD = VDD $\leq$ 5.5 V, AVSS = VSS = 0 V)

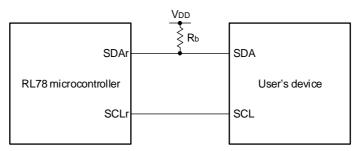
| Parameter                     | Symbol   | Conditions  | HS (high-speed<br>Mode | main)       | Unit |
|-------------------------------|----------|---|------------------------|-------------|------|
|                               |          |   | MIN.                   | MAX.        |      |
| SCLr clock frequency          | fSCL     | 2.7 V $\leq$ VDD $\leq$ 5.5 V,<br>Cb = 50 pF, Rb = 2.7 kΩ |                        | 1000 Note 1 | kHz  |
|                               |          | 2.4 V ≤ VDD ≤ 5.5 V,<br>Cb = 100 pF, Rb = 3 kΩ            |                        | 400 Note 1  | kHz  |
|                               |          | 2.4 V $\leq$ VDD $<$ 2.7 V,<br>Cb = 100 pF, Rb = 5 kΩ     |                        | 300 Note 1  | kHz  |
| Hold time when SCLr = "L"     | tLOW     | 2.7 V $\leq$ VDD $\leq$ 5.5 V,<br>Cb = 50 pF, Rb = 2.7 kΩ | 475                    |             | ns   |
|                               |          | 2.4 V $\leq$ VDD $\leq$ 5.5 V,<br>Cb = 100 pF, Rb = 3 kΩ  | 1150                   |             | ns   |
|                               |          | 2.4 V $\leq$ VDD $<$ 2.7 V,<br>Cb = 100 pF, Rb = 5 kΩ     | 1550                   |             | ns   |
| Hold time<br>when SCLr = "H"  | tHIGH    | 2.7 V $\leq$ VDD $\leq$ 5.5 V,<br>Cb = 50 pF, Rb = 2.7 kΩ | 475                    |             | ns   |
|                               |          | 2.4 V $\leq$ VDD $\leq$ 5.5 V,<br>Cb = 100 pF, Rb = 3 kΩ  | 1150                   |             | ns   |
|                               |          | 2.4 V $\leq$ VDD $<$ 2.7 V,<br>Cb = 100 pF, Rb = 5 kΩ     | 1550                   |             | ns   |
| Data setup time (reception)   | tsu: dat | 2.7 V $\leq$ VDD $\leq$ 5.5 V,<br>Cb = 50 pF, Rb = 2.7 kΩ | 1/fмск + 85 Note 2     |             | ns   |
|                               |          | 2.4 V $\leq$ VDD $\leq$ 5.5 V,<br>Cb = 100 pF, Rb = 3 kΩ  | 1/fмск + 145 Note 2    |             | ns   |
|                               |          | 2.4 V $\leq$ VDD $<$ 2.7 V,<br>Cb = 100 pF, Rb = 5 kΩ     | 1/fMCK + 230 Note 2    |             | ns   |
| Data hold time (transmission) | tHD: DAT | 2.7 V $\leq$ VDD $\leq$ 5.5 V,<br>Cb = 50 pF, Rb = 2.7 kΩ | 0                      | 305         | ns   |
|                               |          | 2.4 V $\leq$ VDD $\leq$ 5.5 V,<br>Cb = 100 pF, Rb = 3 kΩ  | 0                      | 355         | ns   |
|                               |          | 2.4 V $\leq$ VDD $<$ 2.7 V,<br>Cb = 100 pF, Rb = 5 kΩ     | 0                      | 405         | ns   |

**Note 1.** The value must be equal to or less than fMCK/4.

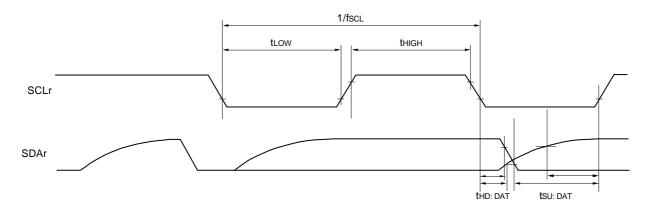
Caution Select the normal input buffer and the N-ch open drain output (VDD tolerance) mode for the SDAr pin and the normal output mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register h (POMh).

**Note 2.** Set the fMCK value to keep the hold time of SCLr = "L" and SCLr = "H".

#### Simplified I<sup>2</sup>C mode connection diagram (during communication at same potential)



#### Simplified I<sup>2</sup>C mode serial transfer timing (during communication at same potential)



 $\textbf{Remark 1.} \ \ Rb[\Omega]: Communication \ line \ (SDAr) \ pull-up \ resistance, \ Cb[F]: Communication \ line \ (SCLr, SDAr) \ load \ capacitance$ 

**Remark 2.** r: IIC number (r = 00, 10, 20), g: PIM number (g = 0, 1, 3, 4, 5, 8),

Remark 3. fmck: Serial array unit operation clock frequency (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number (m = 0, 1), n: Channel number (n = 0, 2), mn = 00, 02, 10)

## (5) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode) (1/2) (TA = -40 to +85°C, 2.4 V $\leq$ AVDD = VDD $\leq$ 5.5 V, AVSS = VSS = 0 V)

| Parameter     | Symbol |           | Conditions   |      | HS (high-speed main)<br>Mode |      |  |                      |     |
|---------------|--------|-----------|--|------|------------------------------|------|--|----------------------|-----|
|               |        |           |  | MIN. | MAX.                         |      |  |                      |     |
| Transfer rate |        | reception | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V},$<br>$2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V}$                     |      | fMCK/6 Note 1                | bps  |  |                      |     |
|               |        |           | Theoretical value of the maximum transfer rate<br>fMCK = fCLK Note 4   |      | 4.0                          | Mbps |  |                      |     |
|               |        |           | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V},$<br>$2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V}$                       |      | fMCK/6 Note 1                | bps  |  |                      |     |
|               |        |           | Theoretical value of the maximum transfer rate $\label{eq:maximum transfer} \text{fmck} = \text{fcLk}  ^{\text{Note 4}}$ |      | 4.0                          | Mbps |  |                      |     |
|               |        |           | $2.4 \text{ V} \leq \text{VDD} < 3.3 \text{ V},$<br>$1.6 \text{ V} \leq \text{V}_b \leq 2.0 \text{ V}$                   |      |                              |      |  | fMCK/6 Notes 1, 2, 3 | bps |
|               |        |           | Theoretical value of the maximum transfer rate<br>fMCK = fCLK Note 4   |      | 4.0                          | Mbps |  |                      |     |

- **Note 1.** Transfer rate in the SNOOZE mode is 4,800 bps only.
- **Note 2.** Use it with  $VDD \ge Vb$ .
- **Note 3.** The following conditions are required for low voltage interface.

 $2.4 \text{ V} \leq \text{VDD} < 2.7 \text{ V}$ : MAX. 2.6 Mbps

Note 4. The maximum operating frequencies of the CPU/peripheral hardware clock (fclk) are:

HS (high-speed main) mode: 24 MHz (2.7 V  $\leq$  VDD  $\leq$  5.5 V)

16 MHz (2.4 V  $\leq$  VDD  $\leq$  5.5 V)

Caution Select the TTL input buffer for the RxDq pin and the N-ch open drain output (VDD tolerance) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and VIL, see the DC characteristics with TTL input buffer selected.

- Remark 1. Vb[V]: Communication line voltage
- **Remark 2.** q: UART number (q = 0 to 2), g: PIM and POM number (g = 0, 1, 3, 4, 5, 8)
- Remark 3. fmck: Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number,

n: Channel number (mn = 00 to 03, 10, 11))

# (5) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode) (2/2) (TA = -40 to +85°C, 2.4 V $\leq$ AVDD = VDD $\leq$ 5.5 V, AVSS = VSS = 0 V)

| Parameter     | Symbol               | Conditions |   | HS (high | Unit        |      |
|---------------|----------------------|------------|---|----------|-------------|------|
|               |                      |            |   | MIN.     | MAX.        |      |
| Transfer rate | er rate transmission |            | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V},$<br>$2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V}$                    |          | Note 1      | bps  |
|               |                      |            | Theoretical value of the maximum transfer rate $C_b = 50$ pF, $R_b = 1.4$ k $\Omega$ , $V_b = 2.7$ V                    |          | 2.8 Note 2  | Mbps |
|               |                      |            | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V},$<br>$2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V}$                      |          | Note 3      | bps  |
|               |                      |            | Theoretical value of the maximum transfer rate $Cb = 50$ pF, $Rb = 2.7$ k $\Omega$ , $Vb = 2.3$ V                       |          | 1.2 Note 4  | Mbps |
|               |                      |            | $2.4 \text{ V} \leq \text{VDD} < 3.3 \text{ V},$<br>$1.6 \text{ V} \leq \text{Vb} \leq 2.0 \text{ V}$                   |          | Notes 5, 6  | bps  |
|               |                      |            | Theoretical value of the maximum transfer rate $C_b = 50 \text{ pF, } R_b = 5.5 \text{ k}\Omega, \ V_b = 1.6 \text{ V}$ |          | 0.43 Note 7 | Mbps |

Note 1. The smaller maximum transfer rate derived by using fMCK/6 or the following expression is the valid maximum transfer rate. Expression for calculating the transfer rate when  $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}$  and  $2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V}$ 

Maximum transfer rate = 
$$\frac{1}{\{-C_b \times R_b \times \ln (1 - \frac{2.2}{V_b})\} \times 3}$$
 [bps]

Baud rate error (theoretical value) = 
$$\frac{\frac{1}{\text{Transfer rate} \times 2} - \{-\text{Cb} \times \text{Rb} \times \text{In} (1 - \frac{2.2}{\text{Vb}})\} }{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \, [\%]$$

- \* This value is the theoretical value of the relative difference between the transmission and reception sides.
- Note 2. This value as an example is calculated when the conditions described in the "Conditions" column are met.

  Refer to Note 1 above to calculate the maximum transfer rate under conditions of the customer.
- Note 3. The smaller maximum transfer rate derived by using fMCK/6 or the following expression is the valid maximum transfer rate. Expression for calculating the transfer rate when 2.7 V  $\leq$  VDD  $\leq$  4.0 V and 2.3 V  $\leq$  Vb  $\leq$  2.7 V

$$\frac{1}{ \left\{ -C_b \times R_b \times \text{In } (1 - \frac{2.0}{V_b}) \right\} \times 3} [bps]$$

Baud rate error (theoretical value) = 
$$\frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}}$$

- \* This value is the theoretical value of the relative difference between the transmission and reception sides.
- **Note 4.** This value as an example is calculated when the conditions described in the "Conditions" column are met. Refer to Note 3 above to calculate the maximum transfer rate under conditions of the customer.
- **Note 5.** Use it with  $VDD \ge Vb$ .



Note 6. The smaller maximum transfer rate derived by using fMCK/6 or the following expression is the valid maximum transfer rate. Expression for calculating the transfer rate when 2.4 V  $\leq$  VDD < 3.3 V and 1.6 V  $\leq$  Vb  $\leq$  2.0 V

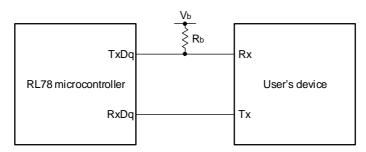
Maximum transfer rate = 
$$\frac{1}{\{-C_b \times R_b \times \ln (1 - \frac{1.5}{V_b})\} \times 3}$$
 [bps]

Baud rate error (theoretical value) = 
$$\frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{1.5}{V_b})\} }{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits} }$$

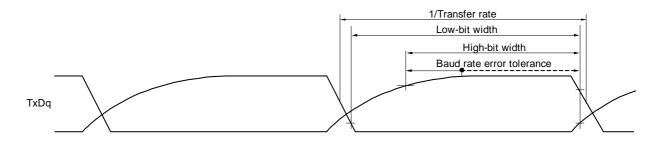
- **Note 7.** This value as an example is calculated when the conditions described in the "Conditions" column are met. Refer to Note 6 above to calculate the maximum transfer rate under conditions of the customer.
- Caution Select the TTL input buffer for the RxDq pin and the N-ch open drain output (VDD tolerance) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and VIL, see the DC characteristics with TTL input buffer selected.

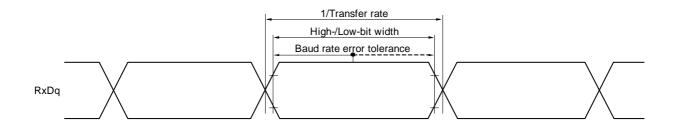
<sup>\*</sup> This value is the theoretical value of the relative difference between the transmission and reception sides.

#### **UART** mode connection diagram (during communication at different potential)



#### UART mode bit width (during communication at different potential) (reference)





- Remark 1.  $Rb[\Omega]$ : Communication line (TxDq) pull-up resistance, Cb[F]: Communication line (TxDq) load capacitance, Vb[V]: Communication line voltage
- **Remark 2.** q: UART number (q = 0 to 2), g: PIM and POM number (g = 0, 1, 3, 4, 5, 8)
- Remark 3. fMCK: Serial array unit operation clock frequency

  (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number,

  n: Channel number (mn = 00 to 03, 10, 11))

(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (Simplified SPI(CSI) mode) (master mode, SCKp... internal clock output) (1/2)

 $(TA = -40 \text{ to } +85^{\circ}C, 2.4 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$ 

| Parameter                  | Parameter Symbol |   | Conditions   | HS (high-speed main) Conditions  Mode |      | Unit |
|----------------------------|------------------|---|--|---------------------------------------|------|------|
|                            |                  |   |  | MIN.                                  | MAX. |      |
| SCKp cycle time            | tKCY1            | tKCY1 ≥ 4/fCLK  | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V},$<br>$C_b = 30 \text{ pF}, R_b = 1.4 \text{ k}\Omega$ | 300                                   |      | ns   |
|                            |                  |   | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V},$<br>$C_b = 30 \text{ pF}, R_b = 2.7 \text{ k}\Omega$   | 500 Note                              |      | ns   |
|                            |                  |   | $2.4 \text{ V} \le \text{VDD} < 3.3 \text{ V}, 1.6 \text{ V} \le \text{Vb} \le 2.0 \text{ V},$<br>$C_b = 30 \text{ pF}, R_b = 5.5 \text{ k}\Omega$   | 1150 Note                             |      | ns   |
| SCKp high-level tkH1 width | tKH1             | 4.0 V ≤ V <sub>DD</sub> ≤ 5<br>C <sub>b</sub> = 30 pF, R <sub>b</sub> = | 5.5 V, 2.7 V $\leq$ Vb $\leq$ 4.0 V,<br>= 1.4 kΩ   | tKCY1/2 - 75                          |      | ns   |
|                            |                  | 2.7 V ≤ VDD < 4<br>Cb = 30 pF, Rb =                                     | 4.0 V, 2.3 V $\leq$ Vb $\leq$ 2.7 V,<br>= 2.7 kΩ   | tKCY1/2 - 170                         |      | ns   |
|                            |                  | 2.4 V ≤ VDD < 3<br>Cb = 30 pF, Rb =                                     | 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V,<br>= 5.5 kΩ   | tKCY1/2 - 458                         |      | ns   |
| SCKp low-level width       | tKL1             | 4.0 V ≤ V <sub>DD</sub> ≤ 5<br>C <sub>b</sub> = 30 pF, R <sub>b</sub> = | 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V,<br>= 1.4 kΩ   | tKCY1/2 - 12                          |      | ns   |
|                            |                  | 2.7 V ≤ VDD < 4<br>Cb = 30 pF, Rb =                                     | 4.0 V, 2.3 V $\leq$ Vb $\leq$ 2.7 V,<br>= 2.7 kΩ   | tKCY1/2 - 18                          |      | ns   |
|                            |                  | 2.4 V ≤ VDD < 3<br>Cb = 30 pF, Rb =                                     | 3.3 V, 1.6 V $\leq$ Vb $\leq$ 2.0 V,<br>= 5.5 kΩ   | tKCY1/2 - 50                          |      | ns   |

**Note** Use it with  $VDD \ge Vb$ .

Caution Select the TTL input buffer for the SIp pin and the N-ch open drain output (VDD tolerance) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and VIL, see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the page after the next page.)

# (6) Communication at different potential (1.8 V, 2.5 V, 3 V) (Simplified SPI(CSI) mode) (master mode, SCKp... internal clock output) (2/2)

 $(TA = -40 \text{ to } +85^{\circ}C, 2.4 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$ 

| Parameter                         | Symbol | Conditions  | HS (high-speed main)<br>Mode |      | Unit |
|-----------------------------------|--------|---|------------------------------|------|------|
|                                   |        |   | MIN.                         | MAX. |      |
| SIp setup time                    | tSIK1  | $4.0~\text{V} \leq \text{VDD} \leq 5.5~\text{V}, 2.7~\text{V} \leq \text{Vb} \leq 4.0~\text{V}, \text{Cb} = 30~\text{pF}, \text{Rb} = 1.4~\text{k}\Omega$   | 81                           |      | ns   |
| (to SCKp↑) Note 1                 |        | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V}, \text{Cb} = 30 \text{ pF}, \text{Rb} = 2.7 \text{ k}\Omega$   | 177                          |      | ns   |
|                                   |        | $2.4 \text{ V} \le \text{VDD} < 3.3 \text{ V}, 1.6 \text{ V} \le \text{V}_b \le 2.0 \text{ V}$ Note 3, $C_b = 30 \text{ pF}, R_b = 5.5 \text{ k}\Omega$     | 479                          |      | ns   |
| SIp hold time (from SCKp↑) Note 1 | tKSI1  | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V}, \text{Cb} = 30 \text{ pF}, \text{Rb} = 1.4 \text{ k}Ω$      | 19                           |      | ns   |
|                                   |        | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V}, \text{Cb} = 30 \text{ pF}, \text{Rb} = 2.7 \text{ k}\Omega$   | 19                           |      | ns   |
|                                   |        | $2.4 \text{ V} \le \text{VDD} < 3.3 \text{ V}, 1.6 \text{ V} \le \text{V}_b \le 2.0 \text{ V}$ Note 3, Cb = 30 pF, Rb = 5.5 kΩ                              | 19                           |      | ns   |
| SCKp↓ to SOp                      | tKSO1  | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V}, \text{Cb} = 30 \text{ pF}, \text{Rb} = 1.4 \text{ k}Ω$      |                              | 100  | ns   |
|                                   |        | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V}, \text{Cb} = 30 \text{ pF}, \text{Rb} = 2.7 \text{ k}\Omega$   |                              | 195  | ns   |
| output Note 1                     |        | $2.4 \text{ V} \le \text{VDD} < 3.3 \text{ V}, 1.6 \text{ V} \le \text{V}_b \le 2.0 \text{ V}$ Note 3, Cb = 30 pF, Rb = 5.5 kΩ                              |                              | 483  | ns   |
| SIp setup time                    | tsik1  | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V}, \text{Cb} = 30 \text{ pF}, \text{Rb} = 1.4 \text{ k}Ω$      | 44                           |      | ns   |
| (to SCKp↓) Note 2                 |        | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V}, \text{Cb} = 30 \text{ pF}, \text{Rb} = 2.7 \text{ k}\Omega$   | 44                           |      | ns   |
|                                   |        | $2.4 \text{ V} \le \text{VDD} < 3.3 \text{ V}, 1.6 \text{ V} \le \text{Vb} \le 2.0 \text{ V}$ Note 3, Cb = 30 pF, Rb = 5.5 kΩ                               | 110                          |      | ns   |
| SIp hold time                     | tKSI1  | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V}, \text{Cb} = 30 \text{ pF}, \text{Rb} = 1.4 \text{ k}\Omega$ | 19                           |      | ns   |
| (from SCKp↓) Note 2               |        | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V}, \text{Cb} = 30 \text{ pF}, \text{Rb} = 2.7 \text{ k}\Omega$   | 19                           |      | ns   |
|                                   |        | $2.4 \text{ V} \le \text{VDD} < 3.3 \text{ V}, 1.6 \text{ V} \le \text{Vb} \le 2.0 \text{ V}$ Note 3, Cb = 30 pF, Rb = 5.5 kΩ                               | 19                           |      | ns   |
| Delay time from                   | tKSO1  | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V}, \text{Cb} = 30 \text{ pF}, \text{Rb} = 1.4 \text{ k}Ω$      |                              | 25   | ns   |
| SCKp↑ to SOp                      |        | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V}, \text{Cb} = 30 \text{ pF}, \text{Rb} = 2.7 \text{ k}\Omega$   |                              | 25   | ns   |
| output Note 2                     |        | $2.4 \text{ V} \le \text{VDD} < 3.3 \text{ V}, 1.6 \text{ V} \le \text{V}_{b} \le 2.0 \text{ V}$ Note 3, Cb = 30 pF, Rb = 5.5 kΩ                            |                              | 25   | ns   |

**Note 1.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.

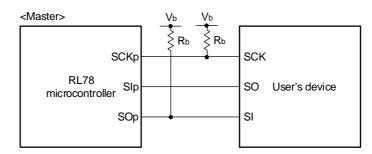
Caution Select the TTL input buffer for the SIp pin and the N-ch open drain output (VDD tolerance) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and VIL, see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the next page.)

Note 2. When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

**Note 3.** Use it with  $VDD \ge Vb$ .

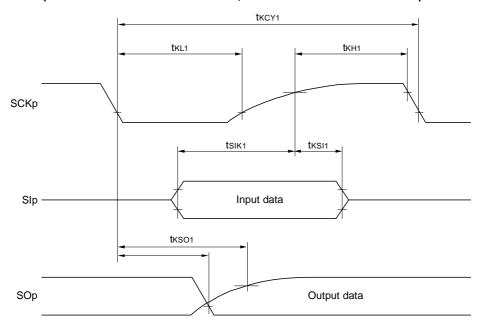
#### Simplified SPI(CSI) mode connection diagram (during communication at different potential)



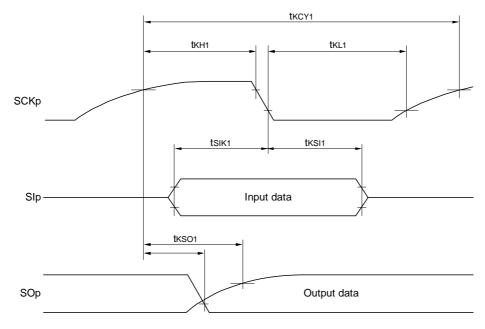
- Remark 1.  $Rb[\Omega]$ : Communication line (SCKp, SOp) pull-up resistance, Cb[F]: Communication line (SCKp, SOp) load capacitance, Vb[V]: Communication line voltage
- **Remark 2.** p: CSI number (p = 00, 10, 20), m: Unit number (m = 0, 1), n: Channel number (n = 0, 2), g: PIM and POM number (g = 0, 1, 3, 4, 5, 8)
- Remark 3. fmck: Serial array unit operation clock frequency

  (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00, 02, 10))

Simplified SPI(CSI) mode serial transfer timing (master mode) (during communication at different potential) (When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



Simplified SPI(CSI) mode serial transfer timing (master mode) (during communication at different potential) (When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)



**Remark** p: CSI number (p = 00, 10, 20), m: Unit number (m = 0, 1), n: Channel number (n = 0, 2), g: PIM and POM number (g = 0, 1, 3, 4, 5, 8)

## (7) Communication at different potential (1.8 V, 2.5 V, 3 V) (Simplified SPI(CSI) mode) (slave mode, SCKp... external clock input)

 $(TA = -40 \text{ to } +85^{\circ}C, 2.4 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$ 

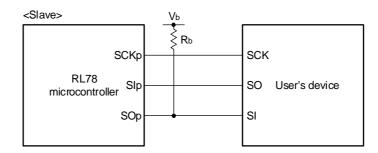
| Parameter                                     | Symbol |   | Conditions                      | HS (high-speed main) Mode |              | Unit |
|---|--------|---|---------------------------------|---------------------------|--------------|------|
| Farameter                                     | Symbol |   | Conditions                      | MIN.                      | MAX.         | Onn  |
| SCKp cycle time Note 1                        | tKCY2  | 4.0 V ≤ VDD ≤ 5.5 V,  | 20 MHz < fMCK                   | 12/fMCK                   |              | ns   |
|   |        | 2.7 V ≤ Vb ≤ 4.0 V  | 8 MHz < fMCK ≤ 20 MHz           | 10/fмck                   |              | ns   |
|   |        |   | 4 MHz < fMCK ≤ 8 MHz            | 8/fMCK                    |              | ns   |
|   |        |   | fMCK ≤ 4 MHz                    | 6/fмск                    |              | ns   |
|   |        | 2.7 V ≤ VDD < 4.0 V,  | 20 MHz < fMCK                   | 16/fMCK                   |              | ns   |
|   |        | 2.3 V ≤ Vb ≤ 2.7 V  | 16 MHz < fмcк ≤ 20 MHz          | 14/fMCK                   |              | ns   |
|   |        |   | 8 MHz < fMCK ≤ 16 MHz           | 12/fMCK                   |              | ns   |
|   |        |   | 4 MHz < fMCK ≤ 8 MHz            | 8/fMCK                    |              | ns   |
|   |        |   | fMCK ≤ 4 MHz                    | 6/fMCK                    |              | ns   |
|   |        | 2.4 V ≤ VDD < 3.3 V,  | 20 MHz < fMCK                   | 36/fMCK                   |              | ns   |
|   |        | 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V Note 2   | 16 MHz < fмcк ≤ 20 MHz          | 32/fMCK                   |              | ns   |
|   |        |   | 8 MHz < fMCK ≤ 16 MHz           | 26/fMCK                   |              | ns   |
|   |        |   | 4 MHz < fMCK ≤ 8 MHz            | 16/fMCK                   |              | ns   |
|   |        |   | fMCK ≤ 4 MHz                    | 10/fMCK                   |              | ns   |
| SCKp high-/low-level                          | tKH2,  | 4.0 V ≤ VDD ≤ 5.5 V, 2.7 V ≤  | 5 Vb ≤ 4.0 V                    | tKCY2/2 - 12              |              | ns   |
| width   | tKL2   | 2.7 V ≤ VDD < 4.0 V, 2.3 V ≤  | ≤ Vb ≤ 2.7 V                    | tKCY2/2 - 18              |              | ns   |
|   |        | 2.4 V ≤ VDD < 3.3 V, 1.6 V ≤  | ≤ Vb ≤ 2.0 V Note 2             | tKCY2/2 - 50              |              | ns   |
| SIp setup time                                | tSIK2  | 4.0 V ≤ VDD ≤ 5.5 V, 2.7 V ≤  | S V <sub>b</sub> ≤ 4.0 V        | 1/fMCK + 20               |              | ns   |
| (to SCKp↑) Note 3                             |        | 2.7 V ≤ VDD < 4.0 V, 2.3 V ≤  | ≤ Vb ≤ 2.7 V                    | 1/fMCK + 20               |              | ns   |
|   |        | 2.4 V ≤ VDD < 3.3 V, 1.6 V ≤  | ≤ Vb ≤ 2.0 V Note 2             | 1/fMCK + 30               |              | ns   |
| SIp hold time                                 | tKSI2  | 4.0 V ≤ VDD ≤ 5.5 V, 2.7 V ≤  | 3 Vb ≤ 4.0 V                    | 1/fMCK + 31               |              | ns   |
| (from SCKp↑) Note 4                           |        | 2.7 V ≤ VDD < 4.0 V, 2.3 V ≤  | ≤ Vb ≤ 2.7 V                    | 1/fMCK + 31               |              | ns   |
|   |        | 2.4 V ≤ VDD < 3.3 V, 1.6 V ≤  | ≤ V <sub>b</sub> ≤ 2.0 V Note 2 | 1/fMCK + 31               |              | ns   |
| Delay time from SCKp↓<br>to SOp output Note 5 | tKSO2  | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2.7 \text{ V} \le$ $Cb = 30 \text{ pF}, Rb = 1.4 \text{ k}Ω$ | S Vb ≤ 4.0 V                    |                           | 2/fmck + 120 | ns   |
|   |        | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le$ $Cb = 30 \text{ pF}, Rb = 2.7 \text{ k}Ω$   | ≤ Vb ≤ 2.7 V                    |                           | 2/fMCK + 214 | ns   |
|   |        | 2.4 V ≤ VDD < 3.3 V, 1.6 V ≤ Cb = 30 pF, Rb = $5.5 \text{ k}\Omega$   | S Vb ≤ 2.0 V Note 2             |                           | 2/fMCK + 573 | ns   |

- Note 1. Transfer rate in the SNOOZE mode: MAX. 1 Mbps
- **Note 2.** Use it with  $VDD \ge Vb$ .
- Note 3. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The SIp setup time becomes "to SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
- Note 4. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp hold time becomes "from SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
- Note 5. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes "from SCKp↑" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
- Caution Select the TTL input buffer for the SIp pin and SCKp pin and the N-ch open drain output (VDD tolerance) mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and VIL, see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the next page.)

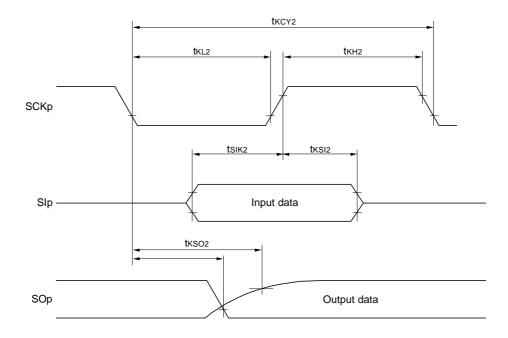


#### Simplified SPI(CSI) mode connection diagram (during communication at different potential)

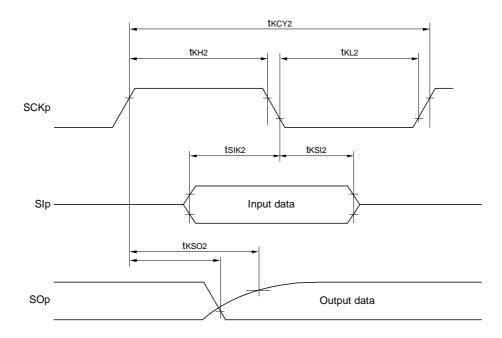


- Remark 1.  $Rb[\Omega]$ : Communication line (SOp) pull-up resistance, Cb[F]: Communication line (SOp) load capacitance, Vb[V]: Communication line voltage
- **Remark 2.** p: CSI number (p = 00, 10, 20), m: Unit number (m = 0, 1), n: Channel number (n = 0, 2), g: PIM and POM number (g = 0, 1, 3, 4, 5, 8)
- Remark 3. fMCK: Serial array unit operation clock frequency
  (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number,
  n: Channel number (mn = 00, 02, 10))

Simplified SPI(CSI) mode serial transfer timing (slave mode) (during communication at different potential) (When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



Simplified SPI(CSI) mode serial transfer timing (slave mode) (during communication at different potential) (When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)



**Remark** p: CSI number (p = 00, 10, 20), m: Unit number (m = 0, 1),

n: Channel number (n = 0, 2), g: PIM and POM number (g = 0, 1, 3, 4, 5, 8)

#### (8) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I<sup>2</sup>C mode)

 $(TA = -40 \text{ to } +85^{\circ}C, 2.4 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$ 

| Parameter       | Symbol   | Conditions  | HS (high-speed m    | ain) Mode   | Unit |
|-----------------|--|---|---------------------|-------------|------|
| Parameter       | Symbol   | Conditions  | MIN.                | MAX.        | Unit |
| SCLr clock      | fSCL   | $4.0~\text{V} \leq \text{VDD} \leq 5.5~\text{V}, 2.7~\text{V} \leq \text{Vb} \leq 4.0~\text{V}, \text{Cb} = 50~\text{pF}, \text{Rb} = 2.7~\text{k}\Omega$                     |                     | 1000 Note 1 | kHz  |
| frequency       |  | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V}, \text{Cb} = 50 \text{ pF}, \text{Rb} = 2.7 \text{ k}\Omega$                     |                     | 1000 Note 1 | kHz  |
|                 |  | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V}, \text{Cb} = 100 \text{ pF}, \text{Rb} = 2.8 \text{ k}\Omega$                  |                     | 400 Note 1  | kHz  |
|                 |  | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V}, \text{Cb} = 100 \text{ pF}, \text{Rb} = 2.7 \text{ k}\Omega$                    |                     | 400 Note 1  | kHz  |
|                 |  | $2.4~\text{V} \leq \text{VDD} < 3.3~\text{V}, 1.6~\text{V} \leq \text{V}_\text{b} \leq 2.0~\text{V}$ Note $^2$ , $\text{Cb} = 100~\text{pF},  \text{Rb} = 5.5~\text{k}\Omega$ |                     | 400 Note 1  | kHz  |
| Hold time       | tLOW   | $4.0~\text{V} \leq \text{VDD} \leq 5.5~\text{V}, 2.7~\text{V} \leq \text{Vb} \leq 4.0~\text{V}, \text{Cb} = 50~\text{pF}, \text{Rb} = 2.7~\text{k}\Omega$                     | 475                 |             | ns   |
| when SCLr = "L" |  | $2.7 \text{ V} \le \text{VDD} \le 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V}, \text{Cb} = 50 \text{ pF}, \text{Rb} = 2.7 \text{ k}\Omega$                   | 475                 |             | ns   |
|                 |  | $4.0~\text{V} \leq \text{VDD} \leq 5.5~\text{V},~2.7~\text{V} \leq \text{Vb} \leq 4.0~\text{V},~\text{Cb} = 100~\text{pF},~\text{Rb} = 2.8~\text{k}\Omega$                    | 1150                |             | ns   |
|                 |  | $2.7~\text{V} \leq \text{VDD} < 4.0~\text{V},  2.3~\text{V} \leq \text{Vb} \leq 2.7~\text{V},  \text{Cb} = 100~\text{pF},  \text{Rb} = 2.7~\text{k}\Omega$                    | 1150                |             | ns   |
|                 | $2.4 \text{ V} \le \text{VDD} < 3.3 \text{ V}, 1.6 \text{ V} \le \text{Vb} \le 2.0 \text{ V}$ Note 2, Cb = 100 pF, Rb = 5.5 kΩ | 1550  |                     | ns          |      |
| Hold time       | tHIGH  | $4.0~\text{V} \leq \text{VDD} \leq 5.5~\text{V},~2.7~\text{V} \leq \text{Vb} \leq 4.0~\text{V},~\text{Cb} = 50~\text{pF},~\text{Rb} = 2.7~\text{k}\Omega$                     | 245                 |             | ns   |
| when SCLr = "H" |  | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V}, \text{Cb} = 50 \text{ pF}, \text{Rb} = 2.7 \text{ k}\Omega$                     | 200                 |             | ns   |
|                 |  | $4.0~\text{V} \leq \text{VDD} \leq 5.5~\text{V},~2.7~\text{V} \leq \text{Vb} \leq 4.0~\text{V},~\text{Cb} = 100~\text{pF},~\text{Rb} = 2.8~\text{k}\Omega$                    | 675                 |             | ns   |
|                 |  | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V}, \text{Cb} = 100 \text{ pF}, \text{Rb} = 2.7 \text{ k}\Omega$                    | 600                 |             | ns   |
|                 |  | $2.4~\text{V} \leq \text{VDD} < 3.3~\text{V}, 1.6~\text{V} \leq \text{V}_{b} \leq 2.0~\text{V}$ Note 2, $C_{b} = 100~\text{pF}, R_{b} = 5.5~\text{k}\Omega$                   | 610                 |             | ns   |
| Data setup time | tsu:dat  | $4.0~\text{V} \leq \text{VDD} \leq 5.5~\text{V}, 2.7~\text{V} \leq \text{Vb} \leq 4.0~\text{V}, \text{Cb} = 50~\text{pF}, \text{Rb} = 2.7~\text{k}\Omega$                     | 1/fMCK + 135 Note 3 |             | ns   |
| (reception)     |  | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V}, \text{Cb} = 50 \text{ pF}, \text{Rb} = 2.7 \text{ k}\Omega$                     | 1/fMCK + 135 Note 3 |             | ns   |
|                 |  | $4.0~\text{V} \leq \text{VDD} \leq 5.5~\text{V},~2.7~\text{V} \leq \text{V}_{b} \leq 4.0~\text{V},~\text{Cb} = 100~\text{pF},~\text{Rb} = 2.8~\text{k}\Omega$                 | 1/fMCK + 190 Note 3 |             | ns   |
|                 |  | $2.7~\text{V} \leq \text{VDD} < 4.0~\text{V},  2.3~\text{V} \leq \text{Vb} \leq 2.7~\text{V},  \text{Cb} = 100~\text{pF},  \text{Rb} = 2.7~\text{k}\Omega$                    | 1/fMCK + 190 Note 3 |             | ns   |
|                 |  | $2.4~\text{V} \leq \text{VDD} < 3.3~\text{V}, 1.6~\text{V} \leq \text{Vb} \leq 2.0~\text{V}$ Note 2, Cb = 100 pF, Rb = $5.5~\text{k}\Omega$                                   | 1/fMCK + 190 Note 3 |             | ns   |
| Data hold time  | thd:dat  | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V}, \text{Cb} = 50 \text{ pF}, \text{Rb} = 2.7 \text{ k}\Omega$                   | 0                   | 305         | ns   |
| (transmission)  |  | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V}, \text{Cb} = 50 \text{ pF}, \text{Rb} = 2.7 \text{ k}\Omega$                     | 0                   | 305         | ns   |
|                 |  | $4.0~\text{V} \leq \text{VDD} \leq 5.5~\text{V}, 2.7~\text{V} \leq \text{V}_{b} \leq 4.0~\text{V}, \text{Cb} = 100~\text{pF}, \text{Rb} = 2.8~\text{k}\Omega$                 | 0                   | 355         | ns   |
|                 |  | $2.7~\text{V} \leq \text{VDD} < 4.0~\text{V},  2.3~\text{V} \leq \text{Vb} \leq 2.7~\text{V},  \text{Cb} = 100~\text{pF},  \text{Rb} = 2.7~\text{k}\Omega$                    | 0                   | 355         | ns   |
|                 |  | $2.4 \text{ V} \le \text{VDD} < 3.3 \text{ V}, 1.6 \text{ V} \le \text{Vb} \le 2.0 \text{ V}$ Note 2, Cb = 100 pF, Rb = 5.5 k $\Omega$  | 0                   | 405         | ns   |

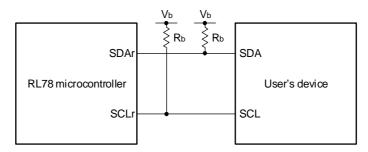
- **Note 1.** The value must also be equal to or less than fMCK/4.
- Note 2. Use it with  $VDD \ge Vb$ .
- **Note 3.** Set the fMCK value to keep the hold time of SCLr = "L" and SCLr = "H".

Caution Select the TTL input buffer and the N-ch open drain output (VDD tolerance) mode for the SDAr pin and the N-ch open drain output (VDD tolerance) mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and VIL, see the DC characteristics with TTL input buffer selected.

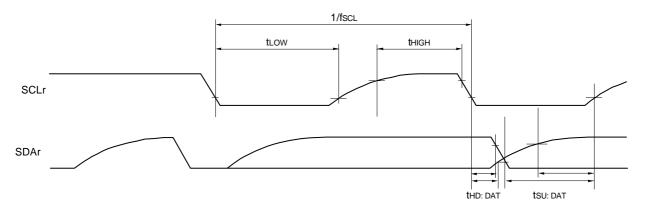
(Remarks are listed on the next page.)



#### Simplified I<sup>2</sup>C mode connection diagram (during communication at different potential)



#### Simplified I<sup>2</sup>C mode serial transfer timing (during communication at different potential)



Remark 1.  $Rb[\Omega]$ : Communication line (SDAr, SCLr) pull-up resistance, Cb[F]: Communication line (SDAr, SCLr) load capacitance, Vb[V]: Communication line voltage

**Remark 2.** r: IIC number (r = 00, 10, 20), g: PIM, POM number (g = 0, 1, 3, 4, 5, 8)

Remark 3. fmck: Serial array unit operation clock frequency (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number (m = 0, 1), n: Channel number (n = 0, 2), mn = 00, 02, 10)

#### 2.5.2 Serial interface IICA

#### (1) I<sup>2</sup>C standard mode

(TA = -40 to +85°C, 2.4 V  $\leq$  AVDD = VDD  $\leq$  5.5 V, AVSS = VSS = 0 V)

| Parameter                            | Symbol   | Conditions          |                     | HS (high-s | Unit |     |
|--------------------------------------|----------|---------------------|---------------------|------------|------|-----|
|                                      |          |                     |                     |            | MAX. |     |
| SCLA0 clock frequency                | fSCL     | Standard mode:      | 2.7 V ≤ VDD ≤ 5.5 V | 0          | 100  | kHz |
|                                      |          | fclk ≥ 1 MHz        | 2.4 V ≤ VDD ≤ 5.5 V | 0          | 100  | kHz |
| Setup time of restart condition      | tsu: sta | 2.7 V ≤ VDD ≤ 5.5 V |                     | 4.7        |      | μs  |
|                                      |          | 2.4 V ≤ VDD ≤ 5.5 V |                     | 4.7        |      | μs  |
| Hold time Note 1                     | tHD: STA | 2.7 V ≤ VDD ≤ 5.5 V |                     | 4.0        |      | μs  |
|                                      |          | 2.4 V ≤ VDD ≤ 5.5 V |                     | 4.0        |      | μs  |
| Hold time                            | tLOW     | 2.7 V ≤ VDD ≤ 5.5 V |                     | 4.7        |      | μs  |
| when SCLA0 = "L"                     |          | 2.4 V ≤ VDD ≤ 5.5 V |                     | 4.7        |      | μs  |
| Hold time                            | tHIGH    | 2.7 V ≤ VDD ≤ 5.5 V |                     | 4.0        |      | μs  |
| when SCLA0 = "H"                     |          | 2.4 V ≤ VDD ≤ 5.5 V |                     | 4.0        |      | μs  |
| Data setup time (reception)          | tsu: DAT | 2.7 V ≤ VDD ≤ 5.5 V |                     | 250        |      | ns  |
|                                      |          | 2.4 V ≤ VDD ≤ 5.5 V |                     | 250        |      | ns  |
| Data hold time (transmission) Note 2 | thd: dat | 2.7 V ≤ VDD ≤ 5.5 V |                     | 0          | 3.45 | μs  |
|                                      |          | 2.4 V ≤ VDD ≤ 5.5 V |                     | 0          |      | μs  |
| Setup time of stop condition         | tsu: sto | 2.7 V ≤ VDD ≤ 5.5 V |                     | 4.0        |      | μs  |
|                                      |          | 2.4 V ≤ VDD ≤ 5.5 V |                     | 4.0        |      | μs  |
| Bus-free time                        | tBUF     | 2.7 V ≤ VDD ≤ 5.5 V |                     | 4.7        |      | μs  |
|                                      |          | 2.4 V ≤ VDD ≤ 5.5 V |                     | 4.7        |      | μs  |

Note 1. The first clock pulse is generated after this period when the start/restart condition is detected.

**Note 2.** The maximum value (MAX.) of thd:DAT is during normal transfer and a clock stretch state is inserted in the ACK (acknowledge) timing.

Remark The maximum value of Cb (communication line capacitance) and the value of Rb (communication line pull-up resistor) at that time in each mode are as follows.

Standard mode: Cb = 400 pF,  $Rb = 2.7 \text{ k}\Omega$ 

#### (2) I2C fast mode

#### (TA = -40 to +85°C, 2.4 V $\leq$ AVDD = VDD $\leq$ 5.5 V, AVSS = VSS = 0 V)

| Parameter                            | Symbol   | Conditions                                 |                     | , , | HS (high-speed main)<br>Mode |     |  |
|--------------------------------------|----------|--|---------------------|-----|------------------------------|-----|--|
|                                      |          |  |                     |     | MAX.                         |     |  |
| SCLA0 clock frequency                | fscL     | Fast mode:                                 | 2.7 V ≤ VDD ≤ 5.5 V | 0   | 400                          | kHz |  |
|                                      |          | fCLK ≥ 3.5 MHz                             | 2.4 V ≤ VDD ≤ 5.5 V | 0   | 400                          | kHz |  |
| Setup time of restart condition      | tsu: sta | 2.7 V ≤ VDD ≤ 5.5 V                        |                     | 0.6 |                              | μs  |  |
|                                      |          | 2.4 V ≤ VDD ≤ 5.5 V                        |                     | 0.6 |                              | μs  |  |
| Hold time Note 1                     | thd: STA | 2.7 V ≤ VDD ≤ 5.5 V<br>2.4 V ≤ VDD ≤ 5.5 V |                     | 0.6 |                              | μs  |  |
|                                      |          |  |                     | 0.6 |                              | μs  |  |
| Hold time when SCLA0 = "L"           | tLOW     | 2.7 V ≤ VDD ≤ 5.5 V                        |                     | 1.3 |                              | μs  |  |
|                                      |          | 2.4 V ≤ VDD ≤ 5.5 V                        |                     | 1.3 |                              | μs  |  |
| Hold time when SCLA0 = "H"           | tHIGH    | 2.7 V ≤ VDD ≤ 5.5 V                        |                     | 0.6 |                              | μs  |  |
|                                      |          | 2.4 V ≤ VDD ≤ 5.5 V                        |                     | 0.6 |                              | μs  |  |
| Data setup time (reception)          | tsu: dat | 2.7 V ≤ VDD ≤ 5.5 V                        |                     | 100 |                              | ns  |  |
|                                      |          | 2.4 V ≤ VDD ≤ 5.5 V                        |                     | 100 |                              | ns  |  |
| Data hold time (transmission) Note 2 | thd: dat | 2.7 V ≤ VDD ≤ 5.5 V                        |                     | 0   | 0.9                          | μs  |  |
|                                      |          | 2.4 V ≤ VDD ≤ 5.5 V                        |                     | 0   |                              | μs  |  |
| Setup time of stop condition         | tsu: sto | 2.7 V ≤ VDD ≤ 5.5 V                        |                     | 0.6 |                              | μs  |  |
|                                      |          | 2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V            |                     | 0.6 |                              | μs  |  |
| Bus-free time                        | tBUF     | 2.7 V ≤ VDD ≤ 5.5 V                        |                     | 1.3 |                              | μs  |  |
|                                      |          | 2.4 V ≤ VDD ≤ 5.5 V                        |                     | 1.3 |                              | μs  |  |

**Note 1.** The first clock pulse is generated after this period when the start/restart condition is detected.

**Note 2.** The maximum value (MAX.) of thd: DAT is during normal transfer and a clock stretch state is inserted in the ACK (acknowledge) timing.

Remark

The maximum value of  $C_b$  (communication line capacitance) and the value of  $R_b$  (communication line pull-up resistor) at that time in each mode are as follows.

Fast mode: Cb = 320 pF,  $Rb = 1.1 \text{ k}\Omega$ 

#### (3) I2C fast mode plus

#### $(TA = -40 \text{ to } +85^{\circ}C, 2.4 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$

| Parameter                            | Symbol   | Symbol Conditions                |                     | HS (high-speed main)<br>Mode |      | Unit |
|--------------------------------------|----------|----------------------------------|---------------------|------------------------------|------|------|
|                                      |          |                                  |                     | MIN.                         | MAX. |      |
| SCLA0 clock frequency                | fscL     | Fast mode plus:<br>fcLk ≥ 10 MHz | 2.7 V ≤ VDD ≤ 5.5 V | 0                            | 1000 | kHz  |
| Setup time of restart condition      | tsu: sta | 2.7 V ≤ VDD ≤ 5.5 V              |                     | 0.26                         |      | μs   |
| Hold time Note 1                     | thd: STA | 2.7 V ≤ VDD ≤ 5.5 V              |                     | 0.26                         |      | μs   |
| Hold time when SCLA0 = "L"           | tLOW     | 2.7 V ≤ VDD ≤ 5.5 V              |                     | 0.5                          |      | μs   |
| Hold time when SCLA0 = "H"           | tHIGH    | 2.7 V ≤ VDD ≤ 5.5 V              |                     | 0.26                         |      | μs   |
| Data setup time (reception)          | tsu: dat | 2.7 V ≤ VDD ≤ 5.5 V              |                     | 50                           |      | ns   |
| Data hold time (transmission) Note 2 | thd: dat | 2.7 V ≤ VDD ≤ 5.5 V              |                     | 0                            | 0.45 | μs   |
| Setup time of stop condition         | tsu: sto | 2.7 V ≤ VDD ≤ 5.5 V              |                     | 0.26                         |      | μs   |
| Bus-free time                        | tBUF     | 2.7 V ≤ VDD ≤ 5.5 V              |                     | 0.5                          |      | μs   |

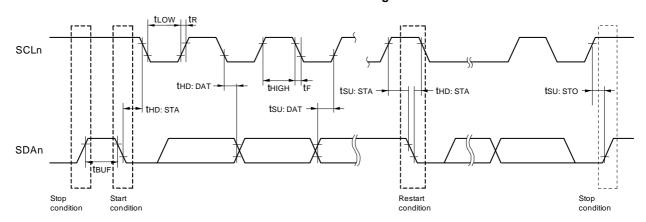
Note 1. The first clock pulse is generated after this period when the start/restart condition is detected.

**Note 2.** The maximum value (MAX.) of thd: DAT is during normal transfer and a clock stretch state is inserted in the ACK (acknowledge) timing.

Remark The maximum value of Cb (communication line capacitance) and the value of Rb (communication line pull-up resistor) at that time in each mode are as follows.

Fast mode plus:  $C_b = 120$  pF,  $R_b = 1.1$  k $\Omega$ 

#### **IICA** serial transfer timing



## 2.6 Analog Characteristics

#### 2.6.1 A/D converter characteristics

(1) When reference voltage (+) = VDD (ADREFP1 = 0, ADREFP0 = 0), reference voltage (-) = Vss (ADREFM = 0), target pin: ANI8 to ANI14, internal reference voltage, and temperature sensor output voltage

(TA = -40 to +85°C, 2.4 V  $\leq$  AVDD = VDD  $\leq$  5.5 V, AVSS = VSS = 0 V, reference voltage (+) = VDD, reference voltage (-) = VSS)

| Parameter                              | Symbol | Conditions   |                     | MIN.   | TYP. | MAX.  | Unit |
|--|--------|--|---------------------|--------|------|-------|------|
| Resolution                             | RES    |  |                     | 8      |      | 10    | bit  |
| Overall error Note 1                   | AINL   | 10-bit resolution  | 2.4 V ≤ VDD ≤ 5.5 V |        | 1.2  | ±7.0  | LSB  |
| Conversion time                        | tCONV  | 10-bit resolution  | 3.6 V ≤ VDD ≤ 5.5 V | 2.125  |      | 39    | μs   |
|  |        | Target pin: ANI8 to ANI14  | 2.7 V ≤ VDD ≤ 5.5 V | 3.1875 |      | 39    | μs   |
|  |        |  | 2.4 V ≤ VDD ≤ 5.5 V | 17     |      | 39    | μs   |
|  |        | 10-bit resolution  | 3.6 V ≤ VDD ≤ 5.5 V | 2.375  |      | 39    | μs   |
|  |        | Target pin: internal reference voltage and                                     | 2.7 V ≤ VDD ≤ 5.5 V | 3.5626 |      | 39    | μs   |
|  |        | temperature sensor output voltage (HS (high-speed main) mode)                  | 2.4 V ≤ VDD ≤ 5.5 V | 17     |      | 39    | μs   |
| Zero-scale error<br>Notes 1, 2         | Ezs    | 10-bit resolution  | 2.4 V ≤ VDD ≤ 5.5 V |        |      | ±0.60 | %FSR |
| Full-scale error<br>Notes 1, 2         | EFS    | 10-bit resolution  | 2.4 V ≤ VDD ≤ 5.5 V |        |      | ±0.60 | %FSR |
| Integral linearity<br>error Note 1     | ILE    | 10-bit resolution  | 2.4 V ≤ VDD ≤ 5.5 V |        |      | ±4.0  | LSB  |
| Differential linearity<br>error Note 1 | DLE    | 10-bit resolution  | 2.4 V ≤ VDD ≤ 5.5 V |        |      | ±2.0  | LSB  |
| Analog input voltage                   | VAIN   | ANI8 to ANI11  | •                   | 0      |      | VDD   | V    |
|  |        | ANI12 to ANI14   |                     | 0      |      | AVDD  | V    |
|  |        | Internal reference voltage<br>(2.4 V ≤ VDD ≤ 5.5 V, HS (high-speed main) mode) |                     |        | V    |       |      |
|  |        | Temperature sensor output voltage (2.4 V ≤ VDD ≤ 5.5 V, HS (high-speed main)   | mode)               | V      | V    |       |      |

- Note 1. Excludes quantization error (±1/2 LSB).
- Note 2. This value is indicated as a ratio (%FSR) to the full-scale value.
- Note 3. Refer to 2.6.2 Temperature sensor/internal reference voltage output characteristics.

# (2) When reference voltage (+) = Internal reference voltage (ADREFP1 = 1, ADREFP0 = 0), reference voltage (-) = Vss (ADREFM = 0), target pin: ANI8 to ANI11, ANI12 to ANI14

(TA = -40 to +85°C, 2.4 V  $\leq$  AVDD = VDD  $\leq$  5.5 V, AVSS = VSS = 0 V, reference voltage (+) = VBGR Note 3, reference voltage (-) = VSS = 0 V, HS (high-speed main) mode)

| Parameter                           | Symbol | Conditions       |                     | MIN. | TYP. | MAX.           | Unit |
|-------------------------------------|--------|------------------|---------------------|------|------|----------------|------|
| Resolution                          | RES    |                  |                     | 8    |      | 3              | bit  |
| Conversion time                     | tCONV  | 8-bit resolution | 2.4 V ≤ VDD ≤ 5.5 V | 17   |      | 39             | μs   |
| Zero-scale error Notes 1, 2         | Ezs    | 8-bit resolution | 2.4 V ≤ VDD ≤ 5.5 V |      |      | ±(0.60 + 0.35) | %FSR |
| Integral linearity error Note 1     | ILE    | 8-bit resolution | 2.4 V ≤ VDD ≤ 5.5 V |      |      | ±(2.0 + 0.5)   | LSB  |
| Differential linearity error Note 1 | DLE    | 8-bit resolution | 2.4 V ≤ VDD ≤ 5.5 V |      |      | ±(1.0 + 0.2)   | LSB  |
| Analog input voltage                | VAIN   |                  |                     | 0    |      | VBGR Note 3    | V    |

- Note 1. Excludes quantization error (±1/2 LSB).
- Note 2. This value is indicated as a ratio (%FSR) to the full-scale value.
- Note 3. Refer to 2.6.2 Temperature sensor/internal reference voltage output characteristics.

## 2.6.2 Temperature sensor/internal reference voltage output characteristics

(TA = -40 to +85°C, 2.4 V  $\leq$  AVDD = VDD  $\leq$  5.5 V, AVSS = VSS = 0 V, HS (high-speed main) mode)

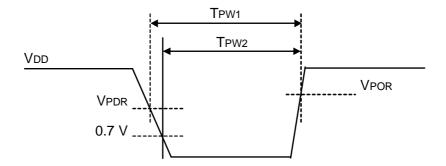
| Parameter                         | Symbol  | Conditions  | MIN. | TYP. | MAX. | Unit  |
|-----------------------------------|---------|---|------|------|------|-------|
| Temperature sensor output voltage | VTMPS25 | TA = +25°C  |      | 1.05 |      | V     |
| Internal reference voltage        | VBGR    |   | 1.38 | 1.45 | 1.5  | V     |
| Temperature coefficient           | FVTMPS  | Temperature sensor output voltage that depends on the temperature |      | -3.6 |      | mV/°C |
| Operation stabilization wait time | tamp    | 2.4 V ≤ VDD ≤ 5.5 V   | 5    |      |      | μs    |

#### 2.6.3 POR circuit characteristics

 $(TA = -40 \text{ to } +85^{\circ}C, Vss = 0 \text{ V})$ 

| Parameter                  | Symbol | Conditions                       | MIN. | TYP. | MAX. | Unit |
|----------------------------|--------|----------------------------------|------|------|------|------|
| Detection voltage          | VPOR   | Power supply rise time           | 1.47 | 1.51 | 1.55 | V    |
|                            | VPDR   | Power supply fall timeNote 1     | 1.46 | 1.50 | 1.54 | V    |
| Minimum pulse width Note 2 | TPW1   | Other than STOP/SUB HALT/SUB RUN | 300  |      |      | μs   |
|                            | TPW2   | STOP/SUB HALT/SUB RUN            | 300  |      |      | μs   |

- **Note 1.** If the power supply voltage falls while the voltage detector is off, be sure to either shift to STOP mode or execute a reset by using the voltage detector or external reset pin before the power supply voltage falls below the minimum operating voltage specified in 2.4 AC Characteristics.
- Note 2. Minimum time required for a POR reset when VDD falls below VPDR. This is also the minimum time required for a POR reset from when VDD exceeds below 0.7 V to when VDD exceeds VPOR while STOP mode is entered or the main system clock is stopped through setting bit 0 (HIOSTOP) and bit 7 (MSTOP) in the clock operation status control register (CSC).



#### 2.6.4 LVD circuit characteristics

# (1) LVD Detection Voltage of Reset Mode and Interrupt Mode (TA = -40 to +85°C, VPDR $\leq$ AVDD = VDD $\leq$ 5.5 V, AVSS = VSS = 0 V)

|              | Parameter            | Symbol | Conditions             | MIN. | TYP. | MAX. | Unit |
|--------------|----------------------|--------|------------------------|------|------|------|------|
| Detection    | Supply voltage level | VLVD0  | Power supply rise time | 3.98 | 4.06 | 4.14 | V    |
| voltage      |                      |        | Power supply fall time | 3.90 | 3.98 | 4.06 | V    |
|              |                      | VLVD1  | Power supply rise time | 3.68 | 3.75 | 3.82 | V    |
|              |                      |        | Power supply fall time | 3.60 | 3.67 | 3.74 | V    |
|              |                      | VLVD2  | Power supply rise time | 3.07 | 3.13 | 3.19 | V    |
|              |                      |        | Power supply fall time | 3.00 | 3.06 | 3.12 | V    |
|              |                      | VLVD3  | Power supply rise time | 2.96 | 3.02 | 3.08 | V    |
|              |                      |        | Power supply fall time | 2.90 | 2.96 | 3.02 | V    |
|              |                      | VLVD4  | Power supply rise time | 2.86 | 2.92 | 2.97 | V    |
|              |                      |        | Power supply fall time | 2.80 | 2.86 | 2.91 | V    |
|              |                      | VLVD5  | Power supply rise time | 2.76 | 2.81 | 2.87 | V    |
|              |                      |        | Power supply fall time | 2.70 | 2.75 | 2.81 | V    |
|              |                      | VLVD6  | Power supply rise time | 2.66 | 2.71 | 2.76 | V    |
|              |                      |        | Power supply fall time | 2.60 | 2.65 | 2.70 | V    |
|              |                      | VLVD7  | Power supply rise time | 2.56 | 2.61 | 2.66 | V    |
|              |                      |        | Power supply fall time | 2.50 | 2.55 | 2.60 | V    |
|              |                      | VLVD8  | Power supply rise time | 2.45 | 2.50 | 2.55 | V    |
|              |                      |        | Power supply fall time | 2.40 | 2.45 | 2.50 | V    |
| Minimum pul  | lse width            | tLW    |                        | 300  |      |      | μs   |
| Detection de | lay time             |        |                        |      |      | 300  | μs   |

Caution Set the detection voltage (VLVD) to be within the operating voltage range. The operating voltage range depends on the setting of the user option byte (000C2H/010C2H). The following shows the operating voltage range.

HS (high-speed main) mode: VDD = 2.7 to 5.5 V @ 1 MHz to 24 MHz

 $\ensuremath{\text{VDD}}$  = 2.4 to 5.5 V @ 1 MHz to 16 MHz

## (2) LVD Detection Voltage of Interrupt & Reset Mode

(TA = -40 to +85°C, VPDR  $\leq$  AVDD = VDD  $\leq$  5.5 V, AVSS = VSS = 0 V)

| Parameter           | Symbol |                 | Со               | nditions                       | MIN. | TYP. | MAX. | Unit |
|---------------------|--------|-----------------|------------------|--------------------------------|------|------|------|------|
| Interrupt and reset | VLVDC0 | VPOC2, VPOC1, V | /POC0 = 0, 1, 0, | falling reset voltage: 2.4 V   | 2.40 | 2.45 | 2.50 | V    |
| mode                | VLVDC1 | LVIS1, L        | VIS0 = 1, 0      | Rising release reset voltage   | 2.56 | 2.61 | 2.66 | V    |
|                     |        |                 |                  | Falling interrupt voltage      | 2.50 | 2.55 | 2.60 | V    |
|                     | VLVDC2 | LVIS1, L        | VIS0 = 0, 1      | Rising release reset voltage   | 2.66 | 2.71 | 2.76 | V    |
|                     |        |                 |                  | Falling interrupt voltage      | 2.60 | 2.65 | 2.70 | V    |
| VLVDC3              |        | LVIS1, L        | VIS0 = 0, 0      | Rising release reset voltage   | 3.68 | 3.75 | 3.82 | V    |
|                     |        |                 |                  | Falling interrupt voltage      | 3.60 | 3.67 | 3.74 | V    |
|                     | VLVDD0 | VPOC2, VPOC1, V | /POC0 = 0, 1, 1  | , falling reset voltage: 2.7 V | 2.70 | 2.75 | 2.81 | V    |
|                     | VLVDD1 | LVIS1, L        | VIS0 = 1, 0      | Rising release reset voltage   | 2.86 | 2.92 | 2.97 | V    |
|                     |        |                 |                  | Falling interrupt voltage      | 2.80 | 2.86 | 2.91 | V    |
|                     | VLVDD2 | LVIS1, L        | VIS0 = 0, 1      | Rising release reset voltage   | 2.96 | 3.02 | 3.08 | V    |
|                     |        |                 |                  | Falling interrupt voltage      | 2.90 | 2.96 | 3.02 | V    |
|                     | VLVDD3 |                 | VIS0 = 0, 0      | Rising release reset voltage   | 3.98 | 4.06 | 4.14 | V    |
|                     |        |                 |                  | Falling interrupt voltage      | 3.90 | 3.98 | 4.06 | V    |

### 2.6.5 Programmable gain instrumentation amplifier and 24-bit $\Delta\Sigma$ A/D converter

#### (1) Analog input in differential input mode

(TA = -40 to +85°C, 2.7 V  $\leq$  AVDD = VDD  $\leq$  5.5 V, AVSS = VSS = 0 V, normal mode: fs1 = 1 MHz, FDATA1 = 3.90625 ksps, low-power mode: fs2 = 0.125 MHz, FDATA2 = 488.28125 sps, SBIAS = 2.1 V, dofr = 0 mV, Vcom = 1.0 V, external clock input used)

| Parameter                                   | Symbol | Conditions                         | MIN.                     | TYP.             | MAX.                     | Unit |
|---|--------|------------------------------------|--------------------------|------------------|--------------------------|------|
| Full-scale differential input voltage range | VID    | VID = (PGA0xP - PGA0xN) (x = 0, 1) | _                        | ±800<br>/GTOTAL0 | _                        | mV   |
| Input voltage range                         | Vı     |                                    | 0.2                      | _                | 1.8                      | V    |
| Common mode input voltage range             | Vсом   | dofr = 0 mV                        | 0.2+( VID X<br>GSET01)/2 | _                | 1.8-( VID X<br>GSET01)/2 | V    |
| Input bias current                          | lin    | VI = 1.0 V                         |                          |                  | ±50                      | nA   |
| Input offset current                        | lino   | VI = 1.0 V                         |                          |                  | ±20                      | nA   |

#### (2) Analog input in single-ended input mode

(TA = -40 to +85°C, 2.7 V  $\leq$  AVDD = VDD  $\leq$  5.5 V, AVSS = VSS = 0 V, normal mode: fs1 = 1 MHz, FDATA1 = 3.90625 ksps, low-power mode: fs2 = 0.125 MHz, FDATA2 = 488.28125 sps, SBIAS = 2.1 V, dofr = 0 mV, Vcom = 1.0 V, external clock input used)

| Parameter           | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---------------------|--------|------------|------|------|------|------|
| Input voltage range | Vı     |            | 0.2  | -    | 1.8  | V    |
| Input bias current  | lin    | VI = 1.0 V |      |      | ±50  | nA   |

#### (3) Programmable gain instrumentation amplifier and 24-bit $\Delta\Sigma$ A/D converter

(TA = -40 to +85°C, 2.7 V  $\leq$  AVDD = VDD  $\leq$  5.5 V, AVSS = VSS = 0 V, normal mode: fs1 = 1 MHz, FDATA1 = 3.90625 ksps, low-power mode: fs2 = 0.125 MHz, FDATA2 = 488.28125 sps, SBIAS = 2.1 V, dofr = 0 mV, Vcom = 1.0 V, external clock input used, in differential input mode) (1/2)

| Parameter                   | Symbol  | Conditions                | MIN.         | TYP.          | MAX.         | Unit |
|-----------------------------|---------|---------------------------|--------------|---------------|--------------|------|
| Resolution                  | RES     |                           |              |               | 24           | bit  |
| Sampling frequency          | fs1     | Normal mode               |              | 1             |              | MHz  |
|                             | fs2     | Low-power mode            |              | 0.125         |              | MHz  |
| Output data rate            | fDATA1  | Normal mode               | 0.488        |               | 15.625       | ksps |
|                             | fDATA2  | Low-power mode            | 61.035       |               | 1953.125     | sps  |
| Gain setting range          | GTOTAL0 | GTOTAL0 = GSET01 x GSET02 | 1            |               | 64           | V/V  |
| 1st gain setting range      | GSET01  |                           |              | 1, 2, 3, 4, 8 |              | V/V  |
| 2nd gain setting range      | GSET02  |                           |              | 1, 2, 4, 8    |              | V/V  |
| Offset adjustment bit range | doffB   |                           |              | 5             |              | bit  |
| Offset adjustment range     | dofr    | Referred to input         | - 164/GSET01 |               | + 164/GSET01 | mV   |
| Offset adjustment steps     | dors    | Referred to input         |              | 11/GSET01     |              | mV   |

 $(TA = -40 \text{ to } +85^{\circ}\text{C}, 2.7 \text{ V} \le \text{AVDD} = \text{VDD} \le 5.5 \text{ V}, \text{AVSS} = \text{VSS} = 0 \text{ V}, \text{normal mode: fs1} = 1 \text{ MHz}, \text{FDATA1} = 3.90625 \text{ ksps, low-power mode: fs2} = 0.125 \text{ MHz}, \text{FDATA2} = 488.28125 \text{ sps, SBIAS} = 2.1 \text{ V}, \text{dofr} = 0 \text{ mV}, \text{VCoM} = 1.0 \text{ V}, \text{external clock input used, in differential input mode)}$  (2/2)

| Parameter                              | Symbol | Conditions  | MIN. | TYP.    | MAX.    | Unit   |
|--|--------|---|------|---------|---------|--------|
| Gain error                             | EG0    | TA = 25°C GSET01 = 1, GSET02 = 1 Excluding SBIAS error            |      | ±0.2    | ±2.7    | %      |
|  |        | TA = 25°C GSET01 = 8, GSET02 = 4 Excluding SBIAS error            |      | ±0.1    |         | %      |
| Gain drift Note                        | dEG0   | GSET01 = 1, GSET02 = 1<br>Excluding SBIAS drift                   |      | (5.6)   | (22.0)  | ppm/°C |
|  |        | GSET01 = 8, GSET02 = 4 Excluding SBIAS drift                      |      | (9.1)   |         | ppm/°C |
| Offset error                           | EOS0   | TA = 25°C<br>GSET01 = 1, GSET02 = 1<br>Referred to input          |      | ±0.32   | ±2.90   | mV     |
|  |        | TA = 25°C GSET01 = 8, GSET02 = 4 Referred to input                |      | ±0.03   |         | mV     |
| Offset drift Note                      | dEos   | GSET01 = 1, GSET02 = 1<br>Referred to input                       |      | (±0.02) | (±6.00) | μV/°C  |
|  |        | GSET01 = 8, GSET02 = 4 Referred to input                          |      | (±0.02) |         | μV/°C  |
| SND ratio                              | SNDR   | GSET01 = 1, GSET02 = 1, fin = 50 Hz<br>Normal mode, Pin = -1 dBFS | (82) | (85)    |         | dB     |
|  |        | GSET01 = 8, GSET02 = 4, fin = 50 Hz<br>Normal mode, Pin = -1 dBFS | (73) | (80)    |         | dB     |
| Noise                                  | Vn     | GSET01 = 1, GSET02 = 1, OSR = 2048                                |      | (13)    |         | μVRms  |
|  |        | GSET01 = 8, GSET02 = 4, OSR = 2048                                |      | (0.6)   |         | μVRms  |
| Integral non-linearity error           | INL    | GSET01 = 1, GSET02 = 1, OSR = 2048                                |      | (±10)   |         | ppmFS  |
| Common mode rejection ratio            | CMRR0  | VCOM = 1.0±0.8 V, fin = 50 Hz<br>GSET01 = 1, GSET02 = 1           | (72) | (90)    |         | dB     |
| Power supply rejection ratio           | PSRR0  | AVDD = 2.7 to 5.5 V,<br>GSET01 = 1, GSET02 = 1                    | (60) | (85)    |         | dB     |
| ΔΣ A/D converter input clock frequency | fADC   |   | 3.8  | 4.0     | 4.2     | MHz    |

**Note** Calculate the gain drift and offset drift by using the following expression (for 85°C products):

For gain drift: (MAX(EG(T(-40) to T(85))) - MIN(EG(T(-40) to T(85)))) / (85°C -(-40°C))

For offset drift: (MAX(EOS(T(-40) to T(85))) - MIN(EOS(T(-40) to T(85)))) / (85°C -(-40°C))

MAX(EG(T(-40) to T(85))): The maximum value of gain error when the temperature range is -40°C to 85°C MIN(EG(T(-40) to T(85))): The minimum value of offset error when the temperature range is -40°C to 85°C MAX(EOS(T(-40) to T(85))): The maximum value of offset error when the temperature range is -40°C to 85°C MIN(EOS(T(-40) to T(85))): The minimum value of offset error when the temperature range is -40°C to 85°C

Remark 1. Values in parentheses are target design values (i.e. not guaranteed) and therefore are not tested for shipment.

**Remark 2.** The typical conditions are the conditions when  $TA = 25^{\circ}C$  and AVDD = 3.3 V.

## 2.6.6 Sensor power supply (SBIAS)

(TA = -40 to +85°C, 2.7 V  $\leq$  AVDD = VDD  $\leq$  5.5 V, AVSS = VSS = 0 V, COUT = 0.22  $\mu$ F, VOUT = 1.0 V)

| Parameter                       | Symbol | Conditions  | MIN.  | TYP. | MAX.  | Unit |
|---------------------------------|--------|---|-------|------|-------|------|
| Output voltage range            | Vout   |   | 0.5   |      | 2.2   | V    |
| Output voltage adjustment steps | VSTEP  |   |       | 0.1  |       | V    |
| Output voltage precision        | VA     | IOUT = 1 mA   | (- 3) |      | (+ 3) | %    |
| Maximum output current          | Іоит   |   | 5     |      |       | mA   |
| Short circuit current           | ISHORT | VOUT = 0 V  |       | 40   | 65    | mA   |
| Load regulation                 | LR     | 1 mA ≤ lout ≤ 5 mA  |       |      | (15)  | mV   |
| Power supply rejection ratio    | PSRR   | AVDD = 5.0 V + 0.1 Vpp ripple<br>f = 100 Hz, Iout = 2.5 mA,<br>Vout = 2.1 V | (45)  | (70) |       | dB   |

Remark 1. Values in parentheses are target design values (i.e. not guaranteed) and therefore are not tested for shipment.

**Remark 2.** The typical conditions are the conditions when  $TA = 25^{\circ}C$  and AVDD = 3.3 V.

### 2.6.7 Internal BIAS power supply

#### $(TA = -40 \text{ to } +85^{\circ}C, 2.7 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$

| Parameter      | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|----------------|--------|------------|------|------|------|------|
| Output voltage | VBIAS  |            | 0.95 | 1.00 | 1.05 | V    |

**Remark** The typical conditions are the conditions when TA = 25°C and AVDD = 3.3 V.

## 2.6.8 Programmable gain instrumentation amplifier (PGA1)

## (TA = -40 to +85°C, 2.7 V $\leq$ AVDD = VDD $\leq$ 5.5 V, AVSS = VSS = 0 V)

(1/2)

| •                      |         |                         |                |          |                |        |
|------------------------|---------|-------------------------|----------------|----------|----------------|--------|
| Parameter              | Symbol  | Conditions              | MIN.           | TYP.     | MAX.           | Unit   |
| Differential input     | VID     | VID = (PGA1xP - PGA1xN) |                | ±800     |                | mV     |
| voltage range          |         | (x = 0, 1)              |                | /GTOTAL1 |                |        |
| Input voltage range    | VIN     |                         | 0.3            |          | AVDD - 0.6     | V      |
| Common mode input      | Vсом    |                         | 0.3+           |          | AVDD-0.6+      | V      |
| voltage range          |         |                         | (( VID + EOS ) |          | (( VID + EOS ) |        |
|                        |         |                         | ×GSET11)/2     |          | ×GSET11)/2     |        |
| Output voltage range   | Vout    |                         | 0.1            |          | AVDD - 0.1     | V      |
| Maximum output         | IOUT    |                         | -0.1           |          | +0.1           | mA     |
| current                |         |                         |                |          |                |        |
| Input bias current     | lin     |                         |                |          | ±50            | nA     |
| Input bias offset      | Ios     |                         |                |          | ±20            | nA     |
| current                |         |                         |                |          |                |        |
| Gain setting range     | GTOTAL1 |                         |                | GSET11 × |                | V/V    |
|                        |         |                         |                | GSET12   |                |        |
| 1st gain setting range | GSET11  |                         |                | 12, 16,  |                | V/V    |
|                        |         |                         |                | 20, 24   |                |        |
| 2nd gain setting range | GSET12  |                         |                | Note     |                | V/V    |
| Gain error             | EG1     | TA = 25°C               |                |          | ±2.7           | %      |
|                        |         | GSET11 = 24, GSET12 = 1 |                |          |                |        |
| Gain drift             | dEG1    | GSET11 = 24, GSET12 = 1 |                | (5.6)    | (22.0)         | ppm/°C |
| Offset error           | Eos1    | TA = 25°C               | -10            |          | +10            | mV     |
|                        |         | GSET11 = 24, GSET12 = 1 |                |          |                |        |
|                        |         | Referred to input       |                |          |                |        |
| Bandwidth              | BW11    | Low-power mode          |                | (1.5)    |                | kHz    |
|                        |         | GSET11 = 24, GSET12 = 1 |                |          |                |        |
|                        | BW12    | High-speed mode         |                | (67)     |                | kHz    |
|                        |         | GSET11 = 24, GSET12 = 1 |                |          |                |        |
| Slew rate              | SR11    | Low-power mode          |                | (6)      |                | mV/µs  |
|                        | SR12    | High-speed mode         |                | (220)    |                | mV/μs  |
| Peak-to-peak voltage   | Enb11   | 0.1 Hz to 10 Hz         |                | (3.0)    |                | μVrms  |
| noise                  |         | Low-power mode          |                |          |                |        |
|                        | Enb12   | 0.1 Hz to 10 Hz         |                | (2.6)    |                | μVrms  |
|                        | 1       | High-speed mode         |                | 1        |                | 1      |

**Note** See the setting of PGA1GC3 to PGA1GC0.

#### (TA = -40 to +85°C, 2.7 V $\leq$ AVDD = VDD $\leq$ 5.5 V, AVSS = VSS = 0 V)

(2/2)

| Parameter                    | Symbol | Conditions   | MIN. | TYP.  | MAX. | Unit       |
|------------------------------|--------|--|------|-------|------|------------|
| Input-referred noise         | En11   | f = 1 kHz<br>Low-power mode  |      | (210) |      | nV/<br>√Hz |
|                              | En12   | f = 1 kHz<br>High-speed mode   |      | (110) |      | nV/<br>√Hz |
|                              | En13   | f = 10 Hz<br>Low-power mode  |      | (460) |      | nV/<br>√Hz |
|                              | En14   | f = 10 Hz<br>High-speed mode   |      | (410) |      | nV/<br>√Hz |
| Common mode rejection ratio  | CMRR1  | GSET11 = 24, GSET12 = 1<br>f = 50 Hz   |      | (100) |      | dB         |
| Power supply rejection ratio | PSRR1  | 2.7 V ≤ AVDD ≤ 5.5 V<br>f = 50 Hz<br>When SBIAS is selected as the reference<br>voltage of the 12-bit D/A converter. |      | (80)  |      | dB         |

Remark 1. Values in parentheses are target design values (i.e. not guaranteed) and therefore are not tested for shipment.

**Remark 2.** The typical conditions are the conditions when TA = 25°C and AVDD = 3.3 V.

Remark 3. Unless otherwise specified, values are for operation in high-speed mode.

# 2.6.9 Operational amplifier 0 (AMP0)

(TA = -40 to +85°C, 2.7 V  $\leq$  AVDD = VDD  $\leq$  5.5 V, AVSS = VSS = 0 V)

| Parameter                       | Symbol | Conditions  | MIN. | TYP.   | MAX.        | Unit       |
|---------------------------------|--------|---|------|--------|-------------|------------|
| Common mode input voltage range | Vсм    |   | 0.1  |        | AVDD - 0.1  | V          |
| Output voltage range            | Vout   | IOUT= ±1 mA   | 0.07 |        | AVDD - 0.15 | V          |
| Maximum output current          | lout   |   | (-2) |        | (+2)        | mA         |
| Input bias current              | lin    |   |      |        | ±50         | nA         |
| Input offset voltage            | Vos1   | Low-power mode  | -10  |        | +10         | mV         |
|                                 | Vos2   | High-speed mode   | -7   |        | +7          | mV         |
| Slew rate                       | SR1    | Low-power mode  |      | (0.04) |             | V/µs       |
|                                 | SR2    | High-speed mode   |      | (0.7)  |             | V/µs       |
| Gain bandwidth                  | GBW1   | Low-power mode  |      | (0.06) |             | MHz        |
|                                 | GBW2   | High-speed mode   |      | (1)    |             | MHz        |
| Phase margin                    | PM1    | Low-power mode  |      | (70)   |             | deg        |
|                                 | PM2    | High-speed mode   |      | (60)   |             | deg        |
| Settling time                   | Tset1  | Low-power mode $CL = 50 \text{ pF}, RL = 10 \text{ k}\Omega$                    |      |        | (300)       | μs         |
|                                 | Tset2  | High-speed mode $CL = 50$ pF, $RL = 10$ kΩ                                      |      |        | (14)        | μs         |
| Stabilization wait time         | Tstaw1 | AMPEn = 0 $\rightarrow$ 1,<br>Low-power mode<br>CL = 50 pF, RL = 10 k $\Omega$  |      |        | (300)       | μs         |
|                                 | Tstaw2 | AMPEn = 0 $\rightarrow$ 1,<br>High-speed mode<br>CL = 50 pF, RL = 10 k $\Omega$ |      |        | (14)        | μs         |
| Input-referred noise            | En1    | f = 1 kHz<br>Low-power mode   |      | (200)  |             | nV/<br>√Hz |
|                                 | En2    | f = 1 kHz<br>High-speed mode  |      | (80)   |             | nV/<br>√Hz |
| Common mode rejection ratio     | CMRR   | DC  |      | (70)   |             | dB         |
| Power supply rejection ratio    | PSRR   | DC  |      | (90)   |             | dB         |

Remark 1. Values in parentheses are target design values (i.e. not guaranteed) and therefore are not tested for shipment.

**Remark 2.** The typical conditions are the conditions when Ta =  $25^{\circ}$ C and AVDD = 3.3 V.

Remark 3. Unless otherwise specified, values are for operation in high-speed mode.

# 2.6.10 Operational amplifiers 1 and 2 (AMP1, AMP2)

(TA = -40 to +85°C, 2.7 V  $\leq$  AVDD = VDD  $\leq$  5.5 V, AVSS = VSS = 0 V)

| Parameter                       | Symbol | Conditions  | MIN. | TYP.   | MAX.       | Unit       |
|---------------------------------|--------|---|------|--------|------------|------------|
| Common mode input voltage range | Vсм1   | Low-power mode  | 0.2  |        | AVDD - 0.5 | V          |
|                                 | VCM2   | High-speed mode   | 0.3  |        | AVDD - 0.6 | V          |
| Output voltage range            | Vout   |   | 0.1  |        | AVDD - 0.1 | V          |
| Maximum output current          | IOUT   | 2.7 V ≤ AVDD ≤ 5.5 V  | -100 |        | +100       | μΑ         |
| Input bias current              | lin    |   |      |        | ±50        | nA         |
| Input offset voltage            | Vos1   | Low-power mode  | -10  |        | +10        | mV         |
|                                 | Vos2   | High-speed mode   | -10  |        | +10        | mV         |
| Slew rate                       | SR1    | Low-power mode  |      | (0.02) |            | V/µs       |
|                                 | SR2    | High-speed mode   |      | (1.1)  |            | V/µs       |
| Gain bandwidth                  | GBW1   | Low-power mode  |      | (0.04) |            | MHz        |
|                                 | GBW2   | High-speed mode   |      | (1.7)  |            | MHz        |
| Phase margin                    | PM1    | Low-power mode  |      | (70)   |            | deg        |
|                                 | PM2    | High-speed mode   |      | (60)   |            | deg        |
| Settling time                   | Tset1  | Low-power mode $CL = 50 \text{ pF}, RL = 10 \text{ k}\Omega$                    |      |        | (750)      | μs         |
|                                 | Tset2  | High-speed mode $CL = 50$ pF, $RL = 10$ kΩ                                      |      |        | (13)       | μs         |
| Stabilization wait time         | Tstaw1 | AMPEn = 0 $\rightarrow$ 1,<br>Low-power mode<br>CL = 50 pF, RL = 10 k $\Omega$  |      |        | (800)      | μs         |
|                                 | Tstaw2 | AMPEn = 0 $\rightarrow$ 1,<br>High-speed mode<br>CL = 50 pF, RL = 10 k $\Omega$ |      |        | (13)       | μs         |
| Input-referred noise            | En1    | f = 1 kHz<br>Low-power mode   |      | (230)  |            | nV/<br>√Hz |
|                                 | En2    | f = 1 kHz<br>High-speed mode  |      | (90)   |            | nV/<br>√Hz |
| Common mode rejection ratio     | CMRR   | DC  |      | (90)   |            | dB         |
| Power supply rejection ratio    | PSRR   | DC  |      | (90)   |            | dB         |

Remark 1. Values in parentheses are target design values (i.e. not guaranteed) and therefore are not tested for shipment.

**Remark 2.** The typical conditions are the conditions when TA =  $25^{\circ}$ C and AVDD = 3.3 V.

Remark 3. Unless otherwise specified, values are for operation in high-speed mode.

# 2.6.11 8-bit D/A converter (DAC0)

#### (TA = -40 to +85°C, 2.7 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V, reference voltage (+) = 2.1 V (SBIAS))

| Parameter                        | Symbol  | Conditions                                    | MIN. | TYP. | MAX. | Unit |
|----------------------------------|---------|---|------|------|------|------|
| Resolution                       | DARES0  |   |      |      | 8    | bit  |
| Absolute accuracy                | LE      | Note  |      |      | ±2.5 | LSB  |
| Differential non-linearity error | DADLE0  |   |      |      | ±2.0 | LSB  |
| Settling time                    | DAtset0 | $CL = 50 \text{ pF}, RL = 10 \text{ k}\Omega$ |      |      | (6)  | μs   |

Note Errors of the SBIAS output voltage are not included.

Remark 1. Values in parentheses are target design values (i.e. not guaranteed) and therefore are not tested for shipment.

Remark 2. The 8-bit D/A converter characteristics are the values obtained with the amplifier unit connected.

# 2.6.12 12-bit D/A converter (DAC1)

#### (1) When reference voltage (+) = 2.1 V (SBIAS)

#### (TA = -40 to +85°C, 2.7 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V, reference voltage (+) = 2.1 V (SBIAS))

| Parameter                        | Symbol  | Conditions  | MIN. | TYP. | MAX.  | Unit |
|----------------------------------|---------|---|------|------|-------|------|
| Resolution                       | DARES1  |   |      |      | (12)  | bit  |
| Output voltage range             | DAOUT   | 12-bit resolution   | 0.35 |      | SBIAS | V    |
| Integral non-linearity error     | DAILE   | 12-bit resolution   |      |      | ±4.0  | LSB  |
| Differential non-linearity error | DADLE1  | 12-bit resolution   |      |      | ±1.0  | LSB  |
| Offset error                     | DAErr   | 12-bit resolution   |      |      | ±30   | mV   |
| Gain error                       | DAEG    | 12-bit resolution Note  |      |      | ±20   | mV   |
| Settling time                    | DAtset1 | 12-bit resolution $CL = 50 \text{ pF}, RL = 10 \text{ k}\Omega$ |      |      | (60)  | μs   |

Note Errors of the SBIAS output voltage are not included.

Remark 1. Values in parentheses are target design values (i.e. not guaranteed) and therefore are not tested for shipment.

Remark 2. The 12-bit D/A converter characteristics are the values obtained with the amplifier unit connected.

#### (2) When reference voltage (+) = AVDD

#### (TA = -40 to +85°C, 2.7 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V, reference voltage (+) = AVDD)

| Parameter                        | Symbol  | Conditions                    | MIN. | TYP. | MAX.        | Unit |
|----------------------------------|---------|-------------------------------|------|------|-------------|------|
| Resolution                       | DARES1  |                               |      |      | (12)        | bit  |
| Output voltage range             | DAOUT   | 12-bit resolution             | 0.35 |      | AVDD - 0.47 | V    |
| Integral non-linearity error     | DAILE   | 12-bit resolution             |      |      | ±4.0        | LSB  |
| Differential non-linearity error | DADLE1  | 12-bit resolution             |      |      | ±1.0        | LSB  |
| Offset error                     | DAErr   | 12-bit resolution             |      |      | ±30         | mV   |
| Gain error                       | DAEG    | 12-bit resolution             |      |      | ±20         | mV   |
| Settling time                    | DAtset1 | 12-bit resolution             |      |      | (60)        | μs   |
|                                  |         | $CL = 50 pF, RL = 10 k\Omega$ |      |      |             |      |

Remark 1. Values in parentheses are target design values (i.e. not guaranteed) and therefore are not tested for shipment.

Remark 2. The 12-bit D/A converter characteristics are the values obtained with the amplifier unit connected.

# 2.7 Power supply voltage rising slope characteristics

#### $(TA = -40 \text{ to } +85^{\circ}C, Vss = 0 \text{ V})$

| Parameter                         | Conditions | MIN. | TYP. | MAX. | Unit |
|-----------------------------------|------------|------|------|------|------|
| Power supply voltage rising slope | SVDD       |      |      | 54   | V/ms |

Caution Make sure to keep the internal reset state by the LVD circuit or an external reset until VDD reaches the operating voltage range shown in 2.4 AC Characteristics.

### 2.8 LCD Characteristics

# 2.8.1 Resistance division method

### (1) Static display mode

 $(TA = -40 \text{ to } +85^{\circ}\text{C}, VL4 \text{ (MIN.)} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$ 

| Parameter         | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-------------------|--------|------------|------|------|------|------|
| LCD drive voltage | VL4    |            | 2.0  |      | VDD  | V    |

#### (2) 1/2 bias method, 1/4 bias method

 $(TA = -40 \text{ to } +85^{\circ}\text{C}, VL4 \text{ (MIN.)} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$ 

| Parameter         | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-------------------|--------|------------|------|------|------|------|
| LCD drive voltage | VL4    |            | 2.7  |      | VDD  | V    |

#### (3) 1/3 bias method

(TA = -40 to +85°C, VL4 (MIN.)  $\leq$  AVDD = VDD  $\leq$  5.5 V, AVSS = VSS = 0 V)

| Parameter         | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-------------------|--------|------------|------|------|------|------|
| LCD drive voltage | VL4    |            | 2.5  |      | VDD  | V    |

# 2.8.2 Internal voltage boosting method

### (1) 1/3 bias method

 $(TA = -40 \text{ to } +85^{\circ}C, 2.4 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$ 

| Parameter                           | Symbol  | Cond                      | ditions    | MIN.        | TYP.  | MAX.  | Unit |
|-------------------------------------|---------|---------------------------|------------|-------------|-------|-------|------|
| LCD output voltage variation range  | VL1     | C1 to C4 Note 1           | VLCD = 04H | 0.90        | 1.00  | 1.08  | V    |
|                                     |         | = 0.47 µF Note 2          | VLCD = 05H | 0.95        | 1.05  | 1.13  | V    |
|                                     |         |                           | VLCD = 06H | 1.00        | 1.10  | 1.18  | V    |
|                                     |         |                           | VLCD = 07H | 1.05        | 1.15  | 1.23  | V    |
|                                     |         |                           | VLCD = 08H | 1.10        | 1.20  | 1.28  | V    |
|                                     |         |                           | VLCD = 09H | 1.15        | 1.25  | 1.33  | V    |
|                                     |         |                           | VLCD = 0AH | 1.20        | 1.30  | 1.38  | V    |
|                                     |         |                           | VLCD = 0BH | 1.25        | 1.35  | 1.43  | V    |
|                                     |         |                           | VLCD = 0CH | 1.30        | 1.40  | 1.48  | V    |
|                                     |         |                           | VLCD = 0DH | 1.35        | 1.45  | 1.53  | V    |
|                                     |         |                           | VLCD = 0EH | 1.40        | 1.50  | 1.58  | V    |
|                                     |         |                           | VLCD = 0FH | 1.45        | 1.55  | 1.63  | V    |
|                                     |         |                           | VLCD = 10H | 1.50        | 1.60  | 1.68  | V    |
|                                     |         |                           | VLCD = 11H | 1.55        | 1.65  | 1.73  | V    |
|                                     |         |                           | VLCD = 12H | 1.60        | 1.70  | 1.78  | V    |
|                                     |         |                           | VLCD = 13H | 1.65        | 1.75  | 1.83  | V    |
| Doubler output voltage              | VL2     | C1 to C4 Note 1 =         | - 0.47 μF  | 2 VL1 - 0.1 | 2 VL1 | 2 VL1 | V    |
| Tripler output voltage              | VL4     | C1 to C4 Note 1 = 0.47 µF |            | 3 VL1- 0.15 | 3 VL1 | 3 VL1 | V    |
| Reference voltage setup time Note 2 | tvwait1 |                           |            | 5           |       |       | ms   |
| Voltage boost wait time Note 3      | tVWAIT2 | C1 to C4 Note 1 = 0.47 µF |            | 500         |       |       | ms   |

Note 1. This is a capacitor that is connected between voltage pins used to drive the LCD.

- C1: A capacitor connected between CAPH and CAPL
- C2: A capacitor connected between VL1 and GND
- C3: A capacitor connected between VL2 and GND
- C4: A capacitor connected between VL4 and GND
- $C1 = C2 = C3 = C4 = 0.47 \mu F \pm 30\%$
- Note 2. This is the time required to wait from when the reference voltage is specified by using the VLCD register (or when the internal voltage boosting method is selected (by setting the MDSET1 and MDSET0 bits of the LCDM0 register to 01B) if the default value reference voltage is used) until voltage boosting starts (VLCON = 1).
- Note 3. This is the wait time from when voltage boosting is started (VLCON = 1) until display is enabled (LCDON = 1).

#### (2) 1/4 bias method

#### (TA = -40 to +85°C, 2.4 V $\leq$ AVDD = VDD $\leq$ 5.5 V, AVSS = VSS = 0 V)

| Parameter                           | Symbol  | Conc                     | litions    | MIN.                     | TYP.  | MAX.  | Unit |
|-------------------------------------|---------|--------------------------|------------|--------------------------|-------|-------|------|
| LCD output voltage variation range  | VL1     | C1 to C5 Note 1          | VLCD = 04H | 0.90                     | 1.00  | 1.08  | V    |
|                                     |         | = $0.47 \mu F$ Note 2    | VLCD = 05H | 0.95                     | 1.05  | 1.13  | V    |
|                                     |         |                          | VLCD = 06H | 1.00                     | 1.10  | 1.18  | V    |
|                                     |         |                          | VLCD = 07H | 1.05                     | 1.15  | 1.23  | V    |
|                                     |         |                          | VLCD = 08H | 1.10                     | 1.20  | 1.28  | V    |
|                                     |         |                          | VLCD = 09H | 1.15                     | 1.25  | 1.33  | V    |
|                                     |         |                          | VLCD = 0AH | 1.20                     | 1.30  | 1.38  | V    |
| Doubler output voltage              | VL2     | C1 to C5 Note 1 =        | : 0.47 μF  | 2 V <sub>L1</sub> - 0.08 | 2 VL1 | 2 VL1 | V    |
| Tripler output voltage              | VL3     | C1 to C5 Note 1 =        | : 0.47 μF  | 3 V <sub>L1</sub> - 0.12 | 3 VL1 | 3 VL1 | V    |
| Quadruply output voltage            | VL4     | C1 to C5 Note 1 =        | : 0.47 μF  | 4 V <sub>L1</sub> - 0.16 | 4 VL1 | 4 VL1 | V    |
| Reference voltage setup time Note 2 | tVWAIT1 |                          |            | 5                        |       |       | ms   |
| Voltage boost wait time Note 3      | tVWAIT2 | C1 to C5 Note 1 = 0.47µF |            | 500                      |       |       | ms   |

- Note 1. This is a capacitor that is connected between voltage pins used to drive the LCD.
  - C1: A capacitor connected between CAPH and CAPL
  - C2: A capacitor connected between VL1 and GND
  - C3: A capacitor connected between VL2 and GND
  - C4: A capacitor connected between VL3 and GND
  - C5: A capacitor connected between VL4 and GND
  - $C1 = C2 = C3 = C4 = C5 = 0.47 \mu F \pm 30\%$
- Note 2. This is the time required to wait from when the reference voltage is specified by using the VLCD register (or when the internal voltage boosting method is selected (by setting the MDSET1 and MDSET0 bits of the LCDM0 register to 01B) if the default value reference voltage is used) until voltage boosting starts (VLCON = 1).
- Note 3. This is the wait time from when voltage boosting is started (VLCON = 1) until display is enabled (LCDON = 1).

# 2.8.3 Capacitor split method

#### (1) 1/3 bias method

(TA = -40 to +85°C, 2.4 V  $\leq$  AVDD = VDD  $\leq$  5.5 V, AVSS = VSS = 0 V)

| Parameter                        | Symbol | Conditions                | MIN.                      | TYP.    | MAX.          | Unit |
|----------------------------------|--------|---------------------------|---------------------------|---------|---------------|------|
| VL4 voltage                      | VL4    | C1 to C4 = 0.47 µF Note 2 |                           | VDD     |               | V    |
| VL2 voltage                      | VL2    | C1 to C4 = 0.47 µF Note 2 | 2/3 V <sub>L4</sub> - 0.1 | 2/3 VL4 | 2/3 VL4 + 0.1 | V    |
| VL1 voltage                      | VL1    | C1 to C4 = 0.47 µF Note 2 | 1/3 VL4 - 0.1             | 1/3 VL4 | 1/3 VL4 + 0.1 | V    |
| Capacitor split wait time Note 1 | tvwait |                           | 100                       |         |               | ms   |

Note 1. This is the wait time from when voltage bucking is started (VLCON = 1) until display is enabled (LCDON = 1).

**Note 2.** This is a capacitor that is connected between voltage pins used to drive the LCD.

C1: A capacitor connected between CAPH and CAPL

C2: A capacitor connected between VL1 and GND

C3: A capacitor connected between VL2 and GND

C4: A capacitor connected between VL4 and GND

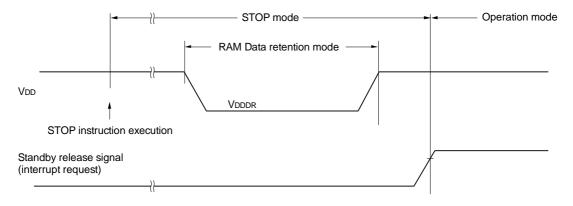
 $C1 = C2 = C3 = C4 = 0.47 \mu F \pm 30\%$ 

#### 2.9 RAM data retention characteristics

#### $(TA = -40 \text{ to } +85^{\circ}C, Vss = 0 \text{ V})$

| Parameter                     | Symbol | Conditions | MIN.      | TYP. | MAX. | Unit |
|-------------------------------|--------|------------|-----------|------|------|------|
| Data retention supply voltage | VDDDR  |            | 1.46 Note |      | 5.5  | V    |

**Note** The value depends on the POR detection voltage. When the voltage drops, the RAM data is retained before a POR reset is effected, but RAM data is not retained when a POR reset is effected.



# 2.10 Flash Memory Programming Characteristics

 $(TA = -40 \text{ to } +85^{\circ}C, 2.4 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$ 

| Parameter                                      | Symbol | Conditions            |           | MIN.    | TYP.      | MAX. | Unit  |
|--|--------|-----------------------|-----------|---------|-----------|------|-------|
| System clock frequency                         | fCLK   | 2.4 V ≤ VDD ≤ 5.5 V   |           | 1       |           | 24   | MHz   |
| Number of code flash rewrites<br>Notes 1, 2, 3 | Cerwr  | Retained for 20 years | TA = 85°C | 1,000   |           |      | Times |
| Number of data flash rewrites                  |        | Retained for 1 year   | TA = 25°C |         | 1,000,000 |      |       |
| Notes 1, 2, 3                                  |        | Retained for 5 years  | TA = 85°C | 100,000 |           |      |       |
|  |        | Retained for 20 years | TA = 85°C | 10,000  |           |      |       |

- Note 1. 1 erase + 1 write after the erase is regarded as 1 rewrite. The retaining years are until next rewrite after the rewrite.
- Note 2. When using flash memory programmer and Renesas Electronics self programming library
- **Note 3.** These are the characteristics of the flash memory and the results obtained from reliability testing by Renesas Electronics Corporation.

# 2.11 Dedicated Flash Memory Programmer Communication (UART)

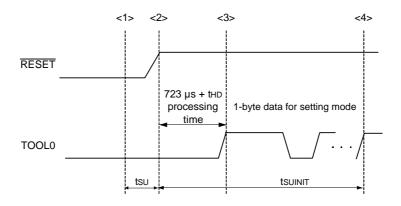
(TA = -40 to +85°C, 2.4 V  $\leq$  AVDD = VDD  $\leq$  5.5 V, AVSS = VSS = 0 V)

| Parameter     | Symbol | Conditions                | MIN.    | TYP. | MAX.      | Unit |
|---------------|--------|---------------------------|---------|------|-----------|------|
| Transfer rate |        | During serial programming | 115,200 |      | 1,000,000 | bps  |

# 2.12 Timing of Entry to Flash Memory Programming Modes

 $(TA = -40 \text{ to } +85^{\circ}C, 2.4 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = 0 \text{ V})$ 

| Parameter   | Symbol  | Conditions   | MIN. | TYP. | MAX. | Unit |
|---|---------|--|------|------|------|------|
| How long from when an external reset ends until the initial communication settings are specified  | tsuinit | POR and LVD reset must end before the external reset ends. |      |      | 100  | ms   |
| How long from when the TOOL0 pin is placed at the low level until an external reset ends  | tsu     | POR and LVD reset must end before the external reset ends. | 10   |      |      | μs   |
| Time to hold the TOOL0 pin at the low level after an external reset is released (excluding the processing time of the firmware to control the flash memory) | tHD     | POR and LVD reset must end before the external reset ends. | 1    |      |      | ms   |



- <1> The low level is input to the TOOL0 pin.
- <2> The external reset ends (POR and LVD reset must end before the external reset ends.).
- <3> The TOOL0 pin is set to the high level.
- <4> Setting of the flash memory programming mode by UART reception and complete the baud rate setting.

**Remark** tsuinit: The segment shows that it is necessary to finish specifying the initial communication settings within 100 ms from when the resets end.

tsu: How long from when the TOOL0 pin is placed at the low level until an external reset ends

thd: Time to hold the TOOL0 pin at the low level after an external reset is released (excluding the processing time of the firmware to control the flash memory)

# 3. ELECTRICAL SPECIFICATIONS (R5F11R) (D: TA = -40 to +85°C)

This chapter describes the electrical specifications for the products "D: Industrial applications (TA = -40 to +85°C)".

- Caution 1. The RL78 microcontrollers have an on-chip debug function, which is provided for development and evaluation. Do not use the on-chip debug function in products designated for mass production, because the guaranteed number of rewritable times of the flash memory may be exceeded when this function is used, and product reliability therefore cannot be guaranteed. Renesas Electronics is not liable for problems occurring when the on-chip debug function is used.
- Caution 2. The pins mounted depend on the product. Refer to 2.1 Port Function to 2.2 Functions other than port pins in the User's Manual: Hardware.

# 3.1 Absolute Maximum Ratings

#### **Absolute Maximum Ratings**

(1/3)

| Parameter              | Symbol | Conditions  | Ratings   | Unit |
|------------------------|--------|---|---|------|
| Supply voltage         | VDD    |   | -0.5 to +6.5  | V    |
|                        | AVDD   | AVDD = VDD  | -0.5 to +6.5  | V    |
|                        | AVss   | AVss = Vss  | -0.5 to +0.3  | V    |
| REGC pin input voltage | VIREGC | REGC  | -0.3 to +2.8<br>and -0.3 to V <sub>DD</sub> + 0.3 <sup>Note 1</sup> | V    |
| Input voltage          | VI1    | P01 to P07, P10 to P17, P30 to P32, P35 to P37, P40, P43, P44, P50 to P53, P70 to P77, P80 to P86, P121 to P124, P125 to P127, P137, EXCLK, EXCLKS, RESET | -0.3 to VDD +0.3 Note 2   | V    |
|                        | VI2    | P60, P61 (N-ch open-drain)  | -0.3 to +6.5  | V    |
|                        | Vıз    | P20 to P27, P150, P151  | -0.3 to AVDD + 0.3 Note 2   | V    |
| Output voltage         | VO1    | P01 to P07, P10 to P17, P30 to P32,<br>P35 to P37, P40, P43, P44, P50 to P53,<br>P60, P61, P70 to P77, P80 to P86,<br>P125 to P127                        | -0.3 to VDD + 0.3 Note 2  | V    |
|                        | VO2    | P20 to P27, P150, P151  | -0.3 to AVDD + 0.3 Note 2   | V    |
| Analog input voltage   | VAI1   | ANI8 to ANI10   | -0.3 to VDD + 0.3 Note 2  | V    |

- Note 1. Connect the REGC pin to Vss via a capacitor (0.47 to 1  $\mu$ F). This value regulates the absolute maximum rating of the REGC pin. Do not use this pin with voltage applied to it.
- Note 2. Must be 6.5 V or lower.

ratings are not exceeded.

Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter.

That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum

Remark 1. Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

**Remark 2.** The reference voltage is Vss (for the VDD systems) = AVss (for the AVDD systems).

#### **Absolute Maximum Ratings**

(2/3)

| Parameter   | Symbol         | Cond                            | ditions                             | Ratings                   | Unit |
|-------------|----------------|---------------------------------|-------------------------------------|---------------------------|------|
| LCD voltage | VLI1           | VL1 input voltage Note 1        |                                     | -0.3 to +2.8              | V    |
|             | VLI2           | VL2 input voltage Note 1        |                                     | -0.3 to +6.5              | V    |
|             | VLI3           | VL3 input voltage Note 1        | VL3 input voltage Note 1            |                           | V    |
|             | VLI4           | VL4 input voltage Note 1        |                                     | -0.3 to +6.5              | V    |
|             | VLI5           | CAPL, CAPH input vol            | tage Note 1                         | -0.3 to +6.5              | V    |
|             | VLO1           | V <sub>L</sub> 1 output voltage |                                     | -0.3 to +2.8              | ٧    |
| _           | VLO2           | VL2 output voltage              |                                     | -0.3 to +6.5              | V    |
|             | VLO3           | VL3 output voltage              |                                     | -0.3 to +6.5              | V    |
|             | VLO4           | VL4 output voltage              |                                     | -0.3 to +6.5              | V    |
|             | VLO5           | CAPL, CAPH output vo            | oltage                              | -0.3 to +6.5              | V    |
|             | VLO6           | COM0 to COM7<br>SEG0 to SEG35   | External resistance division method | -0.3 to VDD + 0.3 Note 2  | V    |
|             | output voltage | Capacitor split method          | -0.3 to VDD + 0.3 Note 2            | V                         |      |
|             |                |                                 | Internal voltage boosting method    | -0.3 to VLI4 + 0.3 Note 2 | V    |

- Note 1. This value only indicates the absolute maximum ratings when applying voltage to the VL1, VL2, VL3, and VL4 pins; it does not mean that applying voltage to these pins is recommended. When using the internal voltage boosting method or capacitance split method, connect these pins to Vss via a capacitor (0.47 μF ± 30%) and connect a capacitor (0.47 μF ± 30%) between the CAPL and CAPH pins.
- Note 2. Must be 6.5 V or lower.
- Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter.

  That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

#### **Absolute Maximum Ratings**

(3/3)

| Parameter            | Symbol |                                  | Conditions                           | Ratings     | Unit |
|----------------------|--------|----------------------------------|--------------------------------------|-------------|------|
| Output current, high | Іон1   | Per pin                          |                                      | -40         | mA   |
|                      |        | Total of all pins                | P40, P43, P44, P80 to P83            | -70         | mA   |
|                      |        | -170 mA                          | P01 to P07, P10 to P17, P30 to P32,  | -100        | mA   |
|                      |        |                                  | P35 to P37, P50 to P53, P70 to P77,  |             |      |
|                      |        |                                  | P84 to P86, P125 to P127             |             |      |
|                      | IOH2   | Per pin                          |                                      | -40         | mA   |
|                      |        | Total of all pins                | P21 to P27                           | -70         | mA   |
|                      |        | -140 mA                          | P20, P150, P151                      | -70         | mA   |
| Output current, low  | IOL1   | Per pin                          |                                      | 40          | mA   |
|                      |        | Total of all pins<br>170 mA      | P40, P43, P44, P80 to P83            | 70          | mA   |
|                      |        |                                  | P01 to P07, P10 to P17, P30 to P32,  | 100         | mA   |
|                      |        |                                  | P35 to P37, P50 to P53, P60, P61,    |             |      |
|                      |        |                                  | P70 to P77, P84 to P86, P125 to P127 |             |      |
|                      | lOL2   | Per pin                          |                                      | 40          | mA   |
|                      |        | Total of all pins                | P21 to P27                           | 70          | mA   |
|                      |        | 140 mA                           | P20, P150, P151                      | 70          | mA   |
| Operating ambient    | TA     | In normal operation              | on mode                              | -40 to +85  | °C   |
| temperature          |        | In flash memory programming mode |                                      | 1           |      |
| Storage temperature  | Tstg   |                                  |                                      | -65 to +150 | °C   |

Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter.

That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

#### 3.2 Oscillator Characteristics

#### 3.2.1 X1 and XT1 characteristics

 $(TA = -40 \text{ to } +85^{\circ}\text{C}, 1.8 \text{ V} \le \text{AVDD} = \text{VDD} \le 5.5 \text{ V}, \text{AVSS} = \text{VSS} = 0 \text{ V})$ 

| Parameter                                 | Resonator          | Conditions          | MIN. | TYP.   | MAX. | Unit |
|---|--------------------|---------------------|------|--------|------|------|
| X1 clock oscillation frequency (fx) Note  | Ceramic resonator/ | 2.7 V ≤ VDD ≤ 5.5 V | 1.0  |        | 20.0 | MHz  |
|   |                    | 2.4 V ≤ VDD < 2.7 V | 1.0  |        | 16.0 |      |
|   |                    | 1.8 V ≤ VDD < 2.4 V | 1.0  |        | 8.0  |      |
| X1 clock oscillation frequency (fxT) Note | Crystal resonator  |                     | 32   | 32.768 | 35   | kHz  |
|   |                    |                     | 31   | 38.4   | 39   |      |

Note Indicates only permissible oscillator frequency ranges. Refer to AC Characteristics for instruction execution time.

Request evaluation by the manufacturer of the oscillator circuit mounted on a board to check the oscillator characteristics.

Caution Since the CPU is started by the high-speed on-chip oscillator clock after a reset release, check the X1 clock oscillation stabilization time using the oscillation stabilization time counter status register (OSTC) by the user. Determine the oscillation stabilization time of the OSTC register and the oscillation stabilization time select register (OSTS) after sufficiently evaluating the oscillation stabilization time with the resonator to be used.

Remark When using the X1 and XT1 oscillator, refer to 5.4 System Clock Oscillator in the User's Manual: Hardware.

# 3.2.2 On-chip oscillator characteristics

 $(TA = -40 \text{ to } +85^{\circ}C, 1.8 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$ 

| Parameter                                     | Symbol | Conditions          |                     | MIN. | TYP. | MAX. | Unit |
|---|--------|---------------------|---------------------|------|------|------|------|
| High-speed on-chip oscillator clock frequency | fiH    | 2.7 V ≤ VDD ≤ 5     | 5.5 V               | 1    |      | 24   | MHz  |
| Notes 1, 2                                    |        | 2.4 V ≤ VDD < 2.7 V |                     | 1    |      | 16   | MHz  |
|   |        | 1.8 V ≤ VDD < 2.4 V |                     | 1    |      | 8    | MHz  |
| High-speed on-chip oscillator clock frequency |        | -20 to +85°C        | 1.8 V ≤ VDD ≤ 5.5 V | -1.0 |      | +1.0 | %    |
| accuracy                                      |        | -40 to -20°C        | 1.8 V ≤ VDD ≤ 5.5 V | -1.5 |      | +1.5 | %    |
| Low-speed on-chip oscillator clock frequency  | fIL    |                     |                     |      | 15   |      | kHz  |
| Low-speed on-chip oscillator clock frequency  |        |                     |                     | -15  |      | +15  | %    |
| accuracy                                      |        |                     |                     |      |      |      |      |

**Note 1.** High-speed on-chip oscillator frequency is selected with bits 0 to 4 of the option byte (000C2H/010C2H) and bits 0 to 2 of the HOCODIV register.

Note 2. This only indicates the oscillator characteristics. Refer to AC Characteristics for instruction execution time.



#### 3.3 DC Characteristics

#### 3.3.1 Pin characteristics

#### $(TA = -40 \text{ to } +85^{\circ}C, 1.8 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$

(1/5)

| Item                        | Symbol                                | Conditions   | Conditions           |  | TYP. | MAX.            | Unit |
|-----------------------------|---------------------------------------|--|----------------------|--|------|-----------------|------|
| Output current, high Note 1 | P30 to P32, P35 to P44, P50 to P53, P | Per pin for P01 to P07, P10 to P17,<br>P30 to P32, P35 to P37, P40, P43,<br>P44, P50 to P53, P70 to P77,<br>P80 to P86, P125 to P127 |                      |  |      | -10.0<br>Note 2 | mA   |
|                             |                                       | Total of P40, P43, P44,  | 4.0 V ≤ VDD ≤ 5.5 V  |  |      | -55             | mA   |
|                             |                                       | P80 to P83   | 2.7 V ≤ VDD < 4.0 V  |  |      | -10             | mA   |
|                             |                                       | (When duty ≤ 70% Note 3)   | 1.8 V ≤ VDD < 2.7 V  |  |      | -5              | mA   |
|                             |                                       | Total of P01 to P07, P10 to P17,   | 4.0 V ≤ VDD ≤ 5.5 V  |  |      | -69             | mA   |
|                             |                                       | P30 to P32, P35 to P37,  | 2.7 V ≤ VDD < 4.0 V  |  |      | -23             | mA   |
|                             |                                       | P50 to P53, P70 to P77,<br>P84 to P86, P125 to P127<br>(When duty ≤ 70% Note 3)  | 1.8 V ≤ VDD < 2.7 V  |  |      | -12             | mA   |
|                             |                                       | Total of all pins 1. (When duty ≤ 70% Note 3)  | 1.8 V ≤ VDD ≤ 5.5 V  |  |      | -124            | mA   |
|                             | ЮН2                                   | Per pin for P20 to P27, P150, P151   | 1.8 V ≤ AVDD ≤ 5.5 V |  |      | -10.0<br>Note 2 | mA   |
|                             |                                       | Total of P21 to P27  | 4.0 V ≤ AVDD ≤ 5.5 V |  |      | -50             | mA   |
|                             |                                       | (When duty ≤ 70% Note 3)   | 2.7 V ≤ AVDD < 4.0 V |  |      | -10             | mA   |
|                             |                                       |  | 1.8 V ≤ AVDD < 2.7 V |  |      | -5              | mA   |
|                             |                                       | Total of P20, P150, P151   | 4.0 V ≤ AVDD ≤ 5.5 V |  |      | -21             | mA   |
|                             |                                       |  | 2.7 V ≤ AVDD < 4.0 V |  |      | -5              | mA   |
|                             |                                       |  | 1.8 V ≤ AVDD < 2.7 V |  |      | -3              | mA   |
|                             |                                       | Total of all pins<br>(When duty ≤ 70% Note 3)  | 1.8 V ≤ AVDD ≤ 5.5 V |  |      | -71             | mA   |

- Note 1. Value of current at which the device operation is guaranteed even if the current flows from the VDD pin (IOH1) and AVDD pin (IOH2) to an output pin.
- Note 2. Do not exceed the total current value.
- **Note 3.** Specification under conditions where the duty factor  $\leq$  70%.

The output current value that has changed to the duty factor > 70% the duty ratio can be calculated with the following expression (when changing the duty factor from 70% to n%).

- Total output current of pins = (IOH  $\times$  0.7)/(n  $\times$  0.01)
  - <Example> Where n = 80% and IOH = -10.0 mA

Total output current of pins =  $(-10.0 \times 0.7)/(80 \times 0.01) \approx -8.7$  mA

However, the current that is allowed to flow into one pin does not vary depending on the duty factor. A current higher than the absolute maximum rating must not flow into one pin.

Caution P02 to P04, P06, P07, P10, P12, P35 to P37, P40, P43, P44, P50 to P52, and P80 to P82 do not output high level in N-ch open-drain mode.

#### $(TA = -40 \text{ to } +85^{\circ}C, 1.8 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$

(2/5)

| Item                       | Symbol | Conditions   |   | MIN. | TYP. | MAX.           | Unit |
|----------------------------|--------|--|---|------|------|----------------|------|
| Output current, low Note 1 | IOL1   | Per pin for P01 to P07, P10 to P17,<br>P30 to P32, P35 to P37, P40, P43,<br>P44, P50 to P53, P70 to P77,<br>P80 to P86, P121 to P127 |   |      |      | 20.0<br>Note 2 | mA   |
|                            |        | Per pin for P60, P61   |   |      |      | 15.0<br>Note 2 | mA   |
|                            |        | Total of P40, P43, P44, P80 to P83   | 4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V                     |      |      | 70             | mA   |
|                            |        | (When duty ≤ 70% Note 3)   | 2.7 V ≤ VDD < 4.0 V                                 |      |      | 15             | mA   |
|                            |        |  | 1.8 V ≤ VDD < 2.7 V                                 |      |      | 9              | mA   |
|                            |        | Total of P01 to P07, P10 to P17,   | 4.0 V ≤ VDD ≤ 5.5 V                                 |      |      | 90             | mA   |
|                            |        | P30 to P32, P35 to P37,  | 2.7 V ≤ VDD < 4.0 V                                 |      |      | 35             | mA   |
|                            |        | P50 to P53, P60, P61, P70 to P77,<br>P84 to P86, P125 to P127<br>(When duty ≤ 70% <sup>Note 3</sup> )                                | 1.8 V ≤ VDD < 2.7 V                                 |      |      | 20             | mA   |
|                            |        | Total of all pins<br>(When duty ≤ 70% Note 3)  | 1.8 V ≤ VDD ≤ 5.5 V                                 |      |      | 160            | mA   |
|                            | IOL2   | Per pin for P20 to P27, P150,<br>P151  | 1.8 V ≤ AVDD ≤ 5.5 V                                |      |      | 20             | mA   |
|                            |        | Total of P21 to P27  | $4.0 \text{ V} \leq \text{AVDD} \leq 5.5 \text{ V}$ |      |      | 60             | mA   |
|                            |        | (When duty ≤ 70% Note 3)   | $2.7 \text{ V} \leq \text{AVDD} < 4.0 \text{ V}$    |      |      | 10             | mA   |
|                            |        |  | $1.8 \text{ V} \leq \text{AVDD} < 2.7 \text{ V}$    |      |      | 5              | mA   |
|                            |        | Total of P20, P150, P151   | 4.0 V ≤ AVDD ≤ 5.5 V                                |      |      | 25             | mA   |
|                            |        | (When duty ≤ 70% Note 3)   | $2.7 \text{ V} \leq \text{AVDD} < 4.0 \text{ V}$    |      |      | 8              | mA   |
|                            |        | 1  | $1.8 \text{ V} \leq \text{AVDD} < 2.7 \text{ V}$    |      |      | 5              | mA   |
|                            |        | Total of all pins<br>(When duty ≤ 70% Note 3)  | 1.8 V ≤ AVDD ≤ 5.5 V                                |      |      | 85             | mA   |

- Note 1. Value of current at which the device operation is guaranteed even if the current flows from the Vss pin (IoL1) and AVss pin (IoL2) to an output pin.
- Note 2. Do not exceed the total current value.
- **Note 3.** Specification under conditions where the duty factor  $\leq 70\%$ .

The output current value that has changed to the duty factor > 70% the duty ratio can be calculated with the following expression (when changing the duty factor from 70% to n%).

- Total output current of pins = (IoL  $\times$  0.7)/(n  $\times$  0.01)
- <Example> Where n = 80% and IOL = 10.0 mA

Total output current of pins =  $(10.0 \times 0.7)/(80 \times 0.01) \approx 8.7 \text{ mA}$ 

However, the current that is allowed to flow into one pin does not vary depending on the duty factor. A current higher than the absolute maximum rating must not flow into one pin.

# (TA = -40 to +85°C, 1.8 V $\leq$ AVDD = VDD $\leq$ 5.5 V, AVSS = VSS = 0 V)

(3/5)

| Item                | Symbol | Conditions  | 3  | MIN.     | TYP. | MAX.     | Unit |
|---------------------|--------|---|--|----------|------|----------|------|
| Input voltage, high | VIH1   | P01 to P07, P10 to P17, P30 to P32, P35 to P37, P40, P43, P44, P50 to P53, P70 to P77, P80 to P86, P125 to P127 | Normal input buffer                      | 0.8 VDD  |      | VDD      | V    |
|                     | VIH2   | For TTL mode supported ports  | TTL input buffer,<br>4.0 V ≤ VDD ≤ 5.5 V | 2.2      |      | VDD      | V    |
|                     |        |   | TTL input buffer,<br>3.3 V ≤ VDD < 4.0 V | 2.0      |      | VDD      | V    |
|                     |        |   | TTL input buffer,<br>1.8 V ≤ VDD < 3.3 V | 1.5      |      | VDD      | V    |
|                     | VIH3   | P20 to P27, P150, P151  |  | 0.8 AVDD |      | AVDD     | V    |
|                     | VIH4   | P60, P61  |  | 0.7 Vdd  |      | 6.0      | V    |
|                     | VIH5   | P121 to P124, P137, EXCLK, EX   | 0.8 VDD                                  |          | VDD  | V        |      |
| Input voltage, low  | VIL1   | P01 to P07, P10 to P17, P30 to P32, P35 to P37, P40, P43, P44, P50 to P53, P70 to P77, P80 to P86, P125 to P127 | Normal input buffer                      | 0        |      | 0.2 VDD  | V    |
|                     | VIL2   | For TTL mode supported ports  | TTL input buffer,<br>4.0 V ≤ VDD ≤ 5.5 V | 0        |      | 0.8      | V    |
|                     |        |   | TTL input buffer,<br>3.3 V ≤ VDD < 4.0 V | 0        |      | 0.5      | V    |
|                     |        |   | TTL input buffer,<br>1.8 V ≤ VDD < 3.3 V | 0        |      | 0.32     | V    |
|                     | VIL3   | P20 to P27, P150, P151  |  | 0        |      | 0.2 AVDD | V    |
|                     | VIL4   | P60, P61  |  | 0        |      | 0.3 VDD  | V    |
|                     | VIL5   | P121 to P124, P137, EXCLK, EX   | CLKS, RESET                              | 0        |      | 0.2 VDD  | V    |

Caution The maximum VIH value on P02 to P04, P06, P07, P10, P12, P35 to P37, P40, P43, P44, P50 to P52, and P80 to P82 is VDD, even in the N-ch open-drain mode.

(TA = -40 to +85°C, 1.8 V  $\leq$  AVDD = VDD  $\leq$  5.5 V, AVSS = VSS = 0 V)

(4/5)

| Item                 | Symbol |   | Conditions                           | MIN.       | TYP. | MAX. | Unit |
|----------------------|--------|---|--------------------------------------|------------|------|------|------|
| Output voltage, high | Voн1   | P01 to P07, P10   | 4.0 V ≤ VDD ≤ 5.5 V, IOH = -10.0 mA  | VDD - 1.5  |      |      | V    |
|                      |        | to P17, P30 to  | 4.0 V ≤ VDD ≤ 5.5 V, IOH = -3.0 mA   | VDD - 0.7  |      |      | V    |
|                      |        | P32, P35 to<br>P37, P40, P43,   | 2.7 V ≤ VDD ≤ 5.5 V, IOH = -2.0 mA   | VDD - 0.6  |      |      | V    |
|                      |        | P44, P50 to<br>P53, P70 to<br>P77, P80 to<br>P86, P125 to<br>P127   | 1.8 V ≤ VDD ≤ 5.5 V, IOH = -1.5 mA   | VDD - 0.5  |      |      | V    |
|                      | VOH2   | P20 to P27,   | 4.0 V ≤ AVDD ≤ 5.5 V, IOH = -10.0 mA | AVDD - 1.5 |      |      | V    |
|                      |        | P150, P151  | 4.0 V ≤ AVDD ≤ 5.5 V, IOH = -3.0 mA  | AVDD - 0.7 |      |      | V    |
|                      |        |   | 2.7 V ≤ AVDD ≤ 5.5 V, IOH = -2.0 mA  | AVDD - 0.6 |      |      | V    |
|                      |        |   | 1.8 V ≤ AVDD ≤ 5.5 V, IOH = -1.5 mA  | AVDD - 0.5 |      |      | V    |
| Output voltage, low  | VOL1   | P01 to P07, P10<br>to P17, P30 to<br>P32, P35 to<br>P37, P40, P43,<br>P44, P50 to<br>P53, P70 to<br>P77, P80 to<br>P86, P125 to<br>P127 | 4.0 V ≤ VDD ≤ 5.5 V, IOL = 20.0 mA   |            |      | 1.3  | V    |
|                      |        |   | 4.0 V ≤ VDD ≤ 5.5 V, IOL = 8.5 mA    |            |      | 0.7  | V    |
|                      |        |   | 2.7 V ≤ VDD ≤ 5.5 V, IOL = 3.0 mA    |            |      | 0.6  | V    |
|                      |        |   | 2.7 V ≤ VDD ≤ 5.5 V, IOL = 1.5 mA    |            |      | 0.4  | V    |
|                      |        |   | 1.8 V ≤ VDD ≤ 5.5 V, IOL = 0.6 mA    |            |      | 0.4  | V    |
|                      | VOL2   | P20 to P27,   | 4.0 V ≤ AVDD ≤ 5.5 V, IOL = 20.0 mA  |            |      | 1.3  | V    |
|                      |        | P150, P151  | 4.0 V ≤ AVDD ≤ 5.5 V, IOL = 8.5 mA   |            |      | 0.7  | V    |
|                      |        |   | 2.7 V ≤ AVDD ≤ 5.5 V, IOL = 3.0 mA   |            |      | 0.6  | V    |
|                      |        |   | 2.7 V ≤ AVDD ≤ 5.5 V, IOL = 1.5 mA   |            |      | 0.4  | V    |
|                      |        |   | 1.8 V ≤ AVDD ≤ 5.5 V, IOL = 0.6 mA   |            |      | 0.4  | V    |
|                      | VOL3   | P60, P61  | 4.0 V ≤ VDD ≤ 5.5 V, IOL = 15.0 mA   |            |      | 2.0  | V    |
|                      |        |   | 4.0 V ≤ VDD ≤ 5.5 V, IOL = 5.0 mA    |            |      | 0.4  | V    |
|                      |        |   | 2.7 V ≤ VDD ≤ 5.5 V, IOL = 3.0 mA    |            |      | 0.4  | V    |
|                      |        |   | 1.8 V ≤ VDD ≤ 5.5 V, IOL = 2.0 mA    |            |      | 0.4  | V    |

Caution The maximum VIH value on P02 to P04, P06, P07, P10, P12, P35 to P37, P40, P43, P44, P50 to P52, and P80 to P82 is VDD, even in the N-ch open-drain mode.

# (TA = -40 to +85°C, 1.8 V $\leq$ AVDD = VDD $\leq$ 5.5 V, AVSS = VSS = 0 V)

(5/5)

| Item                           | Symbol | Condi  | itions                        |   | MIN. | TYP. | MAX. | Unit |
|--------------------------------|--------|--|-------------------------------|---|------|------|------|------|
| Input leakage<br>current, high | ILIH1  | P01 to P07, P10 to P17, P30 to P32, P35 to P37, P40, P43, P44, P50 to P53, P60, P61, P70 to P77, P80 to P86, P125 to P127, P137, RESET | VI = VDD                      |   |      |      | 1    | μА   |
|                                | ILIH2  | P20 to P27, P150, P151   | VI = AVDD                     |   |      |      | 1    | μΑ   |
|                                | ILIH3  | P121 to P124 (X1, X2, EXCLK, XT1, XT2, EXCLKS)   | VI = VDD                      | In input port mode or when using external clock input |      |      | 1    | μΑ   |
|                                |        |  | When a resonator is connected |   |      |      | 10   | μΑ   |
| Input leakage<br>current, low  | ILIL1  | P01 to P07, P10 to P17, P30 to P32, P35 to P37, P40, P43, P44, P50 to P53, P60, P61, P70 to P77, P80 to P86, P125 to P127, P137, RESET | VI = VSS                      |   |      |      | -1   | μA   |
|                                | ILIL2  | P20 to P27, P150, P151   | VI = AVSS                     |   |      | -1   | μΑ   |      |
|                                | ILIL3  | P121 to P124 (X1, X2, EXCLK, XT1, XT2, EXCLKS)   | VI = VSS                      | In input port mode or when using external clock input |      |      | -1   | μΑ   |
|                                |        |  |                               | When a resonator is connected                         |      |      | -10  | μA   |
| On-chip pull-up                | Ru1    | P01 to P07, P10 to P16, P30 to   | VI = VSS,                     | 2.4 V ≤ VDD ≤ 5.5 V                                   | 10   | 20   | 100  | kΩ   |
| resistance                     |        | P32, P35 to P37, P50 to P53, P70 to P77, P125 to P127  |                               | 1.8 V ≤ VDD < 2.4 V                                   | 10   | 30   | 100  | kΩ   |
|                                | RU2    | P17, P40, P43, P44, P80 to P86,  | VI = VSS,                     | in input port mode                                    | 10   | 20   | 100  | kΩ   |
|                                | Ruз    | P20 to P27, P150 and P151  | VI = AVSS                     | , in input port mode                                  | 10   | 20   | 100  | kΩ   |

# 3.3.2 Supply current characteristics

# (TA = -40 to +85°C, 1.8 V $\leq$ AVDD = VDD $\leq$ 5.5 V, AVSS = VSS = 0 V)

(1/2)

| Parameter | Symbol |                   |                        | Conditions                        |                      |                      | MIN. | TYP. | MAX. | Unit |
|-----------|--------|-------------------|------------------------|-----------------------------------|----------------------|----------------------|------|------|------|------|
| Supply    | IDD1   | Operating         | \ 0                    | fIH = 24 MHz Note 3               | Basic                | VDD = 5.0 V          |      | 1.7  |      | mA   |
| current   |        | mode              | main) Mode Note 5      |                                   | operation            | VDD = 3.0 V          |      | 1.7  |      |      |
| Note 1    |        |                   |                        |                                   | Normal               | VDD = 5.0 V          |      | 3.7  | 6.4  |      |
|           |        |                   |                        |                                   | operation            | VDD = 3.0 V          |      | 3.7  | 6.4  |      |
|           |        |                   |                        | fIH = 16 MHz Note 3               | Normal               | VDD = 5.0 V          |      | 2.8  | 5.0  |      |
|           |        |                   |                        |                                   | operation            | VDD = 3.0 V          |      | 2.8  | 5.0  |      |
|           |        |                   | LS (low-speed          | fIH = 8 MHz Note 3                | Normal               | VDD = 3.0 V          |      | 1.2  | 2.1  | mA   |
|           |        |                   | main) Mode Note 5      |                                   | operation            | VDD = 2.0 V          |      | 1.2  | 2.1  | ]    |
|           |        |                   | HS (high-speed         | fmx = 20 MHz Note 2,              | Normal               | Square wave input    |      | 3.1  | 5.4  | mA   |
|           |        |                   | main) Mode Note 5      | VDD = 5.0 V                       | operation            | Resonator connection |      | 3.3  | 5.5  |      |
|           |        |                   |                        | fmx = 20 MHz Note 2,              | Normal               | Square wave input    |      | 3.0  | 5.4  |      |
|           |        |                   |                        | VDD = 3.0 V                       | operation            | Resonator connection |      | 3.3  | 5.5  |      |
|           |        |                   |                        | fmx = 16 MHz Note 2,              | Normal               | Square wave input    |      | 2.6  | 4.7  |      |
|           |        |                   |                        | VDD = 5.0 V                       | operation            | Resonator connection |      | 2.8  | 4.8  |      |
|           |        |                   |                        | fmx = 16 MHz Note 2,              | Normal               | Square wave input    |      | 2.6  | 4.7  |      |
|           |        |                   |                        | VDD = 3.0 V                       | operation            | Resonator connection |      | 2.8  | 4.8  | 1    |
|           |        |                   |                        | fmx = 10 MHz Note 2,              | Normal               | Square wave input    |      | 1.9  | 3.1  | 1    |
|           |        |                   |                        | VDD = 5.0 V                       | operation            | Resonator connection |      | 1.9  | 3.1  | 1    |
|           |        |                   |                        | fMX = 10 MHz Note 2,              | Normal               | Square wave input    |      | 1.9  | 3.1  | 1    |
|           |        |                   |                        | VDD = 3.0 V                       | operation            | Resonator connection |      | 1.9  | 3.1  | 1    |
|           |        |                   | LS (low-speed          | fMX = 8 MHz Note 2,               | Normal               | Square wave input    |      | 1.1  | 2.1  | m/   |
|           | main)  | main) Mode Note 5 | VDD = 3.0 V            | operation                         | Resonator connection |                      | 1.1  | 2.1  | 1    |      |
|           |        |                   |                        | fmx = 8 MH Note 2,                | Normal               | Square wave input    |      | 1.1  | 2.1  | 1    |
|           |        |                   |                        | VDD = 2.0 V                       | operation            | Resonator connection |      | 1.1  | 2.1  | 1    |
|           |        |                   | Subsystem clock        | fsub = 32.768 kHz Note 4          | Normal               | Square wave input    |      | 4.3  | 5.8  | μA   |
|           |        |                   | operation              | TA = -40°C                        | operation            | Resonator connection |      | 4.6  | 5.8  | 1    |
|           |        |                   |                        | fsub = 32.768 kHz Note 4          | Normal               | Square wave input    |      | 4.3  | 5.8  | 1    |
|           |        |                   |                        | TA = +25°C                        | operation            | Resonator connection |      | 4.6  | 5.8  | 1    |
|           |        |                   |                        | fsub = 32.768 kHz Note 4          | Normal               | Square wave input    |      | 4.5  | 7.6  | 1    |
|           |        |                   |                        | TA = +50°C                        | operation            | Resonator connection |      | 4.5  | 7.6  | 1    |
|           |        |                   |                        | fsub = 32.768 kHz Note 4          | Normal               | Square wave input    |      | 4.7  | 9.2  | 1    |
|           |        |                   |                        | TA = +70°C                        | operation            | Resonator connection |      | 5.1  | 9.2  | 1    |
|           |        |                   |                        | fSUB = 32.768 kHz Note 4          | Normal               | Square wave input    |      | 5.2  | 12.6 | 1    |
|           |        |                   |                        | TA = +85°C                        | operation            | Resonator connection |      | 5.7  | 12.6 | 1    |
|           |        |                   |                        | fSUB = 38.4 kHz Note 4            | Normal               | Square wave input    |      | 5.0  | 6.8  | μA   |
|           |        |                   |                        | TA = -40°C                        | operation            | Resonator connection |      | 5.4  | 6.8  | 1 '  |
|           |        |                   |                        | fSUB = 38.4 kHz Note 4            | Normal               | Square wave input    |      | 5.0  | 6.8  | 1    |
|           |        |                   |                        | TA = +25°C                        | operation            | Resonator connection |      | 5.4  | 6.8  | 1    |
|           |        |                   |                        | fSUB = 38.4 kHz Note 4            | Normal               | Square wave input    |      | 5.3  | 8.9  | 1    |
|           |        |                   |                        | TA = +50°C                        | operation            | Resonator connection |      | 5.3  | 8.9  | 1    |
|           |        |                   | fsub = 38.4 kHz Note 4 | Normal                            | Square wave input    |                      | 5.5  | 10.8 | 1    |      |
|           |        |                   | TA = +70°C             | operation                         | Resonator connection |                      | 6.0  | 10.8 | 1    |      |
|           |        |                   |                        | -                                 |                      | -                    |      |      | -    |      |
|           |        |                   |                        | fsub = 38.4 kHz Note 4 TA = +85°C | Normal operation     | Square wave input    |      | 6.1  | 14.8 | -    |
|           |        | I                 |                        | IA = +05 C                        | operation            | Resonator connection |      | 6.7  | 14.8 |      |

(Notes and Remarks are listed on the next page.)

- Note 1. Total current flowing into VDD and AVDD, including the input leakage current flowing when the level of the input pin is fixed to VDD or VSS. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the LCD controller/driver, A/D converter, LVD, I/O ports, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite. The current flowing into AFE is not included.
- **Note 2.** When high-speed on-chip oscillator and subsystem clock are stopped.
- **Note 3.** When high-speed system clock and subsystem clock are stopped.
- Note 4. When high-speed on-chip oscillator and high-speed system clock are stopped. When AMPHS1 = 1 (Ultra-low power consumption oscillation).
- Note 5. Relationship between operation voltage width, operation frequency of CPU, and operation mode is as below.

HS (high-speed main) mode: 2.7 V  $\leq$  VDD  $\leq$  5.5 V @ 1 MHz to 24 MHz

 $2.4 \text{ V} \leq \text{VDD} \leq 5.5 \text{ V} @ 1 \text{ MHz} \text{ to } 16 \text{ MHz}$ 

LS (low-speed main) mode:  $1.8 \text{ V} \leq \text{VDD} \leq 5.5 \text{ V} @ 1 \text{ MHz to } 8 \text{ MHz}$ 

- Remark 1. fMx: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
- Remark 2. fil: High-speed on-chip oscillator clock frequency
- Remark 3. fSUB: Subsystem clock frequency (XT1 clock oscillation frequency)
- Remark 4. Except subsystem clock operation, temperature condition for the TYP. value is TA = 25°C.

(TA = -40 to +85°C, 1.8 V  $\leq$  AVDD = VDD  $\leq$  5.5 V, AVSS = VSS = 0 V)

(2/2)

| Parameter                 | Symbol     |                        | _                                | Conditions                             | _                    | MIN. | TYP. | MAX. | Uni |
|---------------------------|------------|------------------------|----------------------------------|--|----------------------|------|------|------|-----|
| Supply current            | IDD2       | HALT mode              | HS (high-speed                   | fIH = 24 MHz Note 4                    | VDD = 5.0 V          |      | 0.42 | 2.03 | mA  |
| lote 1                    | Note 2     |                        | main) Mode Note 6                |  | VDD = 3.0 V          |      | 0.42 | 2.03 |     |
|                           |            |                        |                                  | fIH = 16 MHz Note 4                    | VDD = 5.0 V          |      | 0.39 | 1.58 |     |
|                           |            |                        |                                  |  | VDD = 3.0 V          |      | 0.39 | 1.58 |     |
|                           |            |                        | LS (low-speed                    | fIH = 8 MHz Note 4                     | VDD = 3.0 V          |      | 0.25 | 0.81 | mA  |
|                           |            |                        | main) Mode Note 6                |  | VDD = 2.0 V          |      | 0.25 | 0.81 |     |
|                           |            |                        | HS (high-speed                   | fmx = 20 MHz Note 3                    | Square wave input    |      | 0.26 | 1.75 | mΑ  |
|                           |            |                        | main) Mode Note 6                | VDD = 5.0 V                            | Resonator connection |      | 0.40 | 1.88 |     |
|                           |            |                        |                                  | fmx = 20 MHz Note 3                    | Square wave input    |      | 0.25 | 1.75 |     |
|                           |            |                        |                                  | VDD = 3.0 V                            | Resonator connection |      | 0.40 | 1.88 |     |
|                           |            |                        |                                  | fmx = 16 MHz Note 3                    | Square wave input    |      | 0.23 | 1.42 |     |
|                           |            |                        |                                  | VDD = 5.0 V                            | Resonator connection |      | 0.36 | 1.59 |     |
|                           |            |                        |                                  | fmx = 16 MHz Note 3                    | Square wave input    |      | 0.22 | 1.42 |     |
|                           |            |                        |                                  | VDD = 3.0 V                            | Resonator connection |      | 0.35 | 1.59 |     |
|                           |            |                        |                                  | fmx = 10 MHz Note 3                    | Square wave input    |      | 0.19 | 0.92 |     |
|                           |            |                        |                                  | VDD = 5.0 V                            | Resonator connection |      | 0.29 | 1.00 |     |
|                           |            |                        |                                  | fmx = 10 MHz Note 3                    | Square wave input    |      | 0.18 | 0.92 |     |
|                           |            |                        |                                  | VDD = 3.0 V                            | Resonator connection |      | 0.28 | 1.00 |     |
|                           |            |                        | LS (low-speed fmx = 8 MHz Note 3 |  | Square wave input    |      | 0.09 | 0.61 | m.  |
|                           |            |                        | main) Mode Note 6                | VDD = 3.0 V                            | Resonator connection |      | 0.15 | 0.66 |     |
|                           |            |                        | ,                                | fmx = 8 MHz Note 3                     | Square wave input    |      | 0.10 | 0.62 | 1   |
|                           |            |                        |                                  | VDD = 2.0 V                            | Resonator connection |      | 0.15 | 0.67 |     |
|                           |            |                        | Subsystem clock                  | fsub = 32.768 kHz Note 5               | Square wave input    |      | 0.32 | 0.69 | μ   |
|                           |            | operation              | TA = -40°C                       | Resonator connection                   |                      | 0.51 | 0.89 | μ,   |     |
|                           |            |                        | •                                | fsub = 32.768 kHz Note 5               | Square wave input    |      | 0.41 | 0.82 | •   |
|                           |            |                        |                                  | TA = +25°C                             | Resonator connection |      | 0.62 | 1.00 |     |
|                           |            |                        |                                  |  | Square wave input    |      | 0.02 | 1.40 |     |
|                           |            |                        |                                  | fsub = 32.768 kHz Note 5<br>TA = +50°C |                      |      |      |      |     |
|                           |            |                        |                                  |  | Resonator connection |      | 0.75 | 1.60 |     |
|                           |            |                        |                                  | SUB = 32.768 kHz Note 5<br>TA = +70°C  | Square wave input    |      | 0.82 | 2.70 |     |
|                           |            |                        |                                  |  | Resonator connection |      | 1.08 | 2.90 |     |
|                           |            |                        |                                  | fSUB = 32.768 kHz Note 5               | Square wave input    |      | 1.38 | 4.95 | ļ   |
|                           |            |                        |                                  | TA = +85°C                             | Resonator connection |      | 1.62 | 5.15 |     |
|                           |            |                        |                                  | fsub = 38.4 kHz Note 5                 | Square wave input    |      | 0.38 | 0.81 | μ   |
|                           |            |                        |                                  | TA = -40°C                             | Resonator connection |      | 0.60 | 1.04 | -   |
|                           |            |                        |                                  | fSUB = 38.4 kHz Note 5                 | Square wave input    |      | 0.48 | 0.96 | ļ   |
|                           |            |                        |                                  | TA = +25°C                             | Resonator connection |      | 0.73 | 1.17 |     |
|                           |            |                        |                                  | fSUB = 38.4 kHz Note 5                 | Square wave input    |      | 0.61 | 1.64 |     |
|                           |            |                        |                                  | TA = +50°C                             | Resonator connection |      | 0.88 | 1.88 |     |
|                           |            |                        |                                  | SUB = 38.4 kHz Note 5                  | Square wave input    |      | 0.96 | 3.16 |     |
| IDD3 STOP mode TA = -40°C |            | TA = +70°C             | Resonator connection             |  | 1.27                 | 3.40 |      |      |     |
|                           |            | fSUB = 38.4 kHz Note 5 | Square wave input                |  | 1.62                 | 5.80 |      |      |     |
|                           |            | TA = +85°C             | Resonator connection             |  | 1.90                 | 6.04 |      |      |     |
|                           | TA = -40°C |                        |                                  |  | 0.20                 | 0.59 | μ    |      |     |
|                           |            | Note 7                 | TA = +25°C                       |  |                      |      | 0.26 | 0.72 |     |
|                           |            | TA = +50°C             |                                  |  |                      | 0.33 | 1.30 |      |     |
|                           |            | TA = +70°C             |                                  |  |                      | 0.53 | 2.60 |      |     |
|                           | TA = +85°C |                        |                                  | İ                                      | 0.93                 | 4.85 |      |      |     |

(Notes and Remarks are listed on the next page.)

- Note 1. Total current flowing into VDD and AVDD, including the input leakage current flowing when the level of the input pin is fixed to VDD or VSS. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the LCD controller/driver, A/D converter, LVD, I/O ports, and on-chip pull-up/pull-down resistors and the current flowing during writing to the data flash. The current flowing into AFE is not included.
- Note 2. During HALT instruction execution from flash memory
- Note 3. When the high-speed on-chip oscillator and the subsystem clock are stopped
- Note 4. When the high-speed system clock and the subsystem clock are stopped
- **Note 5.** When high-speed on-chip oscillator and high-speed system clock are stopped. When RTCLPC = 1 and setting ultra-low current consumption (AMPHS1 = 1).
- Note 6. Relationship between operation voltage width, operation frequency of CPU, and operation mode is as below.

HS (high-speed main) Mode: 2.7 V ≤ VDD ≤ 5.5 V @ 1 MHz to 24 MHz

 $2.4 \text{ V} \leq \text{VDD} \leq 5.5 \text{ V} @ 1 \text{ MHz to } 16 \text{ MHz}$ 

LS (low-speed main) Mode:  $1.8 \text{ V} \leq \text{VDD} \leq 5.5 \text{ V} @ 1 \text{ MHz}$  to 8 MHz

- Note 7. Regarding the value for current to operate the subsystem clock in STOP mode, refer to that in HALT mode.
- Remark 1. fmx: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
- Remark 2. fih: High-speed on-chip oscillator clock frequency
- Remark 3. fSUB: Subsystem clock frequency (XT1 clock oscillation frequency)
- Remark 4. Except subsystem clock operation, temperature condition of the TYP. value is TA = 25°C.

#### • Peripheral functions

# (TA = -40 to +85°C, 1.8 V $\leq$ AVDD = VDD $\leq$ 5.5 V, AVSS = VSS = 0 V)

(1/2)

| Parameter                                      | Symbol            | Conditions                                   |  | MIN. | TYP. | MAX. | Unit |
|--|-------------------|--|--|------|------|------|------|
| Low-speed on-chip oscillator operating current | IFIL Note 1       |  |  |      | 0.20 |      | μΑ   |
| RTC2 operating current                         | IRTC Notes 1, 3   | fsuB = 32.768                                | kHz  |      | 0.02 |      | μΑ   |
| 12-bit Interval timer                          | Ітмка             | fSUB = 38.4 kHz, fMAIN stopped               |  |      | 0.02 |      | μA   |
| operating current                              | Notes 1, 2, 4     | fsub = 32.768                                |  | 0.02 |      | μΑ   |      |
| 8-bit Interval timer                           | ITMRT             | fsub = 38.4                                  | 8-bit counter mode × 2-channel operation             |      | 0.14 |      | μΑ   |
| operating current                              | Notes 1, 14       | kHz, fMAIN<br>stopped,<br>per unit           | 16-bit counter mode operation                        |      | 0.12 |      | μΑ   |
|  |                   | fsub =                                       | 8-bit counter mode × 2-channel operation             |      | 0.12 |      | μΑ   |
|  |                   | 32.768 kHz,<br>fMAIN<br>stopped,<br>per unit | 16-bit counter mode operation                        |      | 0.10 |      | μА   |
| Watchdog timer operating current               | IWDT Notes 1, 5   | fiL = 15 kHz                                 |  |      | 0.22 |      | μA   |
| 10-bit A/D converter                           | IADC Notes 1, 6   | When   | Normal mode, VDD = 5.0 V                             |      | 1.3  | 1.7  | mA   |
| operating current                              |                   | conversion at maximum speed                  | Low-voltage mode, VDD = 3.0 V                        |      | 0.5  | 0.7  | mA   |
| Internal reference voltage (1.45 V) current    | IADREF Notes 1, 7 |  |  |      | 85   |      | μA   |
| Temperature sensor operating current           | ITMPS Note 1      |  |  |      | 85   |      | μA   |
| LVD operating current                          | ILVI Notes 1, 8   |  |  |      | 0.06 |      | μΑ   |
| Self-programming operating current             | IFSP Notes 1, 9   |  |  |      | 2.0  | 12.2 | mA   |
| BGO operating current                          | IBGO Notes 1, 10  |  |  |      | 2.0  | 12.2 | mA   |
| SNOOZE operating                               | ISNOZ Notes 1, 11 | A/D  | The mode is performed                                |      | 0.50 | 0.60 | mA   |
| current  |                   | converter operation                          | During A/D conversion, low-voltage mode, VDD = 3.0 V |      | 1.20 | 1.44 |      |
|  |                   | Simplified SPI                               | (CSI)/UART operation                                 |      | 0.70 | 0.84 |      |
|  |                   | DTC operation                                | า  |      | 3.1  |      |      |

(Notes and Remarks are listed on the page after the next page.)

# (TA = -40 to +85°C, 1.8 V $\leq$ AVDD = VDD $\leq$ 5.5 V, AVSS = VSS = 0 V)

(2/2)

| Parameter                 | Symbol                |  | Con  | ditions                  |  | MIN. | TYP. | MAX. | Unit |
|---------------------------|-----------------------|--|--|--------------------------|--|------|------|------|------|
| LCD operating current     | ILCD1<br>Notes 12, 13 | External<br>resistance<br>division<br>method | fLCD = fSUB<br>(32.768 kHz)<br>LCD clock =<br>128 Hz | 1/3 bias<br>4-time slice | VDD = 5.0 V<br>VL4 = 5.0 V                 |      | 0.04 | 0.20 | μА   |
|                           |                       |  | fLCD = fSUB<br>(38.4 kHz)<br>LCD clock =<br>75 Hz    |                          |  |      | 0.08 | 0.40 |      |
|                           | ILCD2 Note 12         | Internal<br>voltage<br>boosting<br>method    | fLCD = fSUB<br>(32.768 kHz)<br>LCD clock =<br>128 Hz | 1/3 bias<br>4-time slice | VDD = 3.0 V<br>VL4 = 3.0 V<br>(VLCD = 04H) |      | 0.85 | 2.20 | μA   |
|                           |                       |  | fLCD = fSUB<br>(38.4 kHz)<br>LCD clock =<br>75 Hz    |                          |  |      | 0.50 | 2.20 |      |
|                           |                       |  | fLCD = fSUB<br>(32.768 kHz)<br>LCD clock =<br>128 Hz |                          | VDD = 5.0 V<br>VL4 = 5.1 V<br>(VLCD = 12H) |      | 1.55 | 3.70 | μА   |
|                           |                       |  | fLCD = fSUB<br>(38.4 kHz)<br>LCD clock =<br>75 Hz    |                          |  |      | 0.91 | 3.70 |      |
|                           | ILCD3 Note 12         | Capacitor split method                       | fLCD = fSUB<br>(32.768 kHz)<br>LCD clock =<br>128 Hz | 1/3 bias<br>4-time slice | VDD = 3.0 V<br>VL4 = 3.0 V                 |      | 0.20 | 0.50 | μА   |
|                           |                       |  | fLCD = fSUB<br>(38.4 kHz)<br>LCD clock =<br>75 Hz    |                          |  |      | 0.13 | 0.50 |      |
| Operating currents of the | ITMRJ Note 15         | •      |  |                          |  |      | 0.10 |      | μΑ   |
| meter-dedicated macro     | IUARTMG Note 15       |  |  |                          |  |      | 0.12 |      | μΑ   |
|                           | ISMOTD Note 15        |  |  |                          |  |      | 0.10 |      | μΑ   |
|                           | IEXSD Note 15         | fsub = 38.4 kH                               |  |                          | 0.02                                       |      | μA   |      |      |

(Notes and Remarks are listed on the next page.)

- Note 1. Current flowing to VDD.
- Note 2. When the high-speed on-chip oscillator and high-speed system clock are stopped.
- Note 3. Current flowing only to the real-time clock 2 (excluding the operating current of the low-speed on-chip oscillator and the XT1 oscillator). The supply current of the RL78 microcontrollers is the sum of the values of either IDD1 or IDD2, and IRTC, when the real-time clock 2 is operating in operation mode or HALT mode. When the low-speed on-chip oscillator is selected, IFIL should be added. IDD2 subsystem clock operation includes the operational current of the real-time clock 2.
- Note 4. Current flowing only to the 12-bit interval timer (excluding the operating current of the low-speed on-chip oscillator and the XT1 oscillator). The supply current of the RL78 microcontrollers is the sum of the values of either IDD1 or IDD2, and ITMKA, when the 12-bit interval timer operates in the operating mode or HALT mode. When the low-speed on-chip oscillator is selected, IFIL should be added. IDD2 subsystem clock operation includes the operational current of the 12-bit interval timer.
- Note 5. Current flowing only to the watchdog timer (including the operating current of the low-speed on-chip oscillator).

  The supply current of the RL78 microcontrollers is the sum of IDD1, IDD2 or IDD3 and IWDT when the watchdog timer is operating.
- Note 6. Current flowing only to the A/D converter. The supply current of the RL78 microcontrollers is the sum of IDD1 or IDD2, IADC, and IADREF when the A/D converter operates in the operating mode or the HALT mode.
- Note 7. Operation current flowing to the internal reference voltage.
- **Note 8.** Current flowing only to the LVD circuit. The supply current of the RL78 microcontrollers is the sum of IDD1, IDD2, or IDD3 and ILVI when the LVD circuit operates in the operating mode, HALT mode, or STOP mode.
- Note 9. Current flowing during self-programming
- Note 10. Current flowing during writing to the data flash
- Note 11. For time required to shift to the SNOOZE mode, see 27.3.3 SNOOZE mode in the User's Manual: Hardware.
- Note 12. Current flowing only to the LCD controller/driver (VDD pin). The current value of the RL78 microcontrollers is the sum of the LCD operating current (ILCD1, ILCD2, or ILCD3) and the supply current (IDD1 or IDD2) when the LCD controller/driver operates in the operating mode or HALT mode. Not including the current that flows through the LCD panel.
- Note 13. Not including the current that flows through the external divider resistor.
- Note 14. Current flowing only to the 8-bit interval timer (excluding the operating current of the low-speed on-chip oscillator and the XT1 oscillator). The supply current of the RL78 microcontrollers is the sum of the values of either IDD1 or IDD2, and IIT, when the 8-bit interval timer operates in the operating mode or HALT mode. When the low-speed on-chip oscillator is selected, IFIL should be added.
- **Note 15.** The current value of the RL78 microcontrollers is the sum of IDD2 or IDD3 and ITMRJ, IUARTMG, ISMOTD, or IEXSD when each module operates in the sub-HALT mode or STOP mode.
- Remark 1. flL: Low-speed on-chip oscillator clock frequency
- Remark 2. fSUB: Subsystem clock frequency (XT1 clock oscillation frequency)
- Remark 3. fclk: CPU/peripheral hardware clock frequency
- Remark 4. The temperature condition for the TYP. value is TA = 25°C.

# 3.4 AC Characteristics

# (TA = -40 to +85°C, 1.8 V $\leq$ AVDD = VDD $\leq$ 5.5 V, AVSS = VSS = 0 V)

(1/2)

| Items   | Symbol     |                            | Conditions                  |                     | MIN.           | TYP.  | MAX. | Unit |
|---|------------|----------------------------|-----------------------------|---------------------|----------------|-------|------|------|
| Instruction cycle                             | Tcy        | Main system                | HS (high-speed main)        | 2.7 V ≤ VDD ≤ 5.5 V | 0.0417         |       | 1    | μs   |
| (minimum instruction                          |            | clock (fMAIN)              | Mode                        | 2.4 V ≤ VDD < 2.7 V | 0.0625         |       | 1    | μs   |
| execution time)                               |            | operation                  | LS (low-speed main)<br>Mode | 1.8 V ≤ VDD ≤ 5.5 V | 0.125          |       | 1    | μs   |
|   |            | Subsystem                  | fxT = 38.4 kHz              | 1.8 V ≤ VDD ≤ 5.5 V |                | 26.04 |      | μs   |
|   |            | clock (fSUB)<br>operation  | fxt = 32.768 kHz            | 1.8 V ≤ VDD ≤ 5.5 V | 28.5           | 30.5  | 31.3 | μs   |
|   |            | In the self-               | HS (high-speed main)        | 2.7 V ≤ VDD ≤ 5.5 V | 0.0417         |       | 1    | μs   |
|   |            | programming                | Mode                        | 2.4 V ≤ VDD < 2.7 V | 0.0625         |       | 1    | μs   |
|   |            | mode                       | LS (low-speed main)<br>Mode | 1.8 V ≤ VDD ≤ 5.5 V | 0.125          |       | 1    | μs   |
| External system clock                         | fEX        | EXCLK                      | -                           | 2.7 V ≤ VDD ≤ 5.5 V | 1.0            |       | 20.0 | MHz  |
| frequency                                     |            |                            |                             | 2.4 V ≤ VDD < 2.7 V | 1.0            |       | 16.0 | MHz  |
|   |            |                            |                             | 1.8 V ≤ VDD < 2.4 V | 1.0            |       | 8.0  | MHz  |
|   | fEXT       | EXCLKS                     |                             |                     | 32             |       | 35   | kHz  |
| External system clock                         | texH,      | EXCLK                      |                             | 2.7 V ≤ VDD ≤ 5.5 V | 24             |       |      | ns   |
| input high-level width,                       | tEXL       |                            |                             | 2.4 V ≤ VDD < 2.7 V | 30             |       |      | ns   |
| low-level width                               |            |                            |                             | 1.8 V ≤ VDD < 2.4 V | 60             |       |      | ns   |
|   | tEXHS,     | EXCLKS                     |                             |                     | 13.7           |       |      | μs   |
| Timer input high-level width, low-level width | tTIH, tTIL | TI00 to TI07               |                             |                     | 1/fMCK +<br>10 |       |      | ns   |
| Timer RJ input cycle                          | tC         | TRJIO0, TRJI               | 01                          | 2.7 V ≤ VDD ≤ 5.5 V | 100            |       |      | ns   |
|   |            |                            |                             | 1.8 V ≤ VDD < 2.7 V | 300            |       |      | ns   |
| Timer RJ input high-                          | ttjih,     | TRJIO0, TRJI               | 01                          | 2.7 V ≤ VDD ≤ 5.5 V | 40             |       |      | ns   |
| level width, low-level width                  | tTJIL      |                            |                             | 1.8 V ≤ VDD < 2.7 V | 120            |       |      | ns   |
| Timer output                                  | fто        | TO00 to                    | HS (high-speed main)        | 4.0 V ≤ VDD ≤ 5.5 V |                |       | 12   | MHz  |
| frequency                                     |            | TO07                       | Mode                        | 2.7 V ≤ VDD < 4.0 V |                |       | 8    | MHz  |
|   |            | TRJIO0,                    |                             | 2.4 V ≤ VDD < 2.7 V |                |       | 4    | MHz  |
|   |            | TRJIO1,<br>TRJO0,<br>TRJO1 | LS (low-speed main)<br>Mode | 1.8 V ≤ VDD ≤ 5.5 V |                |       | 4    | MHz  |
| Buzzer output                                 | fPCL       | PCLBUZ0,                   | HS (high-speed main)        | 4.0 V ≤ VDD ≤ 5.5 V |                |       | 12   | MHz  |
| frequency                                     |            | PCLBUZ1                    | Mode                        | 2.7 V ≤ VDD < 4.0 V |                |       | 8    | MHz  |
|   |            |                            |                             | 2.4 V ≤ VDD < 2.7 V |                |       | 4    | MHz  |
|   |            |                            | LS (low-speed main) Mode    | 1.8 V ≤ VDD ≤ 5.5 V |                |       | 4    | MHz  |

# (TA = -40 to +85°C, 1.8 V $\leq$ AVDD = VDD $\leq$ 5.5 V, AVSS = VSS = 0 V)

(2/2)

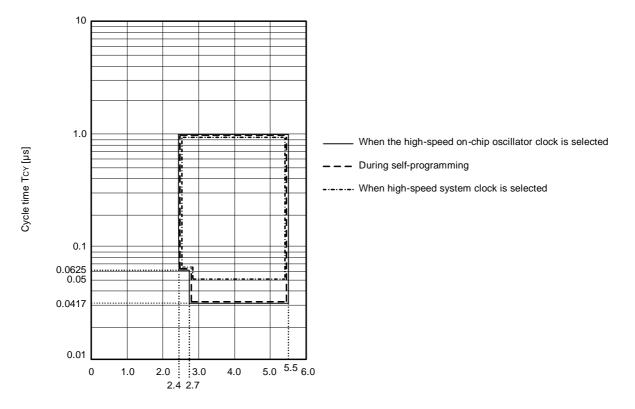
| Items  | Symbol          | Conditions   |                      | MIN. | TYP. | MAX. | Unit |
|--|-----------------|--|----------------------|------|------|------|------|
| Interrupt input high-<br>level width, low-level<br>width | tinth,<br>tintl | INTP0 to INTP7<br>(when the pin on which the function<br>is in use is multiplexed with pin<br>functions other than P27 to P22) | 1.8 V ≤ VDD ≤ 5.5 V  | 1    |      |      | μs   |
|  |                 | INTP2 to INTP7 (when the pin on which the function is in use is multiplexed with a pin function from among P27 to P22)         | 1.8 V ≤ AVDD ≤ 5.5 V | 1    |      |      | μs   |
| RESET low-level width                                    | tRSL            |  |                      | 10   |      |      | μs   |

Remark fMCK: Timer array unit operation clock frequency

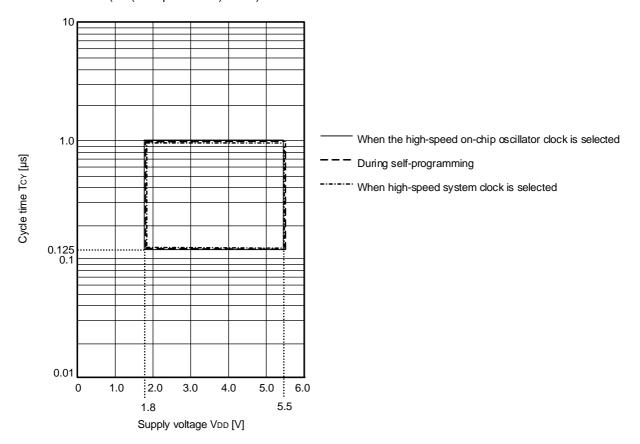
(Operation clock to be set by the CKSmn bit of timer mode register mn (TMRmn). m: Unit number (m = 0), n: Channel number (n = 0 to 7))

Minimum Instruction Execution Time During Main System Clock Operation

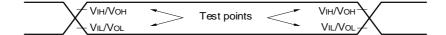
TCY vs VDD (HS (high-speed main) mode)



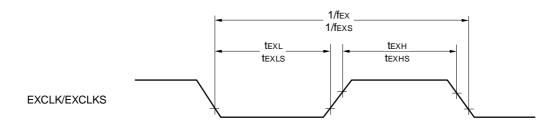
TCY vs VDD (LS (low-speed main) mode)



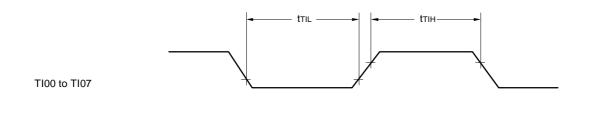
# **AC Timing Test Points**

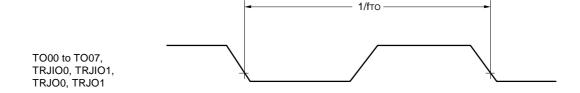


# External System Clock Timing



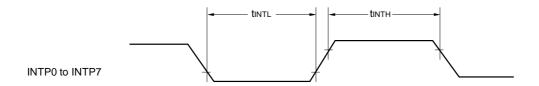
#### TI/TO Timing



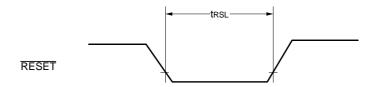




# Interrupt Request Input Timing



# RESET Input Timing



# 3.5 Peripheral Functions Characteristics

### 3.5.1 Serial array unit

#### (1) During communication at same potential (UART mode)

 $(TA = -40 \text{ to } +85^{\circ}\text{C}, 1.8 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$ 

| Parameter            | Symbol | Conditions   | HS (high-speed main) Mode |                  | LS (low-speed main)  Mode |                  | Unit |
|----------------------|--------|--|---------------------------|------------------|---------------------------|------------------|------|
|                      |        |  | MIN.                      | MAX.             | MIN.                      | MAX.             |      |
| Transfer rate Note 1 |        | 2.4 V ≤ VDD ≤ 5.5 V  |                           | fMCK/6<br>Note 2 |                           | fMCK/6<br>Note 2 | bps  |
|                      |        | Theoretical value of the maximum transfer rate $\label{eq:maximum transfer} \text{fMCK} = \text{fCLK} \ ^{\text{Note } 3}$ |                           | 4.0              |                           | 1.3              | Mbps |
|                      |        | 1.8 V ≤ VDD ≤ 5.5 V  | -                         | _                |                           | fмск/6           | bps  |
|                      |        | Theoretical value of the maximum transfer rate $fMCK = fCLK$ Note 3  | _                         | _                |                           | 1.3              | Mbps |

Note 1. Transfer rate in the SNOOZE mode is 4800 bps only.

Note 2. The following conditions are required for low voltage interface.

 $2.4 \text{ V} \le \text{VDD} < 2.7 \text{ V}$ : MAX. 2.6 Mbps

 $1.8 \text{ V} \leq \text{VDD} < 2.4 \text{ V}$ : MAX. 1.3 Mbps

Note 3. The maximum operating frequencies of the CPU/peripheral hardware clock (fCLK) are:

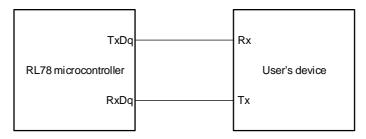
HS (high-speed main) mode: 24 MHz (2.7 V  $\leq$  VDD  $\leq$  5.5 V)

16 MHz (2.4 V  $\leq$  VDD  $\leq$  5.5 V)

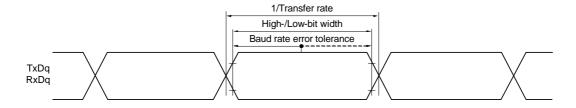
LS (low-speed main) mode:  $8 \text{ MHz} (1.8 \text{ V} \leq \text{VDD} \leq 5.5 \text{ V})$ 

Caution Select the normal input buffer for the RxDq pin and the normal output mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg).

#### **UART** mode connection diagram (during communication at same potential)



#### UART mode bit width (during communication at same potential) (reference)



**Remark 1.** q: UART number (q = 0 to 2), g: PIM or POM number (g = 0, 1, 3, 4, 5, 8)

Remark 2. fmck: Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number,

n: Channel number (mn = 00 to 03, 10, 11))

# (2) During communication at same potential (Simplified SPI(CSI) mode) (master mode, SCKp... internal clock output)

(TA = -40 to +85°C, 1.8 V  $\leq$  AVDD = VDD  $\leq$  5.5 V, AVSS = VSS = 0 V)

| Parameter                         | Symbol | С                   | onditions           | HS (high<br>main) | •    | -       | /-speed<br>Mode | Unit |
|-----------------------------------|--------|---------------------|---------------------|-------------------|------|---------|-----------------|------|
|                                   |        |                     |                     | MIN.              | MAX. | MIN.    | MAX.            |      |
| SCKp cycle time                   | tKCY1  | tkcy1 ≥ 4/fclk      | 2.7 V ≤ VDD ≤ 5.5 V | 167               |      | 500     |                 | ns   |
|                                   |        |                     | 2.4 V ≤ VDD ≤ 5.5 V | 250               |      | 500     |                 | ns   |
|                                   |        |                     | 1.8 V ≤ VDD ≤ 5.5 V | _                 |      | 500     |                 | ns   |
| SCKp high-/low-level width        | tKH1,  | 4.0 V ≤ VDD ≤ 5.5 V |                     | tKCY1/2           |      | tKCY1/2 |                 | ns   |
|                                   | tKL1   |                     |                     | - 12              |      | - 50    |                 |      |
|                                   |        | 2.7 V ≤ VDD ≤ \$    | 5.5 V               | tKCY1/2           |      | tKCY1/2 |                 | ns   |
|                                   |        |                     |                     | - 18              |      | - 50    |                 |      |
|                                   |        | 2.4 V ≤ VDD ≤ 5.5 V |                     | tKCY1/2 -         |      | tKCY1/2 |                 | ns   |
|                                   |        |                     |                     | 38                |      | - 50    |                 |      |
|                                   |        | 1.8 V ≤ VDD ≤ 5.5 V |                     | _                 |      | tKCY1/2 |                 | ns   |
|                                   |        |                     |                     |                   |      | - 50    |                 |      |
| SIp setup time (to SCKp↑) Note 1  | tSIK1  | 4.0 V ≤ VDD ≤ 5     | 5.5 V               | 44                |      | 110     |                 | ns   |
|                                   |        | 2.7 V ≤ VDD ≤ \$    | 5.5 V               | 44                |      | 110     |                 | ns   |
|                                   |        | 2.4 V ≤ VDD ≤ 5     | 5.5 V               | 75                |      | 110     |                 | ns   |
|                                   |        | 1.8 V ≤ VDD ≤ 5     | 5.5 V               | _                 |      | 110     |                 | ns   |
| SIp hold time (from SCKp↑) Note 2 | tKSI1  | 2.4 V ≤ VDD ≤ 5     | 5.5 V               | 19                |      | 19      |                 | ns   |
|                                   |        | 1.8 V ≤ VDD ≤ 5     | 5.5 V               | _                 |      | 19      |                 | ns   |
| Delay time from SCKp↓ to SOp      | tKSO1  | C = 30 pF           | 2.7 V ≤ VDD ≤ 5.5 V |                   | 25   |         | 50              | ns   |
| output Note 3                     |        | Note 4              | 2.4 V ≤ VDD ≤ 5.5 V |                   | 25   |         | 50              | ns   |
|                                   |        |                     | 1.8 V ≤ VDD ≤ 5.5 V |                   | _    |         | 50              | ns   |

- Note 1. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The SIp setup time becomes "to SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
- Note 2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp hold time becomes "from SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
- Note 3. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes "from SCKp↑" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
- **Note 4.** C is the load capacitance of the SCKp and SOp output lines.
- Caution Select the normal input buffer for the SIp pin and the normal output mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg).
- Remark 1. p: CSI number (p = 00, 10, 20), m: Unit number (m = 0, 1), n: Channel number (n = 0, 2), g: PIMand POM number (g = 0, 1, 3, 4, 5, 8)
- Remark 2. fMCK: Serial array unit operation clock frequency (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00, 02, 10))

# (3) During communication at same potential (Simplified SPI(CSI) mode) (slave mode, SCKp... external clock input)

#### $(TA = -40 \text{ to } +85^{\circ}C, 1.8 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$

(1/2)

| Parameter                           | Symbol | Symbol Conditions   | HS (high-spe        |                   | LS (low-spee   |                   | Unit            |    |
|-------------------------------------|--------|---------------------|---------------------|-------------------|----------------|-------------------|-----------------|----|
|                                     |        |                     |                     | MIN.              | MAX.           | MIN.              | MAX.            |    |
| SCKp cycle time Note 5              | tKCY2  | 4.0 V ≤ VDD ≤ 5.5 V | 20 MHz < fMCK       | 8/fмск            |                | _                 |                 | ns |
|                                     |        |                     | fMCK ≤ 20 MHz       | 8/fмск            |                | 6/fмск            |                 | ns |
|                                     |        | 2.7 V ≤ VDD ≤ 5.5 V | 16 MHz > fmck       | 8/fмск            |                | _                 |                 | ns |
|                                     |        |                     | fMCK ≤ 16 MHz       | 6/fмск            |                | 6/fмск            |                 | ns |
|                                     |        | 2.4 V ≤ VDD ≤ 5.5 V |                     | 6/fмск and<br>500 |                | 6/fмск and<br>500 |                 | ns |
|                                     |        | 1.8 V ≤ VDD ≤ 5.5 V |                     | _                 |                | 6/fмск and<br>750 |                 | ns |
| SCKp high-/low-level                | tKH2,  | 4.0 V ≤ VDD ≤ 5.5 V |                     | tKCY2/2 - 7       |                | tKCY2/2 - 7       |                 | ns |
| width                               | tKL2   | 2.7 V ≤ VDD ≤ 5.5 V |                     | tKCY2/2 - 8       |                | tKCY2/2 - 8       |                 | ns |
|                                     |        | 2.4 V ≤ VDD ≤ 5.5 V |                     | tKCY2/2 - 18      |                | tKCY2/2 - 18      |                 | ns |
|                                     |        | 1.8 V ≤ VDD ≤ 5.5 V |                     | _                 |                | tKCY2/2 - 18      |                 | ns |
| SIp setup time                      | tSIK2  | 2.7 V ≤ VDD ≤ 5.5 V |                     | 1/fмск + 20       |                | 1/fмск + 30       |                 | ns |
| (to SCKp↑) Note 1                   |        | 2.4 V ≤ VDD ≤ 5.5 V |                     | 1/fмск + 30       |                | 1/fмск + 30       |                 | ns |
|                                     |        | 1.8 V ≤ VDD ≤ 5.5 V |                     | _                 |                | 1/fмск + 30       |                 | ns |
| SIp hold time                       | tKSI2  | 2.4 V ≤ VDD ≤ 5.5 V |                     | 1/fмск + 31       |                | 1/fмск + 31       |                 | ns |
| (from SCKp↑) Note 2                 |        | 1.8 V ≤ VDD ≤ 5.5 V |                     | _                 |                | 1/fмск + 31       |                 | ns |
| Delay time from SCKp↓ to SOp output | tKSO2  | C = 30 pF Note 4    | 2.7 V ≤ VDD ≤ 5.5 V |                   | 2/fмск<br>+ 44 |                   | 2/fмск<br>+ 110 | ns |
| Note 3                              |        |                     | 2.4 V ≤ VDD ≤ 5.5 V |                   | 2/fмск<br>+ 75 |                   | 2/fмск<br>+ 110 | ns |
|                                     |        |                     | 1.8 V ≤ VDD ≤ 5.5 V |                   | _              |                   | 2/fмск<br>+ 110 | ns |

- Note 1. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The SIp setup time becomes "to SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
- Note 2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp hold time becomes "from SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
- Note 3. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes "from SCKp↑" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
- Note 4. C is the load capacitance of the SOp output lines.
- **Note 5.** The maximum transfer rate when using the SNOOZE mode is 1 Mbps.
- Caution Select the normal input buffer for the SIp and SCKp pins and the normal output mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg).
- Remark 1. p: CSI number (p = 00, 10, 20), m: Unit number (m = 0, 1), n: Channel number (n = 0, 2), g: PIM number (g = 0, 1, 3, 4, 5, 8)
- Remark 2. fMCK: Serial array unit operation clock frequency
  - (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number,
  - n: Channel number (mn = 00, 02, 10))

# (3) During communication at same potential (Simplified SPI(CSI) mode) (slave mode, SCKp... external clock input)

(TA = -40 to +85°C, 1.8 V  $\leq$  AVDD = VDD  $\leq$  5.5 V, AVSS = VSS = 0 V)

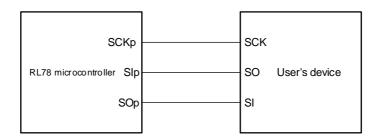
(2/2)

| Parameter        | Symbol | Conditions |                     | HS (high-speed main)  Mode |      | LS (low-speed main)<br>Mode |      | Unit |
|------------------|--------|------------|---------------------|----------------------------|------|-----------------------------|------|------|
|                  |        |            |                     | MIN.                       | MAX. | MIN.                        | MAX. |      |
| SSI00 setup time | tssik  | DAPmn = 0  | 2.7 V ≤ VDD ≤ 5.5 V | 120                        |      | 120                         |      | ns   |
|                  |        |            | 2.4 V ≤ VDD ≤ 5.5 V | 200                        |      | 200                         |      | ns   |
|                  |        |            | 1.8 V ≤ VDD ≤ 5.5 V | _                          |      | 200                         |      | ns   |
|                  |        | DAPmn = 1  | 2.7 V ≤ VDD ≤ 5.5 V | 1/fмск + 120               |      | 1/fmck + 120                |      | ns   |
|                  |        |            | 2.4 V ≤ VDD ≤ 5.5 V | 1/fmck + 200               |      | 1/fmck + 200                |      | ns   |
|                  |        |            | 1.8 V ≤ VDD ≤ 5.5 V | _                          |      | 1/fmck + 200                |      | ns   |
| SSI00 hold time  | tkssi  | DAPmn = 0  | 2.7 V ≤ VDD ≤ 5.5 V | 1/fмск + 120               |      | 1/fмск + 120                |      | ns   |
|                  |        |            | 2.4 V ≤ VDD ≤ 5.5 V | 1/fMCK + 200               |      | 1/fмcк + 200                |      | ns   |
|                  |        |            | 1.8 V ≤ VDD ≤ 5.5 V | _                          |      | 1/fмcк + 200                |      | ns   |
|                  |        | DAPmn = 1  | 2.7 V ≤ VDD ≤ 5.5 V | 120                        |      | 120                         |      | ns   |
|                  |        |            | 2.4 V ≤ VDD ≤ 5.5 V | 200                        |      | 200                         |      | ns   |
|                  |        |            | 1.8 V ≤ VDD ≤ 5.5 V | _                          |      | 200                         |      | ns   |

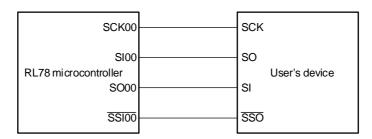
Caution Select the normal input buffer for the SIp and SCKp pins and the normal output mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

**Remark** p: CSI number (p = 00), m: Unit number (m = 0), n: Channel number (n = 0), g: PIM number (g = 3, 4)

#### Simplified SPI(CSI) mode connection diagram (during communication at same potential)

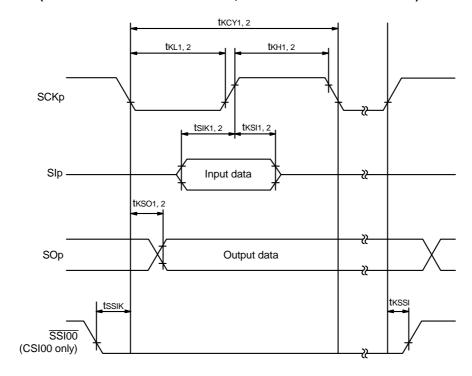


# Simplified SPI(CSI) mode connection diagram (during communication at same potential) (Slave transmission of slave select input function (CSI00))

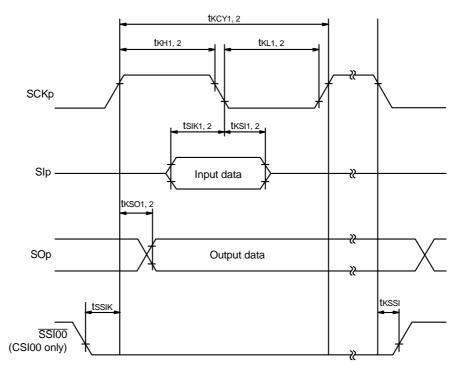


Remark p: CSI number (p = 00, 10, 20), m: Unit number (m = 0, 1), n: Channel number (n = 0, 2)

Simplified SPI(CSI) mode serial transfer timing (during communication at same potential) (When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



Simplified SPI(CSI) mode serial transfer timing (during communication at same potential)
(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)



**Remark** p: CSI number (p = 00, 10, 20), m: Unit number (m = 0, 1), n: Channel number (n = 0, 2)

### (4) During communication at same potential (simplified I<sup>2</sup>C mode)

 $(TA = -40 \text{ to } +85^{\circ}\text{C}, 1.8 \text{ V} \le \text{AVDD} = \text{VDD} \le 5.5 \text{ V}, \text{AVSS} = \text{VSS} = 0 \text{ V})$ 

| Parameter                     | Symbol   | Conditions   | HS (high-<br>main) M   | •              | LS (low-s<br>main) M   | •             | Unit |
|-------------------------------|----------|--|------------------------|----------------|------------------------|---------------|------|
|                               |          |  | MIN.                   | MAX.           | MIN.                   | MAX.          |      |
| SCLr clock frequency          | fSCL     | 2.7 V ≤ VDD ≤ 5.5 V,<br>Cb = 50 pF, Rb = 2.7 kΩ                                      |                        | 1000<br>Note 1 |                        | 400<br>Note 1 | kHz  |
|                               |          | 1.8 V (2.4 V Note 3) $\leq$ VDD $\leq$ 5.5 V,<br>Cb = 100 pF, Rb = 3 kΩ              |                        | 400<br>Note 1  |                        | 400<br>Note 1 | kHz  |
|                               |          | 1.8 V (2.4 V Note 3) $\leq$ VDD $<$ 2.7 V,<br>Cb = 100 pF, Rb = 5 kΩ                 |                        | 300<br>Note 1  |                        | 300<br>Note 1 | kHz  |
| Hold time when SCLr = "L"     | tLOW     | $2.7 \text{ V} \le \text{VDD} \le 5.5 \text{ V},$<br>Cb = 50 pF, Rb = 2.7 k $\Omega$ | 475                    |                | 1150                   |               | ns   |
|                               |          | 1.8 V (2.4 V Note 3) $\leq$ VDD $\leq$ 5.5 V,<br>Cb = 100 pF, Rb = 3 kΩ              | 1150                   |                | 1150                   |               | ns   |
|                               |          | 1.8 V (2.4 V Note 3) $\leq$ VDD $<$ 2.7 V,<br>Cb = 100 pF, Rb = 5 kΩ                 | 1550                   |                | 1550                   |               | ns   |
| Hold time when SCLr = "H"     | tHIGH    | $2.7 \text{ V} \le \text{VDD} \le 5.5 \text{ V},$<br>Cb = 50 pF, Rb = 2.7 k $\Omega$ | 475                    |                | 1150                   |               | ns   |
|                               |          | 1.8 V (2.4 V Note 3) $\leq$ VDD $\leq$ 5.5 V,<br>Cb = 100 pF, Rb = 3 kΩ              | 1150                   |                | 1150                   |               | ns   |
|                               |          | 1.8 V (2.4 V Note 3) $\leq$ VDD $<$ 2.7 V,<br>Cb = 100 pF, Rb = 5 kΩ                 | 1550                   |                | 1550                   |               | ns   |
| Data setup time (reception)   | tsu: dat | 2.7 V ≤ VDD ≤ 5.5 V,<br>Cb = 50 pF, Rb = 2.7 kΩ                                      | 1/fMCK +<br>85 Note 2  |                | 1/fMCK +<br>145 Note 2 |               | ns   |
|                               |          | 1.8 V (2.4 V Note 3) $\leq$ VDD $\leq$ 5.5 V,<br>Cb = 100 pF, Rb = 3 kΩ              | 1/fMCK +<br>145 Note 2 |                | 1/fMCK +<br>145 Note 2 |               | ns   |
|                               |          | 1.8 V (2.4 V Note 3) $\leq$ VDD $<$ 2.7 V,<br>Cb = 100 pF, Rb = 5 kΩ                 | 1/fMCK + 230 Note 2    |                | 1/fMCK + 230 Note 2    |               | ns   |
| Data hold time (transmission) | tHD: DAT | 2.7 V ≤ VDD ≤ 5.5 V,<br>Cb = 50 pF, Rb = 2.7 kΩ                                      | 0                      | 305            | 0                      | 305           | ns   |
|                               |          | 1.8 V (2.4 V Note 3) $\leq$ VDD $\leq$ 5.5 V,<br>Cb = 100 pF, Rb = 3 kΩ              | 0                      | 355            | 0                      | 355           | ns   |
|                               |          | 1.8 V (2.4 V Note 3) $\leq$ VDD $<$ 2.7 V,<br>Cb = 100 pF, Rb = 5 kΩ                 | 0                      | 405            | 0                      | 405           | ns   |

**Note 1.** The value must be equal to or less than fMCK/4.

**Note 2.** Set the fMCK value to keep the hold time of SCLr = "L" and SCLr = "H".

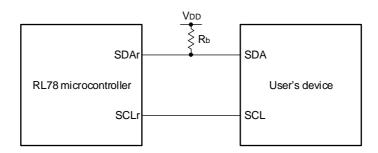
Note 3. Condition in the HS (high-speed main) mode

Caution Select the normal input buffer and the N-ch open drain output (VDD tolerance) mode for the SDAr pin and the normal output mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register h (POMh).

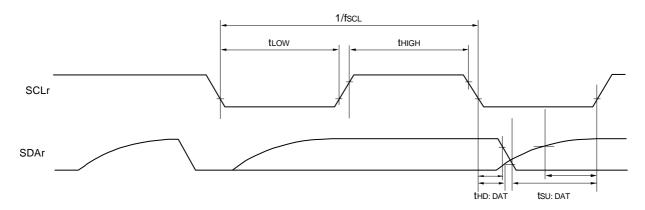
(Remarks are listed on the next page.)



#### Simplified I<sup>2</sup>C mode connection diagram (during communication at same potential)



#### Simplified I<sup>2</sup>C mode serial transfer timing (during communication at same potential)



 $\textbf{Remark 1.} \ \ \mathsf{Rb} \ [\Omega] : \mathsf{Communication line} \ (\mathsf{SDAr}) \ \mathsf{pull-up} \ \mathsf{resistance}, \ \mathsf{Cb} \ [\mathsf{F}] : \mathsf{Communication line} \ (\mathsf{SDAr}, \ \mathsf{SCLr}) \ \mathsf{load} \ \mathsf{capacitance}$ 

**Remark 2.** r: IIC number (r = 00, 10, 20), g: PIM number (g = 0, 1, 3, 4, 5, 8)

Remark 3. fMCK: Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number (m = 0, 1),

n: Channel number (n = 0, 2), mn = 00, 02, 10)

# (5) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode)

 $(TA = -40 \text{ to } +85^{\circ}\text{C}, 1.8 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$ 

(1/2)

| Parameter     | Symbol |           | Conditions   |      | gh-speed<br>n) Mode | ,    | ow-speed<br>n) Mode | Unit |
|---------------|--------|-----------|--|------|---------------------|------|---------------------|------|
|               |        |           |  | MIN. | MAX.                | MIN. | MAX.                |      |
| Transfer rate |        | Reception | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V}$                    |      | fMCK/6<br>Note 1    |      | fMCK/6<br>Note 1    | bps  |
|               |        |           | Theoretical value of the maximum transfer rate fMCK = fCLK Note 4  |      | 4.0                 |      | 1.3                 | Mbps |
|               |        |           | 2.7 V ≤ VDD < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V  |      | fMCK/6<br>Note 1    |      | fMCK/6<br>Note 1    | bps  |
|               |        |           | Theoretical value of the maximum transfer rate fMCK = fCLK Note 4  |      | 4.0                 |      | 1.3                 | Mbps |
|               |        |           | 1.8 V $(2.4 \text{ V}^{\text{Note 5}}) \le \text{VDD} < 3.3 \text{ V},$<br>1.6 V $\le \text{Vb} \le 2.0 \text{ V}$ |      | fMCK/6<br>Notes 1,  |      | fMCK/6<br>Notes 1,  | bps  |
|               |        |           |  |      | 2, 3                |      | 2, 3                |      |
|               |        |           | Theoretical value of the maximum transfer rate fMCK = fCLK Note 4  |      | 4.0                 |      | 1.3                 | Mbps |

- Note 1. Transfer rate in the SNOOZE mode is 4800 bps only.
- Note 2. Use it with VDD ≥ Vb
- Note 3. The following conditions are required for low voltage interface.

 $2.4 \text{ V} \le \text{VDD} < 2.7 \text{ V}$ : MAX. 2.6 Mbps

 $1.8 \text{ V} \leq \text{VDD} < 2.4 \text{ V} : \text{MAX. } 1.3 \text{ Mbps}$ 

Note 4. The maximum operating frequencies of the CPU/peripheral hardware clock (fCLK) are:

HS (high-speed main) Mode: 24 MHz (2.7 V  $\leq$  VDD  $\leq$  5.5 V)

16 MHz (2.4 V  $\leq$  VDD  $\leq$  5.5 V)

LS (low-speed main) Mode:  $8 \text{ MHz} (1.8 \text{ V} \leq \text{VDD} \leq 5.5 \text{ V})$ 

- Note 5. Condition in the HS (high-speed main) mode
- Caution Select the TTL input buffer for the RxDq pin and the N-ch open drain output (VDD tolerance) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and VIL, see the DC characteristics with TTL input buffer selected.
- Remark 1. Vb [V]: Communication line voltage
- **Remark 2.** q: UART number (q = 0 to 2), g: PIM or POM number (g = 0, 1, 3, 4, 5, 8)
- Remark 3. fMCK: Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number,

n: Channel number (mn = 00 to 03, 10, 11))

# (5) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode) (TA = -40 to +85°C, 1.8 V $\leq$ AVDD = VDD $\leq$ 5.5 V, AVSS = VSS = 0 V)

(2/2)

| Parameter | Symbol |              | Conditions  | ` | gh-speed<br>n) Mode | `    | ow-speed<br>n) Mode | Unit |
|-----------|--------|--------------|---|---|---------------------|------|---------------------|------|
|           |        |              |   |   |                     | MIN. | MAX.                |      |
| Transfer  |        | Transmission | 4.0 V ≤ VDD ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V   |   | Note 1              |      | Note 1              | bps  |
| rate      |        |              | Theoretical value of the maximum transfer rate $C_b = 50$ pF, $R_b = 1.4$ k $\Omega$ , $V_b = 2.7$ V                |   | 2.8<br>Note 2       |      | 2.8<br>Note 2       | Mbps |
|           |        |              | 2.7 V ≤ VDD < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V   |   | Note 3              |      | Note 3              | bps  |
|           |        |              | Theoretical value of the maximum transfer rate $C_b = 50$ pF, $R_b = 2.7$ k $\Omega$ , $V_b = 2.3$ V                |   | 1.2<br>Note 4       |      | 1.2<br>Note 4       | Mbps |
|           |        |              | 1.8 V $(2.4 \text{ V }^{\text{Note 8}}) \le \text{VDD} < 3.3 \text{ V},$<br>1.6 V $\le \text{Vb} \le 2.0 \text{ V}$ |   | Notes 5, 6          |      | Notes 5, 6          | bps  |
|           |        |              | Theoretical value of the maximum transfer rate $C_b = 50$ pF, $R_b = 5.5$ k $\Omega$ , $V_b = 1.6$ V                |   | 0.43<br>Note 7      |      | 0.43<br>Note 7      | Mbps |

Note 1. The smaller maximum transfer rate derived by using fmck/12 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 4.0 V  $\leq$  VDD  $\leq$  5.5 V and 2.7 V  $\leq$  Vb  $\leq$  4.0 V

Maximum transfer rate = 
$$\frac{1}{\{-C_b \times R_b \times \ln (1 - \frac{2.2}{V_b})\} \times 3}$$
 [bps]
$$\frac{1}{\{-C_b \times R_b \times \ln (1 - \frac{2.2}{V_b})\} \times 3} \times \frac{1}{\{-C_b \times R_b \times \ln (1 - \frac{2.2}{V_b})\}} \times 100 [\%]$$
Baud rate error (theoretical value) = 
$$\frac{1}{\{-C_b \times R_b \times \ln (1 - \frac{2.2}{V_b})\} \times 100 [\%]} \times 100 [\%]$$

Note 2. This value as an example is calculated when the conditions described in the "Conditions" column are met.

Refer to Note 1 above to calculate the maximum transfer rate under conditions of the customer.

Note 3. The smaller maximum transfer rate derived by using fMCK/6 or the following expression is the valid maximum transfer rate

Expression for calculating the transfer rate when 2.7 V  $\leq$  VDD < 4.0 V and 2.3 V  $\leq$  Vb  $\leq$  2.7 V

Maximum transfer rate = 
$$\frac{1}{\{-C_b \times R_b \times \ln (1 - \frac{2.0}{V_b})\} \times 3}$$
 [bps] 
$$\frac{1}{\text{Transfer rate } \times 2} - \{-C_b \times R_b \times \ln (1 - \frac{2.0}{V_b})\} \times 3$$

Baud rate error (theoretical value) = 
$$\frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\} }{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits} }$$

Note 4. This value as an example is calculated when the conditions described in the "Conditions" column are met.

Refer to Note 3 above to calculate the maximum transfer rate under conditions of the customer.

Note 5. Use it with VDD ≥ Vb



<sup>\*</sup> This value is the theoretical value of the relative difference between the transmission and reception sides.

<sup>\*</sup> This value is the theoretical value of the relative difference between the transmission and reception sides.

Note 6. The smaller maximum transfer rate derived by using fMCK/6 or the following expression is the valid maximum transfer rate

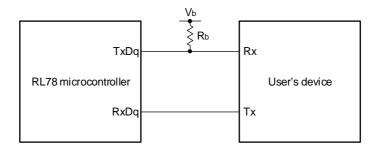
Expression for calculating the transfer rate when 1.8 V  $\leq$  VDD < 3.3 V and 1.6 V  $\leq$  Vb  $\leq$  2.0 V

Maximum transfer rate = 
$$\frac{1}{\{-C_b \times R_b \times \ln (1 - \frac{1.5}{V_b})\} \times 3} [bps]$$

$$\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln (1 - \frac{1.5}{V_b})\}$$
Baud rate error (theoretical value) = 
$$\frac{1}{1} \times \frac{1}{V_b} = \frac{1}{V_b} \times \frac{1}{V_b} \times \frac{1}{V_b} \times \frac{1}{V_b} = \frac{1}{V_b} \times \frac{1}{V_b} \times \frac{1}{V_b} = \frac{1}{V_b} \times \frac{1}{$$

- **Note 7.** This value as an example is calculated when the conditions described in the "Conditions" column are met. Refer to **Note 6** above to calculate the maximum transfer rate under conditions of the customer.
- Note 8. Condition in the HS (high-speed main) mode
- Caution Select the TTL input buffer for the RxDq pin and the N-ch open drain output (VDD tolerance) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and VIL, see the DC characteristics with TTL input buffer selected.

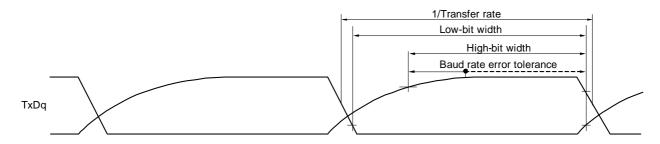
**UART** mode connection diagram (during communication at different potential)

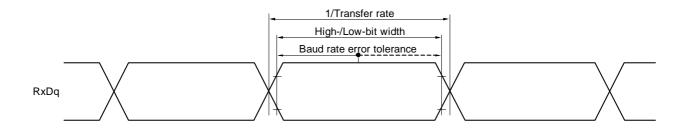


(Remarks are listed on the next page.)

<sup>\*</sup> This value is the theoretical value of the relative difference between the transmission and reception sides.

#### UART mode bit width (during communication at different potential) (reference)





Remark 1. Rb [ $\Omega$ ]: Communication line (TxDq) pull-up resistance,

 $\label{eq:communication} \mbox{Cb [F]: Communication line (TxDq) load capacitance, Vb [V]: Communication line voltage}$ 

**Remark 2.** q: UART number (q = 0 to 2), g: PIM or POM number (g = 0, 1, 3, 4, 5, 8)

Remark 3. fMCK: Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).

m: Unit number, n: Channel number (mn = 00 to 03, 10, 11))

# (6) Communication at different potential (1.8 V, 2.5 V, 3 V) (Simplified SPI(CSI) mode) (master mode, SCKp... internal clock output)

 $(TA = -40 \text{ to } +85^{\circ}C, 1.8 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$ 

(1/2)

| Parameter                 | Symbol |   | Conditions  | HS (high main) I |      | LS (low-<br>main) N | •    | Unit |
|---------------------------|--------|---|---|------------------|------|---------------------|------|------|
|                           |        |   |   | MIN.             | MAX. | MIN.                | MAX. |      |
| SCKp cycle time           | tKCY1  | tkcy1 ≥ 4/fclk  | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V},$ $\text{Cb} = 30 \text{ pF}, \text{Rb} = 1.4 \text{ k}\Omega$ | 300              |      | 1150                |      | ns   |
|                           |        |   | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V},$<br>Cb = 30 pF, Rb = 2.7 k $\Omega$                             | 500<br>Note 1    |      | 1150                |      | ns   |
|                           |        |   | 1.8 V (2.4 V <sup>Note 2</sup> ) ≤ VDD < 3.3 V,<br>1.6 V ≤ Vb ≤ 2.0 V, Cb = 30 pF, Rb = 5.5 kΩ  | 1150<br>Note 1   |      | 1150                |      | ns   |
| SCKp high-<br>level width | tKH1   | 4.0 V ≤ V <sub>DD</sub> ≤ 8<br>C <sub>b</sub> = 30 pF, R <sub>b</sub> | $5.5 \text{ V}, 2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V},$<br>= 1.4 k $\Omega$   | tKCY1/2<br>- 75  |      | tKCY1/2<br>- 75     |      | ns   |
|                           |        | 2.7 V ≤ VDD < 4<br>Cb = 30 pF, Rb                                     | $4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V},$<br>= $2.7 \text{ k}\Omega$  | tKCY1/2<br>- 170 |      | tKCY1/2<br>- 170    |      | ns   |
|                           |        | ,   | $(e^2) \le V_{DD} < 3.3 \text{ V},$<br>0 V, Cb = 30 pF, Rb = 5.5 k $\Omega$   | tKCY1/2<br>- 458 |      | tKCY1/2<br>- 458    |      | ns   |
| SCKp low-<br>level width  | tKL1   |   | .0 V ≤ VDD ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V,<br>tb = 30 pF, Rb = 1.4 kΩ  |                  |      | tKCY1/2<br>- 50     |      | ns   |
|                           |        |   | $7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V},$<br>b = 30 pF, Rb = 2.7 kΩ  |                  |      | tKCY1/2<br>- 50     |      | ns   |
|                           |        | ,   | $(e^2) \le V_{DD} < 3.3 \text{ V},$<br>0 V, Cb = 30 pF, Rb = 5.5 k $\Omega$   | tKCY1/2<br>- 50  |      | tKCY1/2<br>- 50     |      | ns   |

**Note 1.** Use it with VDD ≥ Vb

Note 2. Condition in the HS (high-speed main) mode

Caution Select the TTL input buffer for the SIp pin and the N-ch open drain output (VDD tolerance) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and VIL, see the DC characteristics with TTL input buffer selected.

(Remarks are listed two pages after the next page.)

# (6) Communication at different potential (1.8 V, 2.5 V, 3 V) (Simplified SPI(CSI) mode) (master mode, SCKp... internal clock output)

### $(TA = -40 \text{ to } +85^{\circ}C, 1.8 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$

(2/2)

| Parameter                         | Symbol | Conditions   | HS (high<br>main) I |      | LS (low-<br>main) |      | Unit |
|-----------------------------------|--------|--|---------------------|------|-------------------|------|------|
|                                   |        |  | MIN.                | MAX. | MIN.              | MAX. |      |
| SIp setup time (to SCKp↓) Note 1  | tSIK1  | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V},$ Cb = 30 pF, Rb = 1.4 k $\Omega$   | 81                  |      | 479               |      | ns   |
|                                   |        | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V},$<br>Cb = 30 pF, Rb = 2.7 k $\Omega$  | 177                 |      | 479               |      | ns   |
|                                   |        | 1.8 V (2.4 V <sup>Note 4</sup> ) ≤ VDD < 3.3 V,<br>1.6 V ≤ Vb ≤ 2.0 V Note <sup>3</sup> , Cb = 30 pF, Rb = 5.5 kΩ  | 479                 |      | 479               |      | ns   |
| SIp hold time (from SCKp↓) Note 1 | tKSI1  | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V},$ Cb = 30 pF, Rb = 1.4 k $\Omega$   | 19                  |      | 19                |      | ns   |
|                                   |        | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V},$<br>Cb = 30 pF, Rb = 2.7 k $\Omega$  | 19                  |      | 19                |      | ns   |
|                                   |        | 1.8 V (2.4 V <sup>Note 4</sup> ) $\leq$ V <sub>DD</sub> $<$ 3.3 V,<br>1.6 V $\leq$ V <sub>b</sub> $\leq$ 2.0 V Note <sup>3</sup> , C <sub>b</sub> $=$ 30 pF, R <sub>b</sub> $=$ 5.5 kΩ | 19                  |      | 19                |      | ns   |
| Delay time from SCKp↑ to SOp      | tKSO1  | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V},$ Cb = 30 pF, Rb = 1.4 k $\Omega$   |                     | 100  |                   | 100  | ns   |
| output Note 1                     |        | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V},$<br>Cb = 30 pF, Rb = 2.7 k $\Omega$  |                     | 195  |                   | 195  | ns   |
|                                   |        | 1.8 V (2.4 V <sup>Note 4</sup> ) ≤ V <sub>DD</sub> < 3.3 V,<br>1.6 V ≤ V <sub>b</sub> ≤ 2.0 V Note <sup>3</sup> , C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ                      |                     | 483  |                   | 483  | ns   |
| SIp setup time (to SCKp↓) Note 2  | tSIK1  | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V},$ Cb = 30 pF, Rb = 1.4 k $\Omega$   | 44                  |      | 110               |      | ns   |
|                                   |        | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V},$<br>Cb = 30 pF, Rb = 2.7 k $\Omega$  | 44                  |      | 110               |      | ns   |
|                                   |        | 1.8 V (2.4 V <sup>Note 4</sup> ) ≤ V <sub>DD</sub> < 3.3 V,<br>1.6 V ≤ V <sub>b</sub> ≤ 2.0 V Note <sup>3</sup> , C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ                      | 110                 |      | 110               |      | ns   |
| SIp hold time (from SCKp↓) Note 2 | tKSI1  | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V},$ Cb = 30 pF, Rb = 1.4 k $\Omega$   | 19                  |      | 19                |      | ns   |
|                                   |        | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V},$ $\text{Cb} = 30 \text{ pF}, \text{Rb} = 2.7 \text{ k}\Omega$                            | 19                  |      | 19                |      | ns   |
|                                   |        | 1.8 V (2.4 V <sup>Note 4</sup> ) $\leq$ V <sub>DD</sub> $<$ 3.3 V,<br>1.6 V $\leq$ V <sub>b</sub> $\leq$ 2.0 V Note <sup>3</sup> , C <sub>b</sub> $=$ 30 pF, R <sub>b</sub> $=$ 5.5 kΩ | 19                  |      | 19                |      | ns   |
| Delay time from SCKp↑ to SOp      | tKSO1  | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V},$ Cb = 30 pF, Rb = 1.4 k $\Omega$   |                     | 25   |                   | 25   | ns   |
| output Note 2                     |        | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V},$ Cb = 30 pF, Rb = 2.7 k $\Omega$   |                     | 25   |                   | 25   | ns   |
|                                   |        | 1.8 V (2.4 V <sup>Note 4</sup> ) $\leq$ V <sub>DD</sub> $<$ 3.3 V,<br>1.6 V $\leq$ V <sub>b</sub> $\leq$ 2.0 V Note <sup>3</sup> , C <sub>b</sub> $=$ 30 pF, R <sub>b</sub> $=$ 5.5 kΩ |                     | 25   |                   | 25   | ns   |

**Note 1.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.

Note 2. When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Note 3. Use it with VDD ≥ Vb

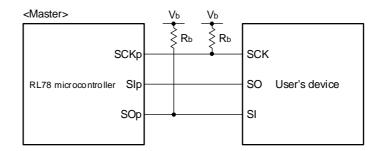
Note 4. Condition in the HS (high-speed main) mode

(Caution and remarks are listed on the next page.)



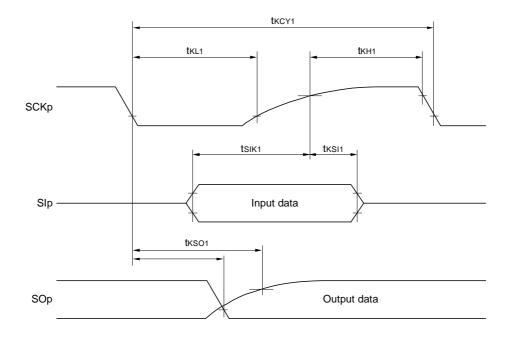
Caution Select the TTL input buffer for the SIp pin and the N-ch open drain output (VDD tolerance) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and VIL, see the DC characteristics with TTL input buffer selected.

Simplified SPI(CSI) mode connection diagram (during communication at different potential)

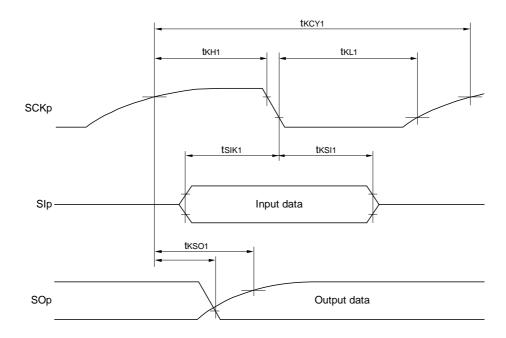


- Remark 1. Rb [ $\Omega$ ]: Communication line (SCKp, SOp) pull-up resistance, Cb [F]: Communication line (SCKp, SOp) load capacitance, Vb [V]: Communication line voltage
- **Remark 2.** p: CSI number (p = 00, 10, 20), m: Unit number (m = 0, 1), n: Channel number (n = 0, 2), g: PIM or POM number (g = 0, 1, 3, 4, 5, 8)
- Remark 3. fMCK: Serial array unit operation clock frequency (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00, 02, 10))

Simplified SPI(CSI) mode serial transfer timing (master mode) (during communication at different potential) (When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



Simplified SPI(CSI) mode serial transfer timing (master mode) (during communication at different potential) (When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)



 $\begin{array}{ll} \textbf{Remark} & \text{p: CSI number (p = 00, 10, 20), m: Unit number (m = 0, 1), n: Channel number (n = 0, 2),} \\ & \text{g: PIM or POM number (g = 0, 1, 3, 4, 5, 8)} \end{array}$ 

# (7) Communication at different potential (1.8 V, 2.5 V, 3 V) (Simplified SPI(CSI) mode) (slave mode, SCKp... external clock input)

 $(TA = -40 \text{ to } +85^{\circ}C, 1.8 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$ 

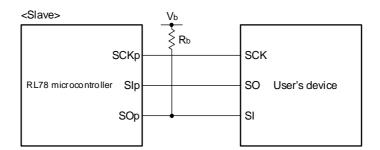
| Parameter                            | Symbol   | Co  | nditions                       | , ,             | peed main)<br>ode |                 | peed main)<br>ode | Unit |
|--------------------------------------|--|---|--------------------------------|-----------------|-------------------|-----------------|-------------------|------|
|                                      |  |   |                                | MIN.            | MAX.              | MIN.            | MAX.              |      |
| SCKp cycle time                      | tKCY2  | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V},$   | 20 MHz < fMCK                  | 12/fmck         |                   | _               |                   | ns   |
| Note 1                               |  | 2.7 V ≤ Vb ≤ 4.0 V  | 8 MHz < fMCK ≤ 20 MHz          | 10/fmck         |                   | _               |                   | ns   |
|                                      |  |   | 4 MHz < fMCK ≤ 8 MHz           | 8/fмск          |                   | _               |                   | ns   |
|                                      |  |   | fMCK ≤ 4 MHz                   | 6/fмск          |                   | _               |                   | ns   |
|                                      |  | 2.7 V ≤ VDD < 4.0 V,  | 20 MHz < fMCK                  | 16/fмск         |                   | _               |                   | ns   |
|                                      |  | 2.3 V ≤ Vb ≤ 2.7 V  | 16 MHz < fмcк ≤ 20<br>MHz      | 14/fMCK         |                   | _               |                   | ns   |
|                                      |  |   | 8 MHz < fMCK ≤ 16 MHz          | 12/fmck         |                   | _               |                   | ns   |
|                                      |  |   | 4 MHz < fMCK ≤ 8 MHz           | 8/fмск          |                   | 16/fмск         |                   | ns   |
|                                      |  |   | fMCK ≤ 4 MHz                   | 6/fмск          |                   | 10/fмск         |                   | ns   |
|                                      |  | 1.8 V (2.4 V <sup>Note 6</sup> ) ≤  | 20 MHz < fMCK                  | 36/fмск         |                   | _               |                   | ns   |
|                                      |  | VDD < 3.3 V,<br>1.6 V \le Vb \le 2.0 V  | 16 MHz < fмcк ≤ 20<br>MHz      | 32/fMCK         |                   | _               |                   | ns   |
|                                      |  | Note 2  | 8 MHz < fMCK ≤ 16 MHz          | 26/fmck         |                   | _               |                   | ns   |
|                                      |  |   | 4 MHz < fMCK ≤ 8 MHz           | 16/fмск         |                   | 16/fмск         |                   | ns   |
|                                      |  |   | fMCK ≤ 4 MHz                   | 10/fmck         |                   | 10/fмск         |                   | ns   |
| SCKp high-/<br>low-level width       | tKH2,<br>tKL2  | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2$   | 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V | tKCY2/2 -       |                   | tKCY2/2 -<br>50 |                   | ns   |
|                                      |  | 2.7 V ≤ VDD < 4.0 V, 2  | tKCY2/2 -<br>18                |                 | tKCY2/2 -<br>50   |                 | ns                |      |
|                                      |  | 1.8 V (2.4 V <sup>Note 6</sup> ) ≤ V<br>1.6 V ≤ V <sub>b</sub> ≤ 2.0 V No   |                                | tKCY2/2 -<br>50 |                   | tKCY2/2 -<br>50 |                   | ns   |
| SIp setup time<br>(to SCKp↑) Note 3  | tSIK2  | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2$   | 2.7 V ≤ Vb ≤ 4.0 V             | 1/fMCK +<br>20  |                   | 1/fмск +<br>30  |                   | ns   |
|                                      |  | 2.7 V ≤ VDD < 4.0 V, 2  | 2.3 V ≤ Vb ≤ 2.7 V             | 1/fMCK +<br>20  |                   | 1/fмск +<br>30  |                   | ns   |
|                                      |  | 1.8 V (2.4 V <sup>Note 6</sup> ) ≤ V<br>1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note 6</sup>  | ·                              | 1/fмск +<br>30  |                   | 1/fмск +<br>30  |                   | ns   |
| SIp hold time<br>(from SCKp↑) Note 4 | tKSI2  | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2$   | 2.7 V ≤ Vb ≤ 4.0 V             | 1/fMCK +<br>31  |                   | 1/fмск +<br>31  |                   | ns   |
|                                      |  | 2.7 V ≤ VDD < 4.0 V, 2  | 2.3 V ≤ Vb ≤ 2.7 V             | 1/fMCK +<br>31  |                   | 1/fмск +<br>31  |                   | ns   |
|                                      |  | 1.8 V $(2.4 \text{ V}^{\text{Note 6}}) \le \text{V}$<br>1.6 V $\le$ Vb $\le$ 2.0 V No   |                                | 1/fMCK +<br>31  |                   | 1/fмск +<br>31  |                   | ns   |
| Delay time from<br>SCKp↓ to SOp      | tKSO2  | 4.0 V ≤ VDD ≤ 5.5 V, 2<br>Cb = 30 pF, Rb = 1.4  |                                |                 | 2/fмск +<br>120   |                 | 2/fмск +<br>573   | ns   |
| output Note 5                        |  | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V},$ $Cb = 30 \text{ pF}, Rb = 2.7 \text{ k}\Omega$ |                                |                 | 2/fMCK +<br>214   |                 | 2/fмск +<br>573   | ns   |
|                                      | 1.8 V (2.4 VNote 6) $\leq$ 1.6 V $\leq$ Vb $\leq$ 2.0 VNote Cb = 30 pF, Rb = 5.5 |   | e 2 <sub>,</sub>               |                 | 2/fмск +<br>573   |                 | 2/fMCK +<br>573   | ns   |

(Notes, Cautions, and Remarks are listed on the next page.)



- Note 1. Transfer rate in the SNOOZE mode: MAX. 1 Mbps
- **Note 2.** Use it with  $VDD \ge Vb$ .
- Note 3. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The SIp setup time becomes "to SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
- Note 4. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The SIp hold time becomes "from SCKp↓" when DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 0.
- Note 5. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes "from SCKp1" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
- Note 6. Condition in the HS (high-speed main) mode
- Caution Select the TTL input buffer for the SIp and SCKp pins, and the N-ch open drain output (VDD tolerance) mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and VIL, see the DC characteristics with TTL input buffer selected.

#### Simplified SPI(CSI) mode connection diagram (during communication at different potential)

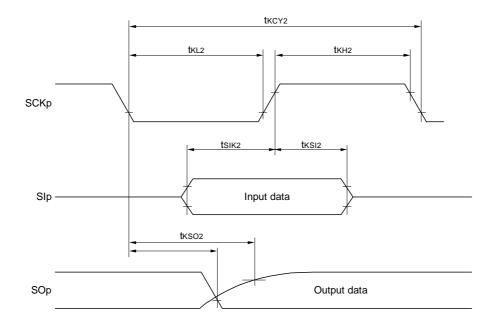


- **Remark 1.** Rb [ $\Omega$ ]: Communication line (SOp) pull-up resistance, Cb [F]: Communication line (SOp) load capacitance, Vb [V]: Communication line voltage
- **Remark 2.** p: CSI number (p = 00, 10, 20), m: Unit number (m = 0, 1), n: Channel number (n = 0, 2), g: PIM or POM number (g = 0, 1, 3, 4, 5, 8)
- Remark 3. fMCK: Serial array unit operation clock frequency

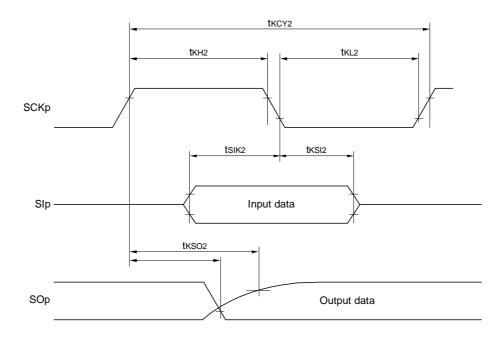
  (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).

  m: Unit number, n: Channel number (mn = 00, 02, 10))

Simplified SPI(CSI) mode serial transfer timing (slave mode) (during communication at different potential) (When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



Simplified SPI(CSI) mode serial transfer timing (slave mode) (during communication at different potential) (When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)



 $\begin{array}{ll} \textbf{Remark} & \text{p: CSI number (p = 00, 10, 20), m: Unit number (m = 0, 1), n: Channel number (n = 0, 2),} \\ & \text{g: PIM or POM number (g = 0, 1, 3, 4, 5, 8)} \end{array}$ 

### (8) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I<sup>2</sup>C mode)

 $(TA = -40 \text{ to } +85^{\circ}C, 1.8 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$ 

(1/2)

| Parameter                 | Symbol | Conditions  | HS (high-<br>speed main)<br>Mode |                | LS (low-<br>speed main)<br>Mode |               | Unit |
|---------------------------|--------|---|----------------------------------|----------------|---------------------------------|---------------|------|
|                           |        |   | MIN.                             | MAX.           | MIN.                            | MAX.          | 1    |
| SCLr clock frequency      | fscL   | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V},$ $Cb = 50 \text{ pF}, Rb = 2.7 \text{ k}Ω$  |                                  | 1000<br>Note 1 |                                 | 300<br>Note 1 | kHz  |
|                           |        | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V},$<br>Cb = 50 pF, Rb = 2.7 k $\Omega$   |                                  | 1000<br>Note 1 |                                 | 300<br>Note 1 | kHz  |
|                           |        | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V},$ $\text{Cb} = 100 \text{ pF}, \text{Rb} = 2.8 \text{ k}\Omega$                    |                                  | 400<br>Note 1  |                                 | 300<br>Note 1 | kHz  |
|                           |        | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V},$ Cb = 100 pF, Rb = 2.7 kΩ   |                                  | 400<br>Note 1  |                                 | 300<br>Note 1 | kHz  |
|                           |        | 1.8 V (2.4 V <sup>Note 4</sup> ) $\leq$ V <sub>DD</sub> $<$ 3.3 V,<br>1.6 V $\leq$ V <sub>D</sub> $\leq$ 2.0 V Note 2, C <sub>D</sub> = 100 pF, R <sub>D</sub> = 5.5 kΩ           |                                  | 400<br>Note 1  |                                 | 300<br>Note 1 | kHz  |
| Hold time when SCLr = "L" | tLOW   | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V},$ $\text{Cb} = 50 \text{ pF}, \text{Rb} = 2.7 \text{ k}\Omega$                     | 475                              |                | 1550                            |               | ns   |
|                           |        | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V},$<br>Cb = 50 pF, Rb = 2.7 k $\Omega$   | 475                              |                | 1550                            |               | ns   |
|                           |        | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V},$ $\text{Cb} = 100 \text{ pF}, \text{Rb} = 2.8 \text{ k}\Omega$                    | 1150                             |                | 1550                            |               | ns   |
|                           |        | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V},$ $\text{Cb} = 100 \text{ pF}, \text{Rb} = 2.7 \text{ k}\Omega$                      | 1150                             |                | 1550                            |               | ns   |
|                           |        | 1.8 V (2.4 V <sup>Note 4</sup> ) $\leq$ V <sub>DD</sub> < 3.3 V,<br>1.6 V $\leq$ V <sub>b</sub> $\leq$ 2.0 V Note 2, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5.5 kΩ             | 1550                             |                | 1550                            |               | ns   |
| Hold time when SCLr = "H" | tHIGH  | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V},$ $\text{Cb} = 50 \text{ pF}, \text{Rb} = 2.7 \text{ k}\Omega$                     | 245                              |                | 610                             |               | ns   |
|                           |        | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V},$ $\text{Cb} = 50 \text{ pF}, \text{Rb} = 2.7 \text{ k}\Omega$                       | 200                              |                | 610                             |               | ns   |
|                           |        | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V},$ Cb = 100 pF, Rb = 2.8 kΩ   | 675                              |                | 610                             |               | ns   |
|                           |        | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V},$ $\text{Cb} = 100 \text{ pF}, \text{Rb} = 2.7 \text{ k}\Omega$                      | 600                              |                | 610                             |               | ns   |
|                           |        | 1.8 V (2.4 V <sup>Note 4</sup> ) $\leq$ V <sub>DD</sub> < 3.3 V,<br>1.6 V $\leq$ V <sub>b</sub> $\leq$ 2.0 V <sup>Note 2</sup> , C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5.5 kΩ | 610                              |                | 610                             |               | ns   |

#### (8) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I<sup>2</sup>C mode)

 $(TA = -40 \text{ to } +85^{\circ}C, 1.8 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$ 

(2/2)

| Parameter                        | Symbol  | Conditions  | HS (high-<br>main) M   | •    | LS (low-s<br>main) M   | •    | Unit |
|----------------------------------|---------|---|------------------------|------|------------------------|------|------|
|                                  |         |   | MIN.                   | MAX. | MIN.                   | MAX. |      |
| Data setup time (reception)      | tsu:dat | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V},$<br>Cb = 50 pF, Rb = 2.7 kΩ                                     | 1/fMCK +<br>135 Note 3 |      | 1/fMCK +<br>190 Note 2 |      | ns   |
|                                  |         | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V},$<br>Cb = 50 pF, Rb = 2.7 k $\Omega$                               | 1/fMCK +<br>135 Note 3 |      | 1/fMCK +<br>190 Note 2 |      | ns   |
|                                  |         | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V},$ $Cb = 100 \text{ pF}, Rb = 2.8 \text{ k}Ω$                     | 1/fMCK +<br>190 Note 3 |      | 1/fMCK +<br>190 Note 3 |      | ns   |
|                                  |         | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V},$<br>$\text{Cb} = 100 \text{ pF}, \text{Rb} = 2.7 \text{ k}\Omega$ | 1/fMCK +<br>190 Note 3 |      | 1/fMCK +<br>190 Note 3 |      | ns   |
|                                  |         | 1.8 V (2.4 V <sup>Note 4</sup> ) $\leq$ VDD $<$ 3.3 V,<br>1.6 V $\leq$ V <sub>b</sub> $\leq$ 2.0 V Note 2,<br>Cb = 100 pF, Rb = 5.5 k $\Omega$                  | 1/fMCK +<br>190 Note 3 |      | 1/fMCK +<br>190 Note 3 |      | ns   |
| Data hold time<br>(transmission) | thd:dat | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V},$<br>Cb = 50 pF, Rb = 2.7 kΩ                                     | 0                      | 305  | 0                      | 305  | ns   |
|                                  |         | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V},$<br>Cb = 50 pF, Rb = 2.7 k $\Omega$                               | 0                      | 305  | 0                      | 305  | ns   |
|                                  |         | $4.0 \text{ V} \le \text{VDD} \le 5.5 \text{ V}, 2.7 \text{ V} \le \text{Vb} \le 4.0 \text{ V},$ Cb = 100 pF, Rb = 2.8 kΩ                                       | 0                      | 355  | 0                      | 355  | ns   |
|                                  |         | $2.7 \text{ V} \le \text{VDD} < 4.0 \text{ V}, 2.3 \text{ V} \le \text{Vb} \le 2.7 \text{ V},$<br>Cb = 100 pF, Rb = 2.7 k $\Omega$                              | 0                      | 355  | 0                      | 355  | ns   |
|                                  |         | 1.8 V (2.4 V <sup>Note 4</sup> ) $\leq$ VDD $<$ 3.3 V,<br>1.6 V $\leq$ V <sub>b</sub> $\leq$ 2.0 V Note 2,<br>Cb = 100 pF, Rb = 5.5 k $\Omega$                  | 0                      | 405  | 0                      | 405  | ns   |

**Note 1.** The value must be equal to or less than fMCK/4.

Caution Select the TTL input buffer and the N-ch open drain output (VDD tolerance) mode for the SDAr pin and the N-ch open drain output (VDD tolerance) mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and VIL, see the DC characteristics with TTL input buffer selected.

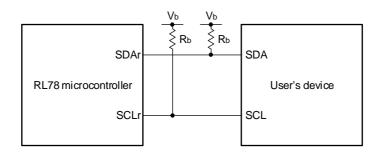
(Remarks are listed on the next page.)

**Note 2.** Use it with  $VDD \ge Vb$ 

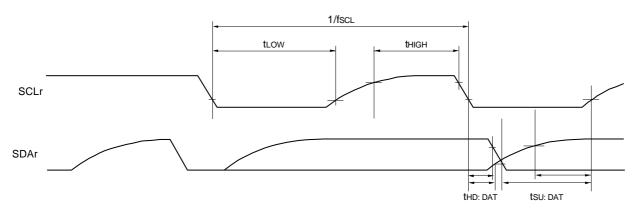
**Note 3.** Set the fMCK value to keep the hold time of SCLr = "L" and SCLr = "H".

Note 4. Condition in the HS (high-speed main) mode

#### Simplified I<sup>2</sup>C mode connection diagram (during communication at different potential)



#### Simplified I<sup>2</sup>C mode serial transfer timing (during communication at different potential)



- Remark 1. Rb [ $\Omega$ ]: Communication line (SDAr, SCLr) pull-up resistance, Cb [F]: Communication line (SDAr, SCLr) load capacitance, Vb [V]: Communication line voltage
- **Remark 2.** r: IIC number (r = 00, 10, 20), g: PIM, POM number (g = 0, 1, 3, 4, 5, 8)
- Remark 3. fMCK: Serial array unit operation clock frequency

  (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number (m = 0),

  n: Channel number (n = 0, 2), mn = 00, 02, 10)

#### 3.5.2 Serial Interface UARTMG

#### $(TA = -40 \text{ to } +85^{\circ}\text{C}, 1.8 \text{ V} \le \text{AVDD} = \text{VDD} \le 5.5 \text{ V}, \text{AVSS} = \text{VSS} = 0 \text{ V})$

| Parameter     | Symbol | Conditions  | MIN. | TYP. | MAX.  | Unit |
|---------------|--------|---|------|------|-------|------|
| Transfer rate |        | fsub = 38.4 kHz                                       | 200  |      | 9600  | bps  |
|               |        | fsub = 38.4 kHz<br>(when the clock doubler is in use) | 200  |      | 19200 | bps  |

### 3.5.3 Serial interface IICA

#### (1) I<sup>2</sup>C standard mode

 $(TA = -40 \text{ to } +85^{\circ}\text{C}, 1.8 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$ 

| Parameter             | Symbol   | Co                               | onditions  | ` `  | speed main)<br>ode | LS (low-spee | ed main) Mode | Unit |
|-----------------------|----------|----------------------------------|--|------|--------------------|--------------|---------------|------|
|                       |          |                                  |  | MIN. | MAX.               | MIN.         | MAX.          |      |
| SCLA0 clock frequency | fSCL     | Standard mode:                   | 2.7 V ≤ VDD ≤ 5.5 V  | 0    | 100                | 0            | 100           | kHz  |
|                       |          | fCLK ≥ 1 MHz                     | 1.8 V (2.4 V <sup>Note 3</sup> ) ≤ VDD ≤ 5.5 V             | 0    | 100                | 0            | 100           | kHz  |
| Setup time of restart | tsu: sta | 2.7 V ≤ VDD ≤ 5.5                | V  | 4.7  |                    | 4.7          |               | μs   |
| condition             |          | 1.8 V (2.4 VNote 3)              | ≤ VDD ≤ 5.5 V  | 4.7  |                    | 4.7          |               | μs   |
| Hold time Note 1      | thd: STA | 2.7 V ≤ VDD ≤ 5.5                | V  | 4.0  |                    | 4.0          |               | μs   |
|                       |          | 1.8 V (2.4 V <sup>Note 3</sup> ) | 1.8 V (2.4 V <sup>Note 3</sup> ) ≤ V <sub>DD</sub> ≤ 5.5 V |      |                    | 4.0          |               | μs   |
| Hold time             | tLOW     | 2.7 V ≤ VDD ≤ 5.5                | 2.7 V ≤ VDD ≤ 5.5 V  |      |                    | 4.7          |               | μs   |
| when SCLA0 = "L"      |          | 1.8 V (2.4 V <sup>Note 3</sup> ) | ≤ VDD ≤ 5.5 V  | 4.7  |                    | 4.7          |               | μs   |
| Hold time             | tHIGH    | 2.7 V ≤ VDD ≤ 5.5                | V  | 4.0  |                    | 4.0          |               | μs   |
| when SCLA0 = "H"      |          | 1.8 V (2.4 V <sup>Note 3</sup> ) | ≤ VDD ≤ 5.5 V  | 4.0  |                    | 4.0          |               | μs   |
| Data setup time       | tsu: dat | 2.7 V ≤ VDD ≤ 5.5                | V  | 250  |                    | 250          |               | ns   |
| (reception)           |          | 1.8 V (2.4 VNote 3)              | ≤ VDD ≤ 5.5 V  | 250  |                    | 250          |               | ns   |
| Data hold time        | thd: dat | 2.7 V ≤ VDD ≤ 5.5                | V  | 0    | 3.45               | 0            | 3.45          | μs   |
| (transmission) Note 2 |          | 1.8 V (2.4 V <sup>Note 3</sup> ) | ≤ VDD ≤ 5.5 V  | 0    |                    | 0            | 3.45          | μs   |
| Setup time of stop    | tsu: sto | 2.7 V ≤ VDD ≤ 5.5                | V  | 4.0  |                    | 4.0          |               | μs   |
| condition             |          | 1.8 V (2.4 V <sup>Note 3</sup> ) | ≤ VDD ≤ 5.5 V  | 4.0  |                    | 4.0          |               | μs   |
| Bus-free time         | tBUF     | 2.7 V ≤ VDD ≤ 5.5                | V  | 4.7  |                    | 4.7          |               | μs   |
|                       |          | 1.8 V (2.4 V <sup>Note 3</sup> ) | ≤ VDD ≤ 5.5 V  | 4.7  |                    | 4.7          |               | μs   |

- Note 1. The first clock pulse is generated after this period when the start/restart condition is detected.
- **Note 2.** The maximum value (MAX.) of thd:Dat is during normal transfer and a clock stretch state is inserted in the ACK (acknowledge) timing.
- Note 3. Condition in the HS (high-speed main) mode

Remark The maximum value of Cb (communication line capacitance) and the value of Rb (communication line pull-up resistor) at that time in each mode are as follows.

Standard mode: Cb = 400 pF,  $Rb = 2.7 \text{ k}\Omega$ 

#### (2) I2C fast mode

### $(TA = -40 \text{ to } +85^{\circ}C, 1.8 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$

| Parameter             | Symbol   | С  | Conditions   |      | speed main)<br>ode | , ,  | peed main)<br>ode | Unit |
|-----------------------|----------|--|--|------|--------------------|------|-------------------|------|
|                       |          |  |  | MIN. | MAX.               | MIN. | MAX.              |      |
| SCLA0 clock frequency | fscl     | Fast mode:   | 2.7 V ≤ VDD ≤ 5.5 V  | 0    | 400                | 0    | 400               | kHz  |
|                       |          | fclk ≥ 3.5 MHz   | 1.8 V (2.4 V <sup>Note 3</sup> ) ≤ VDD ≤ 5.5 V             | 0    | 400                | 0    | 400               | kHz  |
| Setup time of restart | tsu: sta | 2.7 V ≤ VDD ≤ 5.5  | V  | 0.6  |                    | 0.6  |                   | μs   |
| condition             |          | 1.8 V (2.4 VNote 3   | ) ≤ VDD ≤ 5.5 V  | 0.6  |                    | 0.6  |                   | μs   |
| Hold time Note 1      | tHD: STA | 2.7 V ≤ VDD ≤ 5.5  | i V  | 0.6  |                    | 0.6  |                   | μs   |
|                       |          | 1.8 V (2.4 V <sup>Note 3</sup>                             | ) ≤ VDD ≤ 5.5 V  | 0.6  |                    | 0.6  |                   | μs   |
| Hold time             | tLOW     | 2.7 V ≤ VDD ≤ 5.5  | i V  | 1.3  |                    | 1.3  |                   | μs   |
| when SCLA0 = "L"      |          | 1.8 V (2.4 V <sup>Note 3</sup>                             | ) ≤ VDD ≤ 5.5 V  | 1.3  |                    | 1.3  |                   | μs   |
| Hold time             | tHIGH    | 2.7 V ≤ VDD ≤ 5.5  | i V  | 0.6  |                    | 0.6  |                   | μs   |
| when SCLA0 = "H"      |          | 1.8 V (2.4 V <sup>Note 3</sup>                             | ) ≤ VDD ≤ 5.5 V  | 0.6  |                    | 0.6  |                   | μs   |
| Data setup time       | tsu: DAT | 2.7 V ≤ VDD ≤ 5.5  | i V  | 100  |                    | 100  |                   | ns   |
| (reception)           |          | 1.8 V (2.4 VNote 3   | ) ≤ VDD ≤ 5.5 V  | 100  |                    | 100  |                   | ns   |
| Data hold time        | thd: dat | 2.7 V ≤ VDD ≤ 5.5  | i V  | 0    | 0.9                | 0    | 0.9               | μs   |
| (transmission) Note 2 |          | 1.8 V (2.4 V <sup>Note 3</sup>                             | ) ≤ VDD ≤ 5.5 V  | 0    |                    | 0    | 0.9               | μs   |
| Setup time of stop    | tsu: sto | 2.7 V ≤ VDD ≤ 5.5  | 2.7 V ≤ VDD ≤ 5.5 V  |      |                    | 0.6  |                   | μs   |
| condition             |          | 1.8 V (2.4 V <sup>Note 3</sup> ) ≤ V <sub>DD</sub> ≤ 5.5 V |  | 0.6  |                    | 0.6  |                   | μs   |
| Bus-free time         | tBUF     | 2.7 V ≤ VDD ≤ 5.5  | i V  | 1.3  |                    | 1.3  |                   | μs   |
|                       |          | 1.8 V (2.4 V <sup>Note 3</sup>                             | 1.8 V (2.4 V <sup>Note 3</sup> ) ≤ V <sub>DD</sub> ≤ 5.5 V |      |                    | 1.3  |                   | μs   |

- **Note 1.** The first clock pulse is generated after this period when the start/restart condition is detected.
- **Note 2.** The maximum value (MAX.) of thd: DAT is during normal transfer and a clock stretch state is inserted in the ACK (acknowledge) timing.
- Note 3. Condition in the HS (high-speed main) mode

Remark The maximum value of Cb (communication line capacitance) and the value of Rb (communication line pull-up resistor) at that time in each mode are as follows.

Fast mode: Cb = 320 pF,  $Rb = 1.1 \text{ k}\Omega$ 

#### (3) I2C fast mode plus

#### $(TA = -40 \text{ to } +85^{\circ}C, 1.8 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$

| Parameter                               | Symbol   | Cor                              | nditions            |      | peed main)<br>ode | LS (low-sp<br>Mo |      | Unit |
|---|----------|----------------------------------|---------------------|------|-------------------|------------------|------|------|
|   |          |                                  |                     | MIN. | MAX.              | MIN.             | MAX. |      |
| SCLA0 clock frequency                   | fSCL     | Fast mode plus:<br>fcLK ≥ 10 MHz | 2.7 V ≤ VDD ≤ 5.5 V | 0    | 1000              | _                | _    | kHz  |
| Setup time of restart condition         | tsu: sta | 2.7 V ≤ VDD ≤ 5.5 V              |                     | 0.26 |                   | _                | _    | μs   |
| Hold time Note 1                        | thd: STA | 2.7 V ≤ VDD ≤ 5.5 V              |                     | 0.26 |                   | _                | =    | μs   |
| Hold time when SCLA0 = "L"              | tLOW     | 2.7 V ≤ VDD ≤ 5.5 V              |                     | 0.5  |                   | _                | =    | μs   |
| Hold time when SCLA0 = "H"              | tHIGH    | 2.7 V ≤ VDD ≤ 5.5 V              |                     | 0.26 |                   | _                | -    | μs   |
| Data setup time (reception)             | tsu: dat | 2.7 V ≤ VDD ≤ 5.5 V              |                     | 50   |                   | _                | _    | ns   |
| Data hold time<br>(transmission) Note 2 | thd: dat | 2.7 V ≤ VDD ≤ 5.5 V              |                     | 0    | 0.45              | _                | -    | μs   |
| Setup time of stop condition            | tsu: sto | 2.7 V ≤ VDD ≤ 5.5 V              |                     | 0.26 |                   | _                | _    | μs   |
| Bus-free time                           | tBUF     | 2.7 V ≤ VDD ≤ 5.5 V              |                     | 0.5  |                   | -                | _    | μs   |

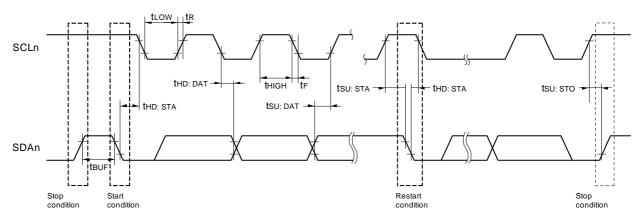
Note 1. The first clock pulse is generated after this period when the start/restart condition is detected.

**Note 2.** The maximum value (MAX.) of thd: DAT is during normal transfer and a clock stretch state is inserted in the ACK (acknowledge) timing.

Remark The maximum value of Cb (communication line capacitance) and the value of Rb (communication line pull-up resistor) at that time in each mode are as follows.

Fast mode plus: Cb = 120 pF,  $Rb = 1.1 \text{ k}\Omega$ 

#### **IICA** serial transfer timing



## 3.6 Analog Characteristics

#### 3.6.1 A/D converter Characteristics

(1) When reference voltage (+) = VDD (ADREFP1 = 0, ADREFP0 = 0), reference voltage (-) = VSS (ADREFM = 0), target pin: ANI8 to ANI10, internal reference voltage, and temperature sensor output voltage
 (TA = -40 to +85°C, 1.8 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V, reference voltage (+) = VDD, reference voltage (-) = VSS)

| Parameter                              | Symbol   | Conditions  |                     | MIN.           | TYP. | MAX.  | Unit |
|--|--|---|---------------------|----------------|------|-------|------|
| Resolution                             | RES  |   |                     | 8              |      | 10    | bit  |
| Overall error Note 1                   | AINL   | 10-bit resolution   | 1.8 V ≤ VDD ≤ 5.5 V |                | 1.2  | ±7.0  | LSB  |
| Conversion time                        | tconv  | 10-bit resolution   | 3.6 V ≤ VDD ≤ 5.5 V | 2.125          |      | 39    | μs   |
|  |  | Target pin: ANI8 to ANI10   | 2.7 V ≤ VDD ≤ 5.5 V | 3.1875         |      | 39    | μs   |
|  |  |   | 1.8 V ≤ VDD ≤ 5.5 V | 17             |      | 39    | μs   |
|  |  | 10-bit resolution   | 3.6 V ≤ VDD ≤ 5.5 V | 2.375          |      | 39    | μs   |
|  | Target pin: internal reference voltage and temperature sensor output voltage | 2.7 V ≤ VDD ≤ 5.5 V   | 3.5626              |                | 39   | μs    |      |
|  |  | (HS (high-speed main) mode)   | 1.8 V ≤ VDD ≤ 5.5 V | 17             |      | 39    | μs   |
| Zero-scale error<br>Notes 1, 2         | Ezs  | 10-bit resolution   | 1.8 V ≤ VDD ≤ 5.5 V |                |      | ±0.60 | %FSR |
| Full-scale error<br>Notes 1, 2         | EFS  | 10-bit resolution   | 1.8 V ≤ VDD ≤ 5.5 V |                |      | ±0.60 | %FSR |
| Integral linearity error<br>Note 1     | ILE  | 10-bit resolution   | 1.8 V ≤ VDD ≤ 5.5 V |                |      | ±4.0  | LSB  |
| Differential linearity<br>error Note 1 | DLE  | 10-bit resolution   | 1.8 V ≤ VDD ≤ 5.5 V |                |      | ±2.0  | LSB  |
| Analog input voltage                   | VAIN   | ANI8 to ANI10   | •                   | 0              |      | VDD   | V    |
|  |  | Internal reference voltage<br>(2.4 V ≤ VDD ≤ 5.5 V, HS (high-speed ma     |                     | VBGR Note 3    |      | V     |      |
|  |  | Temperature sensor output voltage (2.4 V ≤ VDD ≤ 5.5 V, HS (high-speed ma | ain) mode)          | VTMPS25 Note 3 |      |       | V    |

Note 1. Excludes quantization error (±1/2 LSB).

Note 2. This value is indicated as a ratio (%FSR) to the full-scale value.

Note 3. Refer to 3.6.2 Temperature sensor/internal reference voltage output characteristics.

# (2) When reference voltage (+) = Internal reference voltage (ADREFP1 = 1, ADREFP0 = 0), reference voltage (-) = Vss (ADREFM = 0), target pin: ANI8 to ANI10

(TA = -40 to +85°C, 2.4 V  $\leq$  AVDD = VDD  $\leq$  5.5 V, AVSS = VSS = 0 V, reference voltage (+) = VBGR<sup>Note 3</sup>, reference voltage (-) = VSS = 0 V, HS (high-speed main) mode)

| Parameter                           | Symbol | Conditions       |                     |    | TYP. | MAX.         | Unit |
|-------------------------------------|--------|------------------|---------------------|----|------|--------------|------|
| Resolution                          | RES    |                  |                     |    | 8    |              |      |
| Conversion time                     | tconv  | 8-bit resolution | 2.4 V ≤ VDD ≤ 5.5 V | 17 |      | 39           | μs   |
| Zero-scale error Notes 1, 2,        | Ezs    | 8-bit resolution | 2.4 V ≤ VDD ≤ 5.5 V |    |      | ±(0.60+0.35) | %FSR |
| Integral linearity error Note 1     | ILE    | 8-bit resolution | 2.4 V ≤ VDD ≤ 5.5 V |    |      | ±(2.0+0.5)   | LSB  |
| Differential linearity error Note 1 | DLE    | 8-bit resolution | 2.4 V ≤ VDD ≤ 5.5 V |    |      | ±(1.0+0.2)   | LSB  |
| Analog input voltage                | VAIN   |                  | ·                   | 0  |      | VBGR Note 3  | V    |

- Note 1. Excludes quantization error (±1/2 LSB).
- Note 2. This value is indicated as a ratio (%FSR) to the full-scale value.
- Note 3. Refer to 3.6.2 Temperature sensor/internal reference voltage output characteristics.

### 3.6.2 Temperature sensor/internal reference voltage output characteristics

(TA = -40 to +85°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V, HS (high-speed main) Mode)

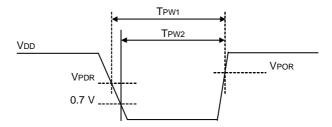
| Parameter                         | Symbol | Conditions  | MIN. | TYP. | MAX. | Unit  |
|-----------------------------------|--------|---|------|------|------|-------|
| Temperature sensor output voltage | VTEMP  | TA = +25°C  |      | 1.05 |      | V     |
| Internal reference voltage        | VBGR   |   | 1.38 | 1.45 | 1.5  | V     |
| Temperature coefficient           | FVTMPS | Temperature sensor output voltage that depends on the temperature |      | -3.6 |      | mV/°C |
| Operation stabilization wait time | tamp   | 2.4 V ≤ VDD ≤ 5.5 V   | 5    |      |      | μs    |

#### 3.6.3 POR circuit characteristics

 $(TA = -40 \text{ to } +85^{\circ}C, Vss = 0 \text{ V})$ 

| Parameter                  | Symbol | Conditions                       | MIN. | TYP. | MAX. | Unit |
|----------------------------|--------|----------------------------------|------|------|------|------|
| Detection voltage          | VPOR   | Power supply rise time           | 1.47 | 1.51 | 1.55 | V    |
|                            | VPDR   | Power supply fall time Note 1    | 1.46 | 1.50 | 1.54 | V    |
| Minimum pulse width Note 2 | TPW1   | Other than STOP/SUB HALT/SUB RUN | 300  |      |      | μs   |
|                            | TPW2   | STOP/SUB HALT/SUB RUN            | 300  |      |      | μs   |

- **Note 1.** If the power supply voltage falls while the voltage detector is off, be sure to either shift to STOP mode or execute a reset by using the voltage detector or external reset pin before the power supply voltage falls below the minimum operating voltage specified in **3.4 AC Characteristics**.
- Note 2. Minimum time required for a POR reset when VDD falls below VPDR. This is also the minimum time required for a POR reset from when VDD exceeds below 0.7 V to when VDD exceeds VPOR while STOP mode is entered or the main system clock is stopped through setting bit 0 (HIOSTOP) and bit 7 (MSTOP) in the clock operation status control register (CSC).



#### 3.6.4 LVD circuit characteristics

# (1) LVD detection voltage in reset mode and interrupt mode $(TA = -40 \text{ to } +85^{\circ}\text{C}, VPDR \le AVDD} = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$

| Pa                  | rameter              | Symbol       | Conditions   | MIN. | TYP. | MAX. | Unit |
|---------------------|----------------------|--------------|--------------|------|------|------|------|
| Detection voltage   | Supply voltage level | VLVD0        | Rising edge  | 3.98 | 4.06 | 4.14 | V    |
|                     |                      |              | Falling edge | 3.90 | 3.98 | 4.06 | V    |
|                     |                      | VLVD1        | Rising edge  | 3.68 | 3.75 | 3.82 | V    |
|                     |                      |              | Falling edge | 3.60 | 3.67 | 3.74 | V    |
|                     |                      | VLVD2        | Rising edge  | 3.07 | 3.13 | 3.19 | V    |
|                     |                      |              | Falling edge | 3.00 | 3.06 | 3.12 | V    |
|                     |                      | VLVD3        | Rising edge  | 2.96 | 3.02 | 3.08 | V    |
|                     |                      |              | Falling edge | 2.90 | 2.96 | 3.02 | V    |
|                     |                      | VLVD4        | Rising edge  | 2.86 | 2.92 | 2.97 | V    |
|                     |                      |              | Falling edge | 2.80 | 2.86 | 2.91 | V    |
|                     |                      | VLVD5        | Rising edge  | 2.76 | 2.81 | 2.87 | V    |
|                     |                      | Falling edge | 2.70         | 2.75 | 2.81 | V    |      |
|                     |                      | VLVD6        | Rising edge  | 2.66 | 2.71 | 2.76 | V    |
|                     |                      |              | Falling edge | 2.60 | 2.65 | 2.70 | V    |
|                     |                      | VLVD7        | Rising edge  | 2.56 | 2.61 | 2.66 | V    |
|                     |                      |              | Falling edge | 2.50 | 2.55 | 2.60 | V    |
|                     |                      | VLVD8        | Rising edge  | 2.45 | 2.50 | 2.55 | V    |
|                     |                      |              | Falling edge | 2.40 | 2.45 | 2.50 | V    |
|                     |                      | VLVD9        | Rising edge  | 2.05 | 2.09 | 2.13 | V    |
|                     |                      |              | Falling edge | 2.00 | 2.04 | 2.08 | V    |
|                     |                      | VLVD10       | Rising edge  | 1.94 | 1.98 | 2.02 | V    |
|                     |                      |              | Falling edge | 1.90 | 1.94 | 1.98 | V    |
|                     |                      | VLVD11       | Rising edge  | 1.84 | 1.88 | 1.91 | V    |
|                     |                      |              | Falling edge | 1.80 | 1.84 | 1.87 | V    |
| Minimum pulse wid   | ith                  | tLW          |              | 300  |      |      | μs   |
| Detection delay tim | ne                   |              |              |      |      | 300  | μs   |

Caution Set the detection voltage (VLVD) to be within the operating voltage range. The operating voltage range depends on the setting of the user option byte (000C2H/010C2H). The following shows the operating voltage range.

HS (high-speed main) mode:  $\,$  VDD = 2.7 to 5.5 V @ 1 MHz to 24 MHz

VDD = 2.4 to 5.5 V @ 1 MHz to 16 MHz

LS (low-speed main) mode: VDD = 1.8 to 5.5 V @ 1 MHz to 8 MHz

# (2) LVD Detection Voltage of Interrupt & Reset Mode

(TA = -40 to +85°C, VPDR  $\leq$  AVDD = VDD  $\leq$  5.5 V, AVSS = VSS = 0 V)

| Parameter           | Symbol |       | Cond                         | tions                        | MIN. | TYP. | MAX. | Unit |
|---------------------|--------|-------|------------------------------|------------------------------|------|------|------|------|
| Interrupt and reset | VLVDB0 | VPOC2 | , VPOC1, VPOC0 = 0, 0, 1, fa | Illing reset voltage: 1.8 V  | 1.80 | 1.84 | 1.87 | V    |
| mode                | VLVDB1 |       | LVIS1, LVIS0 = 1, 0          | Rising release reset voltage | 1.94 | 1.98 | 2.02 | V    |
|                     |        |       |                              | Falling interrupt voltage    | 1.90 | 1.94 | 1.98 | V    |
|                     | VLVDB2 |       | LVIS1, LVIS0 = 0, 1          | Rising release reset voltage | 2.05 | 2.09 | 2.13 | V    |
|                     |        |       |                              | Falling interrupt voltage    | 2.00 | 2.04 | 2.08 | V    |
|                     | VLVDB3 |       | LVIS1, LVIS0 = 0, 0          | Rising release reset voltage | 3.07 | 3.13 | 3.19 | V    |
|                     |        |       |                              | Falling interrupt voltage    | 3.00 | 3.06 | 3.12 | V    |
|                     | VLVDC0 | VPOC2 | , VPOC1, VPOC0 = 0, 1, 0, fa | alling reset voltage: 2.4 V  | 2.40 | 2.45 | 2.50 | V    |
| V                   | VLVDC1 |       | LVIS1, LVIS0 = 1, 0          | Rising release reset voltage | 2.56 | 2.61 | 2.66 | V    |
|                     |        |       |                              | Falling interrupt voltage    | 2.50 | 2.55 | 2.60 | V    |
|                     | VLVDC2 |       | LVIS1, LVIS0 = 0, 1          | Rising release reset voltage | 2.66 | 2.71 | 2.76 | V    |
|                     |        |       |                              | Falling interrupt voltage    | 2.60 | 2.65 | 2.70 | V    |
|                     | VLVDC3 |       | LVIS1, LVIS0 = 0, 0          | Rising release reset voltage | 3.68 | 3.75 | 3.82 | V    |
|                     |        |       |                              | Falling interrupt voltage    | 3.60 | 3.67 | 3.74 | V    |
|                     | VLVDD0 | VPOC2 | , VPOC1, VPOC0 = 0, 1, 1, fa | Illing reset voltage: 2.7 V  | 2.70 | 2.75 | 2.81 | V    |
|                     | VLVDD1 |       | LVIS1, LVIS0 = 1, 0          | Rising release reset voltage | 2.86 | 2.92 | 2.97 | V    |
|                     |        |       |                              | Falling interrupt voltage    | 2.80 | 2.86 | 2.91 | V    |
|                     | VLVDD2 |       | LVIS1, LVIS0 = 0, 1          | Rising release reset voltage | 2.96 | 3.02 | 3.08 | V    |
|                     |        |       |                              | Falling interrupt voltage    | 2.90 | 2.96 | 3.02 | V    |
|                     | VLVDC3 |       | LVIS1, LVIS0 = 0, 0          | Rising release reset voltage | 3.98 | 4.06 | 4.14 | V    |
|                     |        |       |                              | Falling interrupt voltage    | 3.90 | 3.98 | 4.06 | V    |

# 3.7 Power supply voltage rising slope characteristics

 $(TA = -40 \text{ to } +85^{\circ}\text{C}, \text{ Vss} = 0 \text{ V})$ 

| Parameter                         | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-----------------------------------|--------|------------|------|------|------|------|
| Power supply voltage rising slope | SVDD   |            |      |      | 54   | V/ms |

Caution Make sure to keep the internal reset state by the LVD circuit or an external reset until VDD reaches the operating voltage range shown in 3.4 AC Characteristics.

### 3.8 LCD Characteristics

#### 3.8.1 Resistance division method

#### (1) Static display mode

 $(TA = -40 \text{ to } +85^{\circ}\text{C}, VL4 \text{ (MIN.)} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$ 

| Parameter         | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-------------------|--------|------------|------|------|------|------|
| LCD drive voltage | VL4    |            | 2.0  |      | VDD  | V    |

#### (2) 1/2 bias method, 1/4 bias method

 $(TA = -40 \text{ to } +85^{\circ}\text{C}, VL4 \text{ (MIN.)} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$ 

| Parameter         | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-------------------|--------|------------|------|------|------|------|
| LCD drive voltage | VL4    |            | 2.7  |      | VDD  | V    |

#### (3) 1/3 bias method

 $(TA = -40 \text{ to } +85^{\circ}\text{C}, VL4 \text{ (MIN.)} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$ 

| Parameter         | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-------------------|--------|------------|------|------|------|------|
| LCD drive voltage | VL4    |            | 2.5  |      | VDD  | V    |

## 3.8.2 Internal voltage boosting method

#### (1) 1/3 bias method

 $(TA = -40 \text{ to } +85^{\circ}C, 1.8 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$ 

| Parameter                           | Symbol  | Cond                      | ditions    | MIN.                    | TYP.  | MAX.  | Unit |
|-------------------------------------|---------|---------------------------|------------|-------------------------|-------|-------|------|
| LCD output voltage variation range  | VL1     | C1 to C4 Note 1           | VLCD = 04H | 0.90                    | 1.00  | 1.08  | V    |
|                                     |         | = 0.47 µF Note 2          | VLCD = 05H | 0.95                    | 1.05  | 1.13  | V    |
|                                     |         |                           | VLCD = 06H | 1.00                    | 1.10  | 1.18  | V    |
|                                     |         |                           | VLCD = 07H | 1.05                    | 1.15  | 1.23  | V    |
|                                     |         |                           | VLCD = 08H | 1.10                    | 1.20  | 1.28  | V    |
|                                     |         |                           | VLCD = 09H | 1.15                    | 1.25  | 1.33  | V    |
|                                     |         |                           | VLCD = 0AH | 1.20                    | 1.30  | 1.38  | V    |
|                                     |         |                           | VLCD = 0BH | 1.25                    | 1.35  | 1.43  | V    |
|                                     |         |                           | VLCD = 0CH | 1.30                    | 1.40  | 1.48  | V    |
|                                     |         |                           | VLCD = 0DH | 1.35                    | 1.45  | 1.53  | V    |
|                                     |         |                           | VLCD = 0EH | 1.40                    | 1.50  | 1.58  | V    |
|                                     |         |                           | VLCD = 0FH | 1.45                    | 1.55  | 1.63  | V    |
|                                     |         |                           | VLCD = 10H | 1.50                    | 1.60  | 1.68  | V    |
|                                     |         |                           | VLCD = 11H | 1.55                    | 1.65  | 1.73  | V    |
|                                     |         |                           | VLCD = 12H | 1.60                    | 1.70  | 1.78  | V    |
|                                     |         |                           | VLCD = 13H | 1.65                    | 1.75  | 1.83  | V    |
| Doubler output voltage              | VL2     | C1 to C4 Note 1 =         | - 0.47 μF  | 2 V <sub>L1</sub> - 0.1 | 2 VL1 | 2 VL1 | V    |
| Tripler output voltage              | VL4     | C1 to C4 Note 1 = 0.47 µF |            | 3 VL1- 0.15             | 3 VL1 | 3 VL1 | V    |
| Reference voltage setup time Note 2 | tvwait1 |                           |            | 5                       |       |       | ms   |
| Voltage boost wait time Note 3      | tVWAIT2 | C1 to C4 Note 1 = 0.47µF  |            | 500                     |       |       | ms   |

Note 1. This is a capacitor that is connected between voltage pins used to drive the LCD.

- C1: A capacitor connected between CAPH and CAPL
- C2: A capacitor connected between VL1 and GND
- C3: A capacitor connected between VL2 and GND
- C4: A capacitor connected between VL4 and GND
- $C1 = C2 = C3 = C4 = 0.47 \mu F \pm 30\%$
- Note 2. This is the time required to wait from when the reference voltage is specified by using the VLCD register (or when the internal voltage boosting method is selected (by setting the MDSET1 and MDSET0 bits of the LCDM0 register to 01B) if the default value reference voltage is used) until voltage boosting starts (VLCON = 1).
- Note 3. This is the wait time from when voltage boosting is started (VLCON = 1) until display is enabled (LCDON = 1).

#### (2) 1/4 bias method

#### (TA = -40 to +85°C, 1.8 V $\leq$ AVDD = VDD $\leq$ 5.5 V, AVSS = VSS = 0 V)

| Parameter                           | Symbol  | Conc                      | litions    | MIN.                     | TYP.  | MAX.  | Unit |
|-------------------------------------|---------|---------------------------|------------|--------------------------|-------|-------|------|
| LCD output voltage variation range  | VL1     | C1 to C5 Note 1           | VLCD = 04H | 0.90                     | 1.00  | 1.08  | V    |
|                                     |         | = $0.47 \mu F$ Note 2     | VLCD = 05H | 0.95                     | 1.05  | 1.13  | V    |
|                                     |         |                           | VLCD = 06H | 1.00                     | 1.10  | 1.18  | V    |
|                                     |         |                           | VLCD = 07H | 1.05                     | 1.15  | 1.23  | V    |
|                                     |         |                           | VLCD = 08H | 1.10                     | 1.20  | 1.28  | V    |
|                                     |         |                           | VLCD = 09H | 1.15                     | 1.25  | 1.33  | V    |
|                                     |         |                           | VLCD = 0AH | 1.20                     | 1.30  | 1.38  | V    |
| Doubler output voltage              | VL2     | C1 to C5 Note 1 =         | : 0.47 μF  | 2 V <sub>L1</sub> - 0.08 | 2 VL1 | 2 VL1 | V    |
| Tripler output voltage              | VL3     | C1 to C5 Note 1 =         | : 0.47 μF  | 3 V <sub>L1</sub> - 0.12 | 3 VL1 | 3 VL1 | V    |
| Quadruply output voltage            | VL4     | C1 to C5 Note 1 = 0.47 µF |            | 4 V <sub>L1</sub> - 0.16 | 4 VL1 | 4 VL1 | V    |
| Reference voltage setup time Note 2 | tVWAIT1 |                           |            | 5                        |       |       | ms   |
| Voltage boost wait time Note 3      | tVWAIT2 | C1 to C5 Note 1 =         | : 0.47μF   | 500                      |       |       | ms   |

- **Note 1.** This is a capacitor that is connected between voltage pins used to drive the LCD.
  - C1: A capacitor connected between CAPH and CAPL
  - C2: A capacitor connected between VL1 and GND
  - C3: A capacitor connected between VL2 and GND
  - C4: A capacitor connected between VL3 and GND
  - C5: A capacitor connected between VL4 and GND
  - $C1 = C2 = C3 = C4 = C5 = 0.47 \mu F \pm 30\%$
- Note 2. This is the time required to wait from when the reference voltage is specified by using the VLCD register (or when the internal voltage boosting method is selected (by setting the MDSET1 and MDSET0 bits of the LCDM0 register to 01B) if the default value reference voltage is used) until voltage boosting starts (VLCON = 1).
- Note 3. This is the wait time from when voltage boosting is started (VLCON = 1) until display is enabled (LCDON = 1).

# 3.8.3 Capacitor split method

#### (1) 1/3 bias method

(TA = -40 to +85°C, 2.2 V  $\leq$  AVDD = VDD  $\leq$  5.5 V, AVSS = VSS = 0 V)

| Parameter                        | Symbol | Conditions                | MIN.                      | TYP.    | MAX.                      | Unit |
|----------------------------------|--------|---------------------------|---------------------------|---------|---------------------------|------|
| VL4 voltage                      | VL4    | C1 to C4 = 0.47 µF Note 2 |                           | VDD     |                           | V    |
| VL2 voltage                      | VL2    | C1 to C4 = 0.47 µF Note 2 | 2/3 V <sub>L4</sub> - 0.1 | 2/3 VL4 | 2/3 V <sub>L4</sub> + 0.1 | V    |
| VL1 voltage                      | VL1    | C1 to C4 = 0.47 µF Note 2 | 1/3 VL4 - 0.1             | 1/3 VL4 | 1/3 VL4 + 0.1             | V    |
| Capacitor split wait time Note 1 | tvwait |                           | 100                       |         |                           | ms   |

Note 1. This is the wait time from when voltage bucking is started (VLCON = 1) until display is enabled (LCDON = 1).

**Note 2.** This is a capacitor that is connected between voltage pins used to drive the LCD.

C1: A capacitor connected between CAPH and CAPL

C2: A capacitor connected between VL1 and GND

C3: A capacitor connected between VL2 and GND

C4: A capacitor connected between VL4 and GND

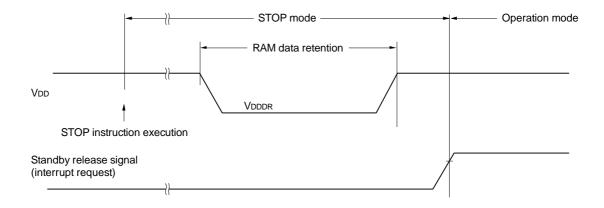
 $C1 = C2 = C3 = C4 = 0.47 \mu F \pm 30\%$ 

#### 3.9 RAM Data Retention Characteristics

#### $(TA = -40 \text{ to } +85^{\circ}C, Vss = 0 \text{ V})$

| Parameter                     | Symbol | Conditions | MIN.      | TYP. | MAX. | Unit |
|-------------------------------|--------|------------|-----------|------|------|------|
| Data retention supply voltage | VDDDR  |            | 1.46 Note |      | 5.5  | V    |

**Note** The value depends on the POR detection voltage. When the voltage drops, the RAM data is retained before a POR reset is effected, but RAM data is not retained when a POR reset is effected.



### 3.10 Flash Memory Programming Characteristics

#### $(TA = -40 \text{ to } +85^{\circ}\text{C}, 1.8 \text{ V} \le \text{AVDD} = \text{VDD} \le 5.5 \text{ V}, \text{AVSS} = \text{VSS} = 0 \text{ V})$

| Parameter                                      | Symbol | Conditions            |           | MIN.    | TYP.      | MAX. | Unit  |
|--|--------|-----------------------|-----------|---------|-----------|------|-------|
| System clock frequency                         | fCLK   | 1.8 V ≤ VDD ≤ 5.5 V   |           | 1       |           | 24   | MHz   |
| Number of code flash rewrites<br>Notes 1, 2, 3 | Cerwr  | Retained for 20 years | TA = 85°C | 1,000   |           |      | Times |
| Number of data flash rewrites                  |        | Retained for 1 year   | TA = 25°C |         | 1,000,000 |      |       |
| Notes 1, 2, 3                                  |        | Retained for 5 years  | TA = 85°C | 100,000 |           |      |       |
|  |        | Retained for 20 years | TA = 85°C | 10,000  |           |      |       |

- Note 1. 1 erase + 1 write after the erase is regarded as 1 rewrite. The retaining years are until next rewrite after the rewrite.
- Note 2. When using flash memory programmer and Renesas Electronics self-programming library
- **Note 3.** These are the characteristics of the flash memory and the results obtained from reliability testing by Renesas Electronics Corporation.

### 3.11 Dedicated Flash Memory Programmer Communication (UART)

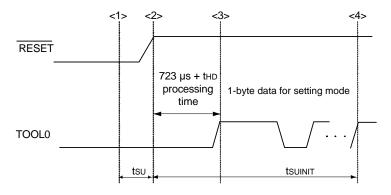
#### $(TA = -40 \text{ to } +85^{\circ}C, 1.8 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$

| Parameter     | Symbol | Conditions                | MIN.    | TYP. | MAX.      | Unit |
|---------------|--------|---------------------------|---------|------|-----------|------|
| Transfer rate |        | During serial programming | 115,200 |      | 1,000,000 | bps  |

## 3.12 Timing of Entry to Flash Memory Programming Modes

 $(TA = -40 \text{ to } +85^{\circ}C, 1.8 \text{ V} \le AVDD = VDD \le 5.5 \text{ V}, AVSS = VSS = 0 \text{ V})$ 

| Parameter   | Symbol  | Conditions   | MIN. | TYP. | MAX. | Unit |
|---|---------|--|------|------|------|------|
| How long from when an external reset ends until the initial communication settings are specified  | tsuinit | POR and LVD reset must end before the external reset ends. |      |      | 100  | ms   |
| How long from when the TOOL0 pin is placed at the low level until an external reset ends  | tsu     | POR and LVD reset must end before the external reset ends. | 10   |      |      | μs   |
| How long the TOOL0 pin must be kept at the low level after an external reset ends (excluding the processing time of the firmware to control the flash memory) | tHD     | POR and LVD reset must end before the external reset ends. | 1    |      |      | ms   |



- <1> The low level is input to the TOOL0 pin.
- <2> The external reset ends (POR and LVD reset must end before the external reset ends).
- <3> The TOOL0 pin is set to the high level.
- <4> Setting of the flash memory programming mode by UART reception and complete the baud rate setting.

**Remark** tsuint: The segment shows that it is necessary to finish specifying the initial communication settings within 100 ms from when the external resets end.

tsu: How long from when the TOOL0 pin is placed at the low level until a pin reset ends
thd: How long to keep the TOOL0 pin at the low level from when the external resets end
(excluding the processing time of the firmware to control the flash memory)

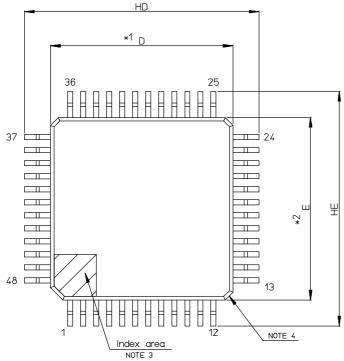
RL78/H1D 4. PACKAGE DRAWINGS

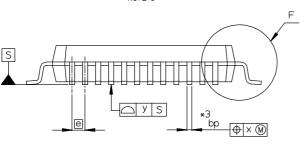
# 4. PACKAGE DRAWINGS

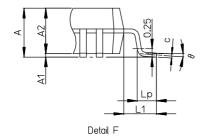
#### 4.1 48-pin products

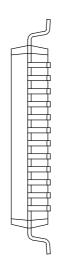
R5F11NGGAFB, R5F11NGFAFB

| JEITA Package Code | RENESAS Code | Previous Code | MASS[Typ.] |
|--------------------|--------------|---------------|------------|
| P-LFQFP48-7×7-0.50 | PLQP0048KB-B |               | 0.2g       |









#### NOTE)

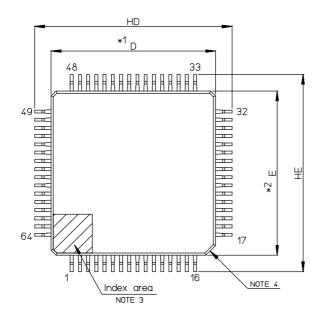
- DIMENSIONS '\*1' AND '\*2" DO NOT INCLUDE MOLD FLASH.
  DIMENSION '\*3' DOES NOT INCLUDE TRIM OFFSET.
  PIN 1 VISUAL INDEX FEATURE MAY VARY, BUT MUST BE
  LOCATED WITHIN THE HATCHED AREA.
  CHAMFERS AT CORNERS ARE OPTIONAL; SIZE MAY VARY. 1. 2. 3.

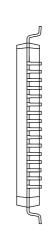
| Reference | Dimens | ion in Mil | limeters |
|-----------|--------|------------|----------|
| Symbol    | Min    | Nom        | Max      |
| D         | 6.9    | 7.0        | 7.1      |
| Е         | 6.9    | 7.0        | 7.1      |
| A2        |        | 1.4        |          |
| HD        | 8.8    | 9.0        | 9.2      |
| HE        | 8.8    | 9.0        | 9.2      |
| Α         |        |            | 1.7      |
| A1        | 0.05   |            | 0.15     |
| bp        | 0.17   | 0.20       | 0.27     |
| С         | 0.09   |            | 0.20     |
| θ         | 0 "    | 3.5        | 8 "      |
| е         |        | 0.5        |          |
| ×         |        |            | 0.08     |
| У         |        |            | 0.08     |
| Lp        | 0.45   | 0.6        | 0.75     |
| L1        |        | 1.0        |          |

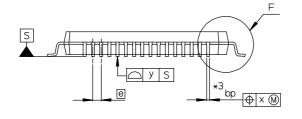
#### 4.2 64-pin products

R5F11NLGAFB, R5F11NLFAFB

| JEITA Package Code   | RENESAS Code | Previous Code | MASS[Typ.] |
|----------------------|--------------|---------------|------------|
| P-LFQFP64-10×10-0.50 | PLQP0064KB-C |               | 0.3g       |







#### NOTE)

- 1. 2. 3.
- DIMENSIONS '\*1' AND '\*2' DO NOT INCLUDE MOLD FLASH.
  DIMENSION '\*3' DOES NOT INCLUDE TRIM OFFSET.
  PIN 1 VISUAL INDEX FEATURE MAY VARY, BUT MUST BE
  LOCATED WITHIN THE HATCHED AREA.
  CHAMFERS AT CORNERS ARE OPTIONAL, SIZE MAY VARY.

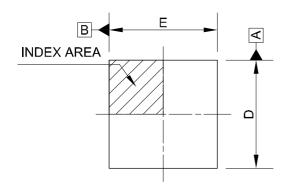
| ∀ | A2 |          | 00.25         |
|---|----|----------|---------------|
|   | A1 |          | 117           |
|   |    |          | Lp<br>L1      |
|   |    | Detail F | - <del></del> |

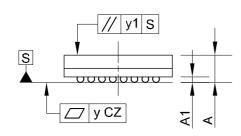
| Reference | Dimens | ion in Mil | limeters |
|-----------|--------|------------|----------|
| Symbol    | Min    | Nom        | Max      |
| D         | 9.9    | 10.0       | 10.1     |
| Е         | 9.9    | 10.0       | 10.1     |
| A2        |        | 1.4        |          |
| HD        | 11.8   | 12.0       | 12.2     |
| HE        | 11.8   | 12.0       | 12.2     |
| Α         |        |            | 1.7      |
| A1        | 0.05   |            | 0.15     |
| bp        | 0.15   | 0.20       | 0.27     |
| С         | 0.09   |            | 0.20     |
| θ         | 0 "    | 3.5        | 8 "      |
| е         |        | 0.5        |          |
| ×         |        |            | 0.08     |
| У         |        |            | 0.08     |
| Lp        | 0.45   | 0.6        | 0.75     |
| L1        |        | 1.0        |          |

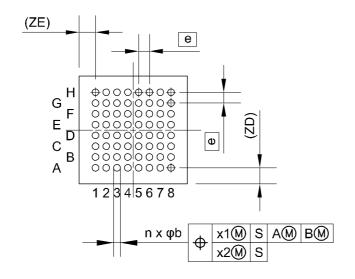
RL78/H1D 4. PACKAGE DRAWINGS

### R5F11PLGABG, R5F11PLFABG

| JEITA Package code | RENESAS code | MASS(TYP.)[g] |
|--------------------|--------------|---------------|
| P-TFBGA64-4x4-0.40 | PTBG0064LA-A | 0.03          |





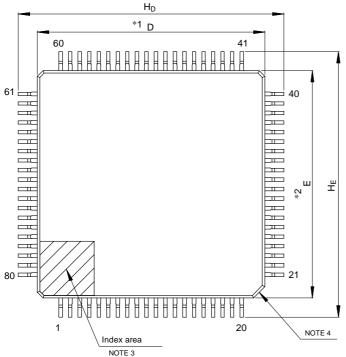


| Reference | Dimension in Millimeters |      |      |  |  |
|-----------|--------------------------|------|------|--|--|
| Symbol    | Min.                     | Nom. | Max. |  |  |
| D         | 3.9                      | 4.0  | 4.1  |  |  |
| E         | 3.9                      | 4.0  | 4.1  |  |  |
| А         | _                        | _    | 1.10 |  |  |
| A1        | 0.15                     | 0.20 | 0.25 |  |  |
| b         | 0.20                     | 0.25 | 0.30 |  |  |
| е         | _                        | 0.40 | -    |  |  |
| x1        | _                        | _    | 0.15 |  |  |
| x2        | _                        | _    | 0.05 |  |  |
| у         | _                        | _    | 0.08 |  |  |
| y1        | _                        | _    | 0.20 |  |  |
| n         | _                        | 64   | 1    |  |  |
| ZD        | _                        | 0.60 | _    |  |  |
| ZE        | _                        | 0.60 | _    |  |  |

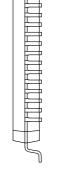
#### 4.3 80-pin products

R5F11NMGAFB, R5F11NMFAFB, R5F11NMEAFB R5F11RMGDFB

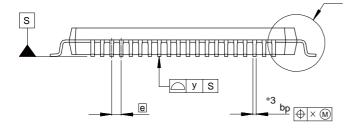
| JEITA Package Code   | RENESAS Code | Previous Code | MASS (Typ) [g] |
|----------------------|--------------|---------------|----------------|
| P-LFQFP80-12x12-0.50 | PLQP0080KB-B | _             | 0.5            |

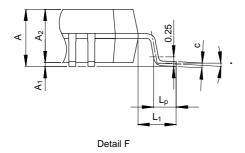






- 1. DIMENSIONS "\*1"AND "\*2" DO NOT INCLUDE MOLD FLASH
  2. DIMENSION "\*3" DOES NOT INCLUDE TRIM OFFSET.
  3. PIN 1 VISUAL INDEX FEATURE MAY VARY, BUT MUST BE LOCATED WITHINTHE HATCHEDAREA.
- 4. CHAMFERSAT CORNERSARE OPTIONAL, SIZE MAY VARY.





| Reference<br>Symbol | Dimensions in millimeters |       |      |  |
|---------------------|---------------------------|-------|------|--|
|                     | Min                       | Nom   | Max  |  |
| D                   | 11.9                      | 12.0  | 12.1 |  |
| Е                   | 11.9                      | 12.0  | 12.1 |  |
| A <sub>2</sub>      | •                         | 1.4   | •    |  |
| H <sub>D</sub>      | 13.8                      | 14.0  | 14.2 |  |
| HE                  | 13.8                      | 14.0  | 14.2 |  |
| Α                   | •                         | ٠     | 1.7  |  |
| A <sub>1</sub>      | 0.05                      | •     | 0.15 |  |
| bp                  | 0.15                      | 0.20  | 0.27 |  |
| С                   | 0.09                      | •     | 0.20 |  |
| •                   | 0 •                       | 3.5 • | 8 •  |  |
| е                   | •                         | 0.5   | •    |  |
| х                   | •                         | ٠     | 0.08 |  |
| у                   | •                         | •     | 0.08 |  |
| Lp                  | 0.45                      | 0.6   | 0.75 |  |
| L <sub>1</sub>      | •                         | 1.0   | •    |  |

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| REVISION HISTORY | RL78/H1D Datasheet |
|------------------|--------------------|
|------------------|--------------------|

| Rev. | Date -           | Description  |  |  |  |
|------|------------------|--|--|--|--|
|      |                  | Page   | Summary  |  |  |
| 1.00 | Apr 13 2018      | _  | First Edition issued   |  |  |
| 1.10 | 1.10 Apr 28 2023 | All  | The module name for CSI was changed to simplified SPI.                       |  |  |
|      |                  |  | "Wait" was modified to "clock stretch".                                      |  |  |
|      |                  | p.2  | Addition of Note 3 in 1.1 Features   |  |  |
|      |                  |  | Modification of Note 3 to Note 4 in 1.1 Features                             |  |  |
|      |                  |  | Modification of Note 4 to Note 5 in 1.1 Features                             |  |  |
|      |                  | p.5  | Modification of Figure 1 - 1 in 1.2 Ordering Information                     |  |  |
|      |                  | p.31   | Modification of Note 1 in 2.3.2 Supply current characteristics               |  |  |
|      |                  |  | Modification of Note 4 in 2.3.2 Supply current characteristics               |  |  |
|      |                  | p.33   | Modification of Note 1 in 2.3.2 Supply current characteristics               |  |  |
|      |                  |  | Modification of Note 5 in 2.3.2 Supply current characteristics               |  |  |
|      |                  |  | Deletion of Note 6 in 2.3.2 Supply current characteristics                   |  |  |
|      |                  |  | Modification of Note 7 to Note 6 in 2.3.2 Supply current characteristics     |  |  |
|      |                  |  | Modification of Note 8 to Note 7 in 2.3.2 Supply current characteristics     |  |  |
|      |                  |  | Modification of Note 9 to Note 8 in 2.3.2 Supply current characteristics     |  |  |
|      |                  | p.93   | Modification of Note 1 in 3.3.2 Supply current characteristics               |  |  |
|      |                  |  | Modification of Note 4 in 3.3.2 Supply current characteristics               |  |  |
|      |                  | p.95   | Modification of Note 1 in 3.3.2 Supply current characteristics               |  |  |
|      |                  |  | Modification of Note 5 in 3.3.2 Supply current characteristics               |  |  |
|      |                  |  | Deletion of Note 6 in 3.3.2 Supply current characteristics                   |  |  |
|      |                  |  | Modification of Note 7 to Note 6 in 3.3.2 Supply current characteristics     |  |  |
|      |                  | Modification of Note 8 to Note 7 in 3.3.2 Supply current characteristics |  |  |  |
|      |                  | p.140  | Replacement of PLQP0048KB-A with PLQP0048KB-B in 4.1 48-pin products         |  |  |
|      |                  | p.141  | Replacement of PLQP0064KB-A with PLQP0064KB-C in 4.2 64-pin products         |  |  |
|      |                  | p.143  | Replacement of PLQP0080KB-A with PLQP0080KB-B in 4.3 80-pin products         |  |  |
| 1.11 | Mar 22 2024      | p.5  | Modification of table in 1.2 Ordering Information                            |  |  |
|      |                  | p.6  | Modification of Figure 1-1 Part Number, Memory Size, and Package of RL78/H1D |  |  |

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# General Precautions in the Handling of Microprocessing Unit and Microcontroller Unit Products

The following usage notes are applicable to all Microprocessing unit and Microcontroller unit products from Renesas. For detailed usage notes on the products covered by this document, refer to the relevant sections of the document as well as any technical updates that have been issued for the products.

1. Precaution against Electrostatic Discharge (ESD)

A strong electrical field, when exposed to a CMOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop the generation of static electricity as much as possible, and quickly dissipate it when it occurs. Environmental control must be adequate. When it is dry, a humidifier should be used. This is recommended to avoid using insulators that can easily build up static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work benches and floors must be grounded. The operator must also be grounded using a wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions must be taken for printed circuit boards with mounted semiconductor devices.

2. Processing at power-on

The state of the product is undefined at the time when power is supplied. The states of internal circuits in the LSI are indeterminate and the states of register settings and pins are undefined at the time when power is supplied. In a finished product where the reset signal is applied to the external reset pin, the states of pins are not guaranteed from the time when power is supplied until the reset process is completed. In a similar way, the states of pins in a product that is reset by an on-chip power-on reset function are not guaranteed from the time when power is supplied until the power reaches the level at which resetting is specified.

3. Input of signal during power-off state

Do not input signals or an I/O pull-up power supply while the device is powered off. The current injection that results from input of such a signal or I/O pull-up power supply may cause malfunction and the abnormal current that passes in the device at this time may cause degradation of internal elements. Follow the guideline for input signal during power-off state as described in your product documentation.

4. Handling of unused pins

Handle unused pins in accordance with the directions given under handling of unused pins in the manual. The input pins of CMOS products are generally in the high-impedance state. In operation with an unused pin in the open-circuit state, extra electromagnetic noise is induced in the vicinity of the LSI, an associated shoot-through current flows internally, and malfunctions occur due to the false recognition of the pin state as an input signal become possible.

5. Clock signals

After applying a reset, only release the reset line after the operating clock signal becomes stable. When switching the clock signal during program execution, wait until the target clock signal is stabilized. When the clock signal is generated with an external resonator or from an external oscillator during a reset, ensure that the reset line is only released after full stabilization of the clock signal. Additionally, when switching to a clock signal produced with an external resonator or by an external oscillator while program execution is in progress, wait until the target clock signal is stable.

6. Voltage application waveform at input pin

Waveform distortion due to input noise or a reflected wave may cause malfunction. If the input of the CMOS device stays in the area between  $V_{IL}$  (Max.) and  $V_{IH}$  (Min.) due to noise, for example, the device may malfunction. Take care to prevent chattering noise from entering the device when the input level is fixed, and also in the transition period when the input level passes through the area between  $V_{IL}$  (Max.) and  $V_{IH}$  (Min.).

7. Prohibition of access to reserved addresses

Access to reserved addresses is prohibited. The reserved addresses are provided for possible future expansion of functions. Do not access these addresses as the correct operation of the LSI is not guaranteed.

8. Differences between products

Before changing from one product to another, for example to a product with a different part number, confirm that the change will not lead to problems. The characteristics of a microprocessing unit or microcontroller unit products in the same group but having a different part number might differ in terms of internal memory capacity, layout pattern, and other factors, which can affect the ranges of electrical characteristics, such as characteristic values, operating margins, immunity to noise, and amount of radiated noise. When changing to a product with a different part number, implement a system-evaluation test for the given product.

#### **Notice**

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